

# Nanotechnology in Photovoltaics

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University of Trieste*



# Our laboratory

Two lines of research on photovoltaic materials:

- Thin film PV (CdS/CdTe-based)
- Novel nanostructured materials – low-cost and high efficiency

## Part of MEL, Laboratory for Energy Materials

research and services in the field of energy materials, including photovoltaic installations (e.g. 20 kW installation on DMRN's building roof, 20 kW installation on the City Hall's Roof in Trieste, ...)

# Our laboratory

## *Doctoral student:*

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## *Students:*

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Alice Furlan

Emanuele Slejko

Giulio Pipan

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Andrea Radivo

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Dept. Materials and Natural Resources (DMRN)

Spectroscopy Lab DMRN

# Contents

- Introduction – Why photovoltaics (PV)?
- Evolution of PV (economical – technical – social)
- Current PV technologies
  - Basic physics
  - Si-based technology
  - Thin films
- Emerging technologies
  - High efficiency approaches (Tandem)
  - Low-cost approaches (Biomimetics)
- Third generation technologies
  - Nanostructured materials – colloidal solids



# **Photovoltaics**

**Direct conversion of solar energy  
to electrical energy (for free!)**



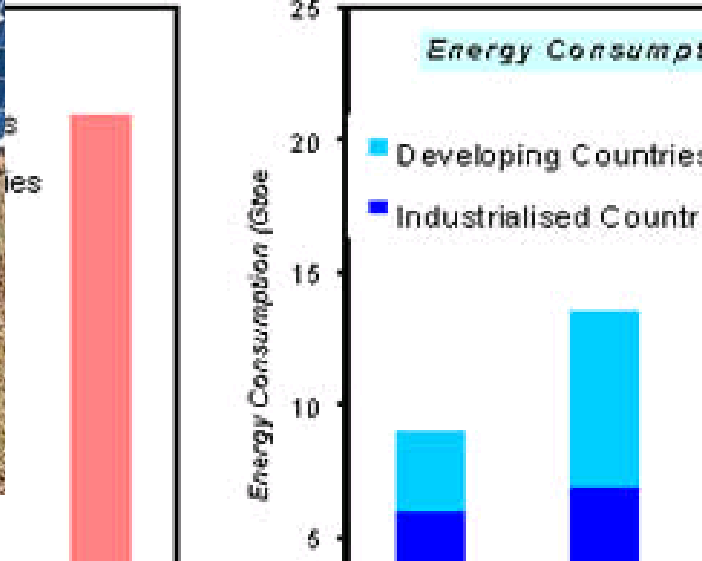
# Why Photovoltaics?

# Growth of the Energy Demand

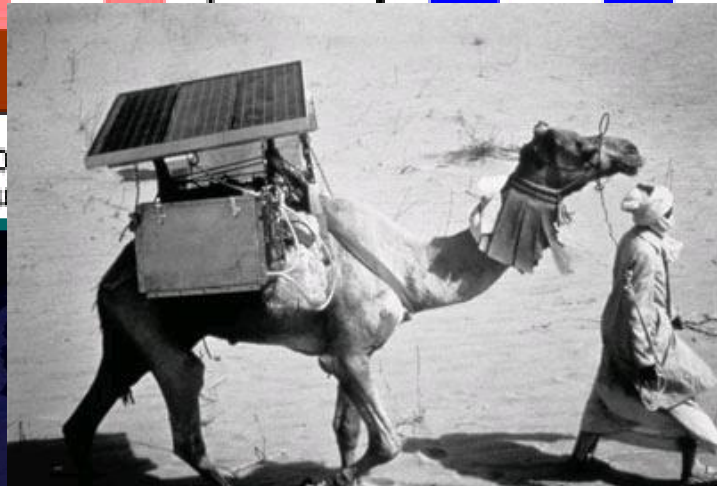
- Particularly in the developing countries-



h in world population and energy consumption



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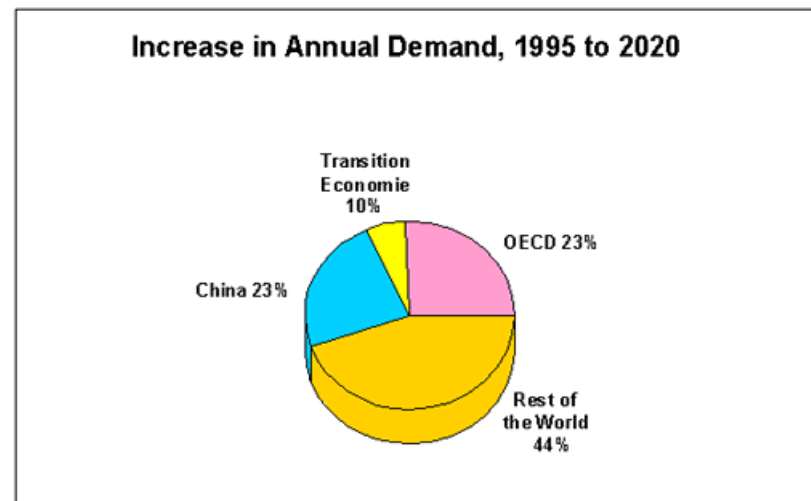
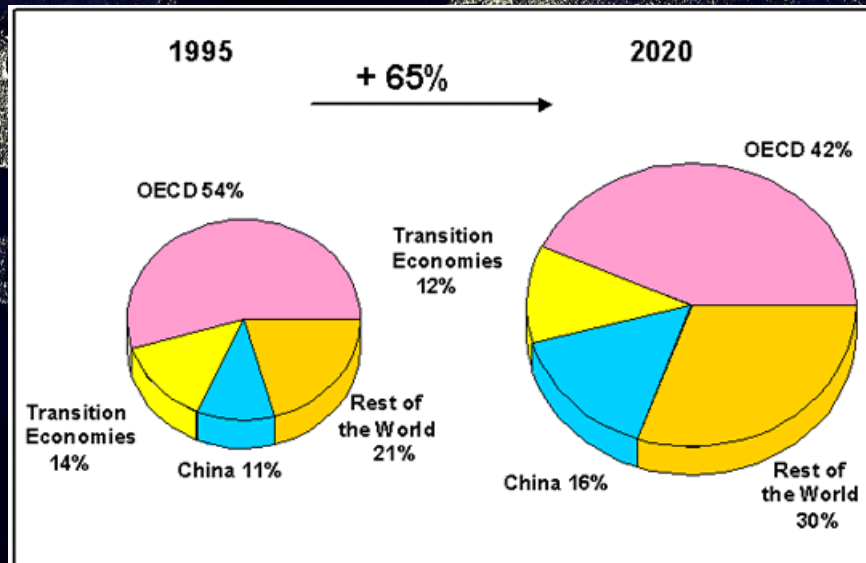


2050



# Growth of the Energy Demand

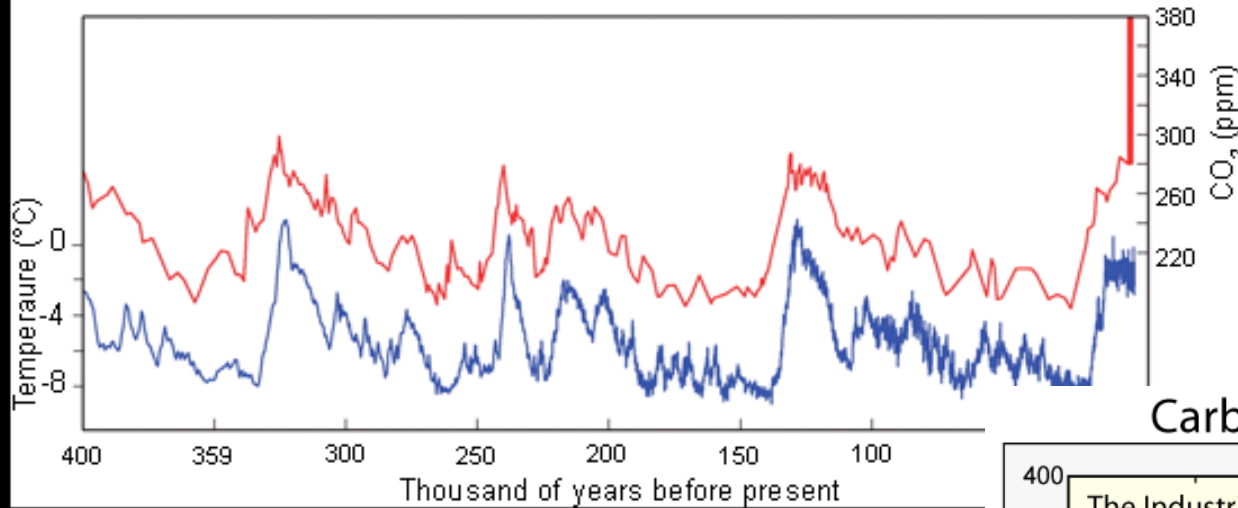
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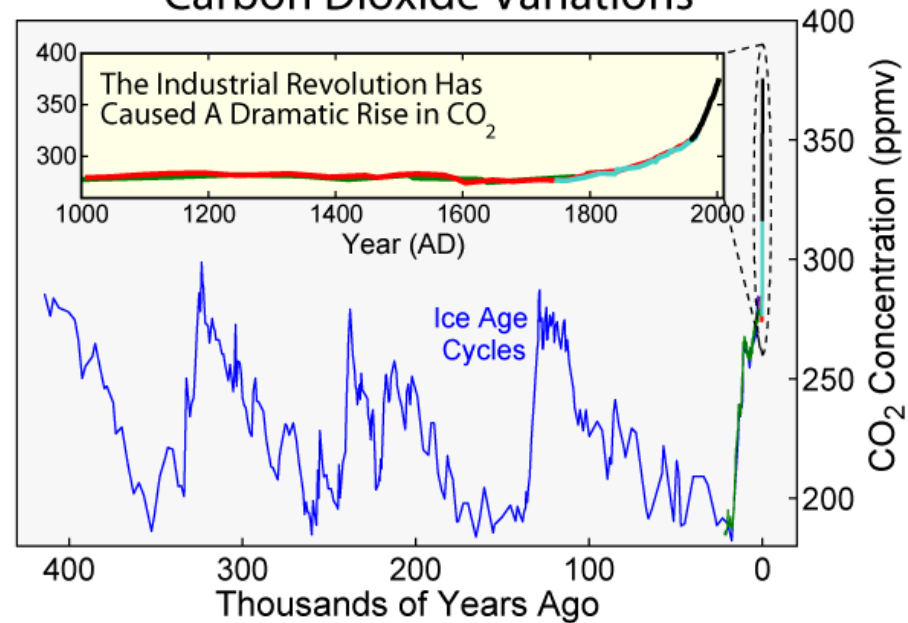
# Need for carbon-free energy sources

## Temperature rising (?)

Figure 1: Changes in Carbon Dioxide and Temperature in the last 400,000 years



## Carbon Dioxide Variations



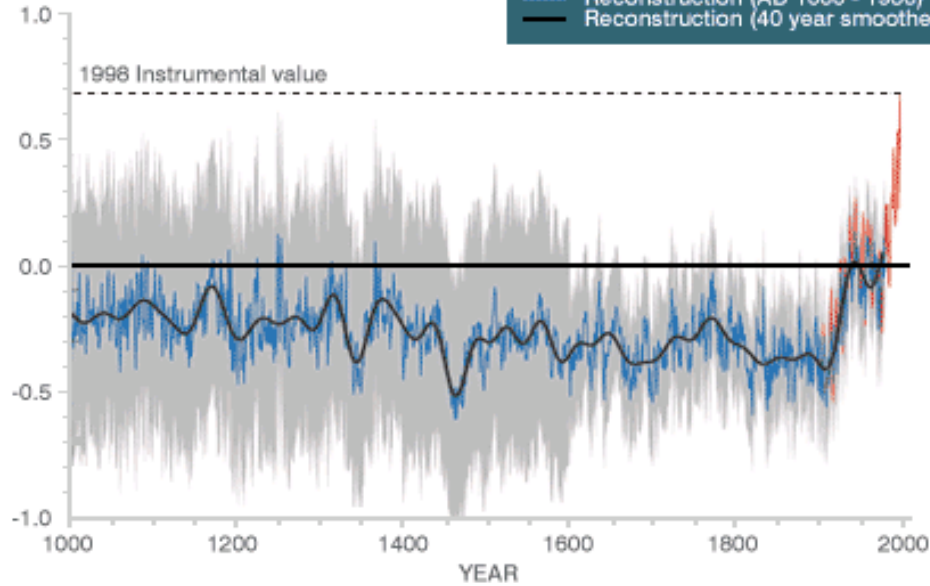
<http://epa.gov/climatechange/science/images/co2-temp.gif>

Earth at Night



# Need for carbon-free energy sources

Northern Hemisphere anomaly (°C)  
relative to 1961 -1990

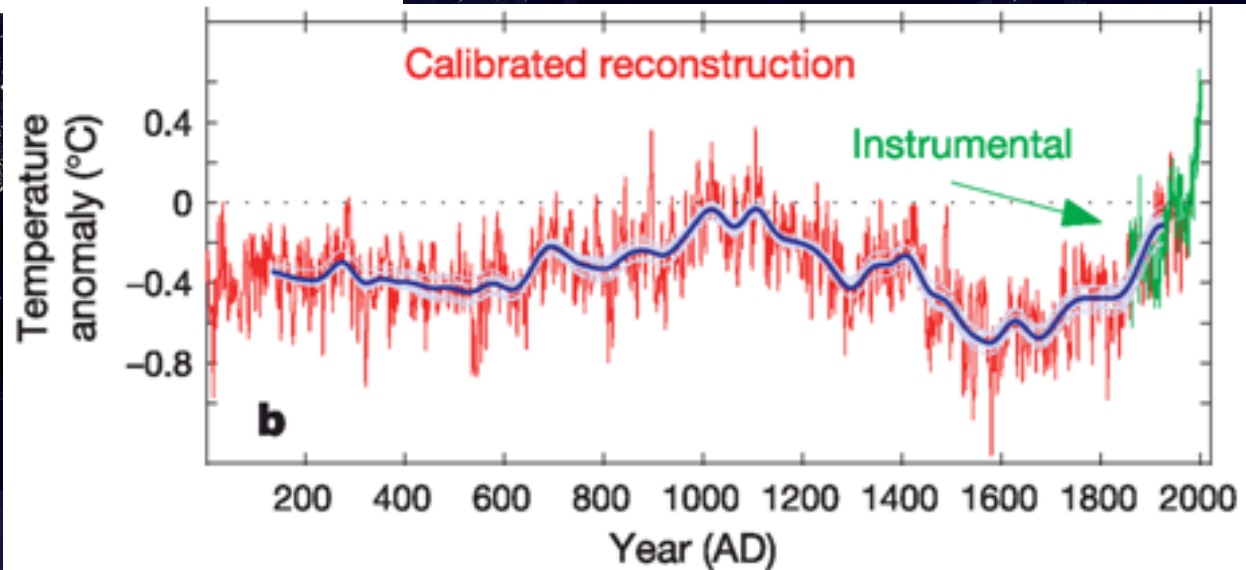


Temperature rising (?)



New Data

Old Data



# Need for carbon-free energy sources

## Ice Melting



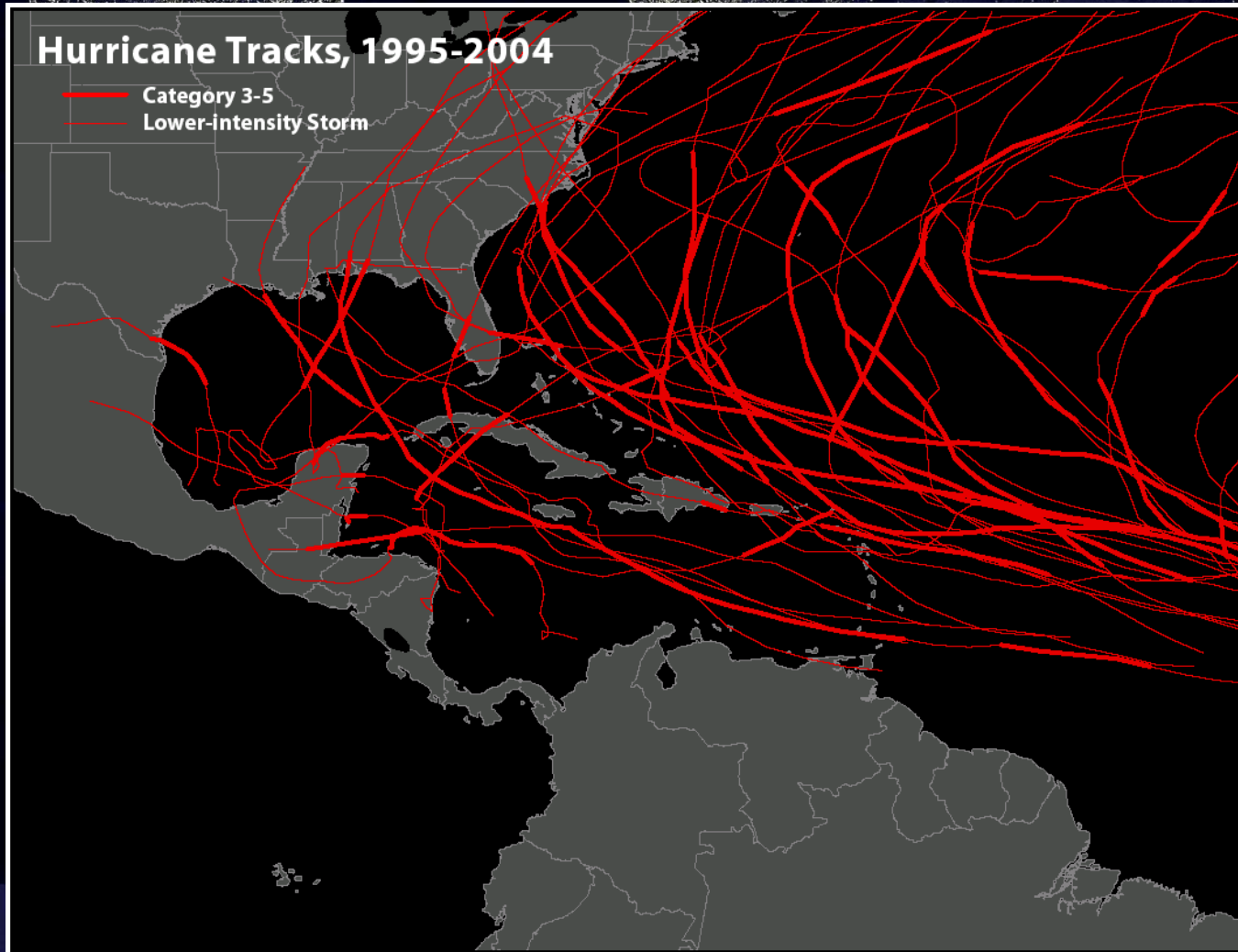
Pasterze Glacier, Austria  
Change between 1875 and 2004

<http://www.worldviewofglobalwarming.org/pages/glaciers.html>



# Need for carbon-free energy sources

## Climate change





# Need for carbon-free energy sources

## Economic sanctions

**la Repubblica.it**

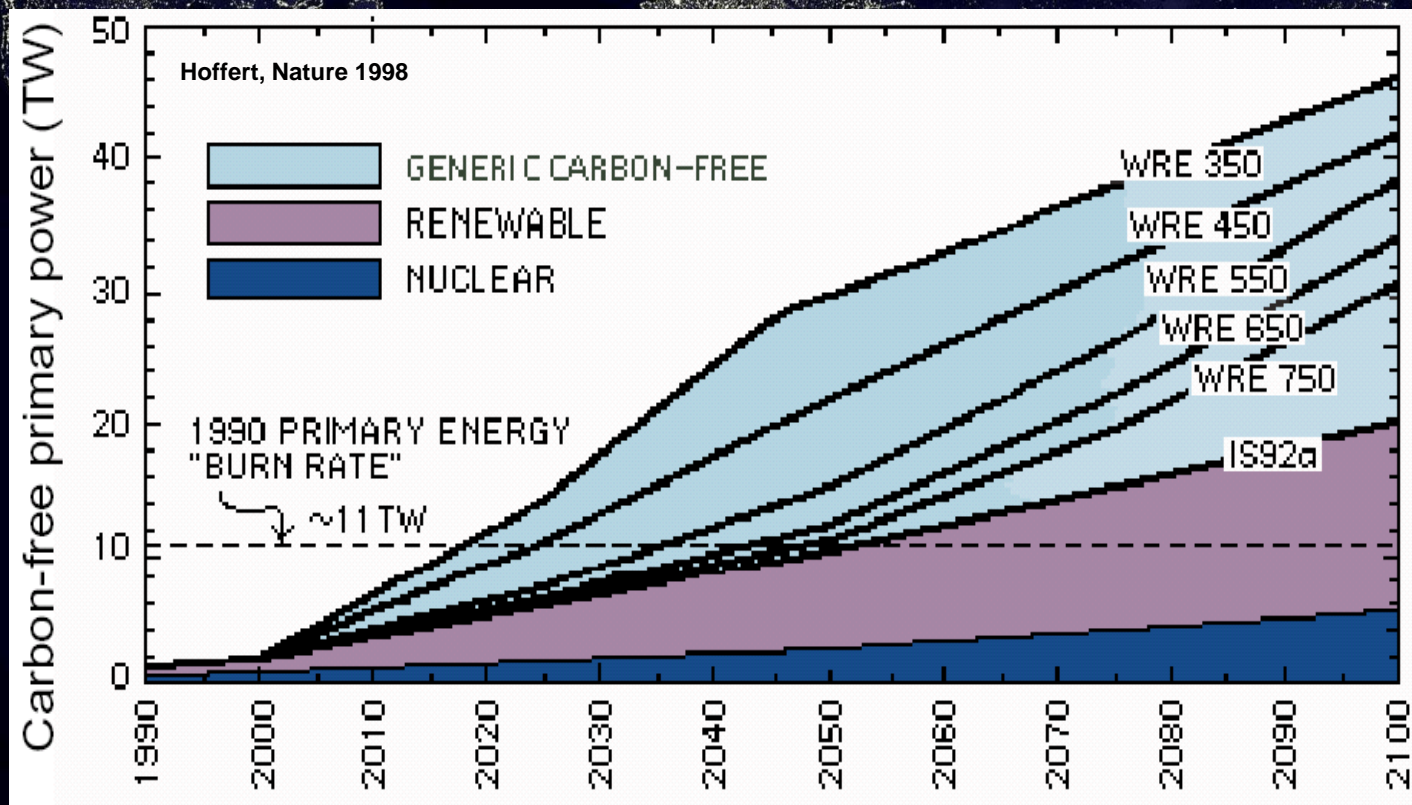
Ultimo aggiornamento **lunedì 08.01.2007 ore 10.45**

### **AMBIENTE**

Entro gennaio convocati gli esperti che hanno preparato la ricerca per la Ue  
Nel conto i danni a turismo e agricoltura e le sanzioni per le violazioni di Kyoto

## **Clima, minaccia per l'economia l'Italia rischia decine di miliardi**

# Need for carbon-free energy sources





# Photovoltaics vs. other Renewable Resources

**Wave and tidal:**  
Limited generating capacity



**Solar thermal:**  
Useful for low-grade heat; electricity use limited to desert regions



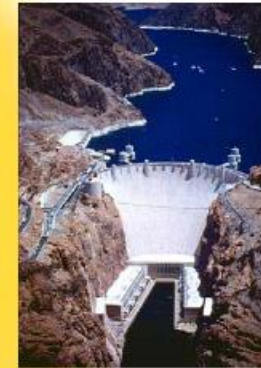
**Wind:**  
Site issues



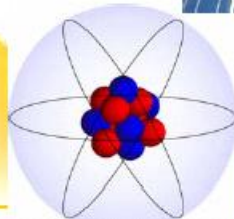
**Biomass:**  
Large land use



**Hydro:**  
Large dam sites already developed



**Photovoltaics**



**Nuclear:**  
Cost, waste

**Geothermal:**  
Location of resource

*Allen Barnett*

# Evolution of Photovoltaics

- Economical
- Technical
- “Social” – acceptance and integration

# **Economical Evolution: Photovoltaic Market**



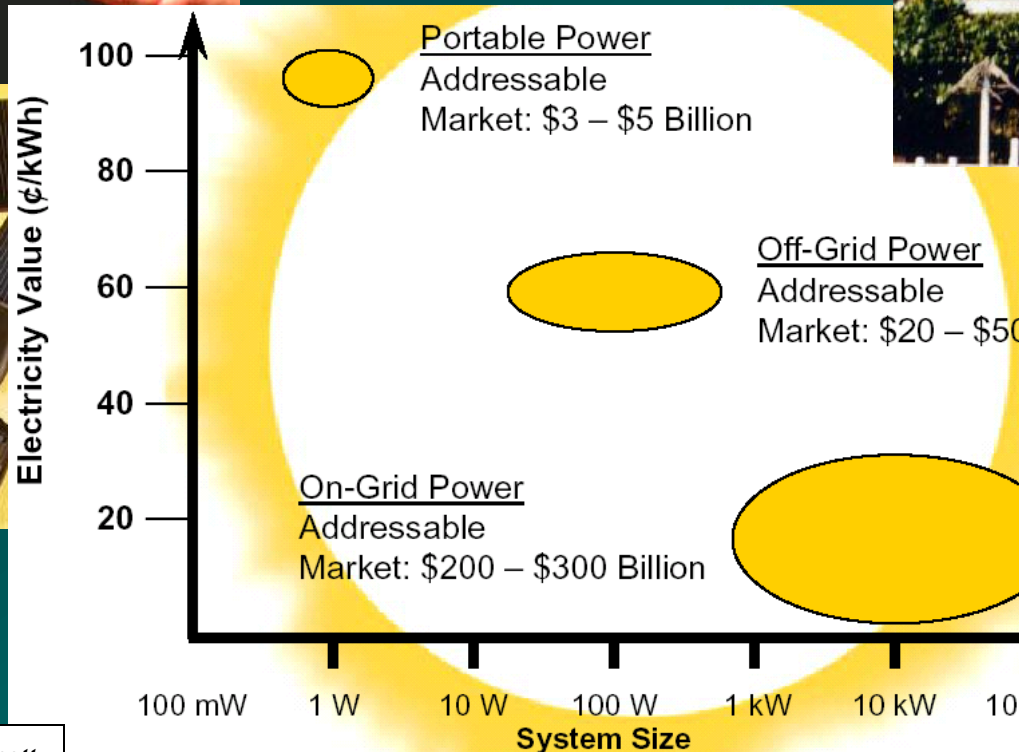
# New Markets



Off-grid  
Rural Applications



Off-grid  
Telecommunications



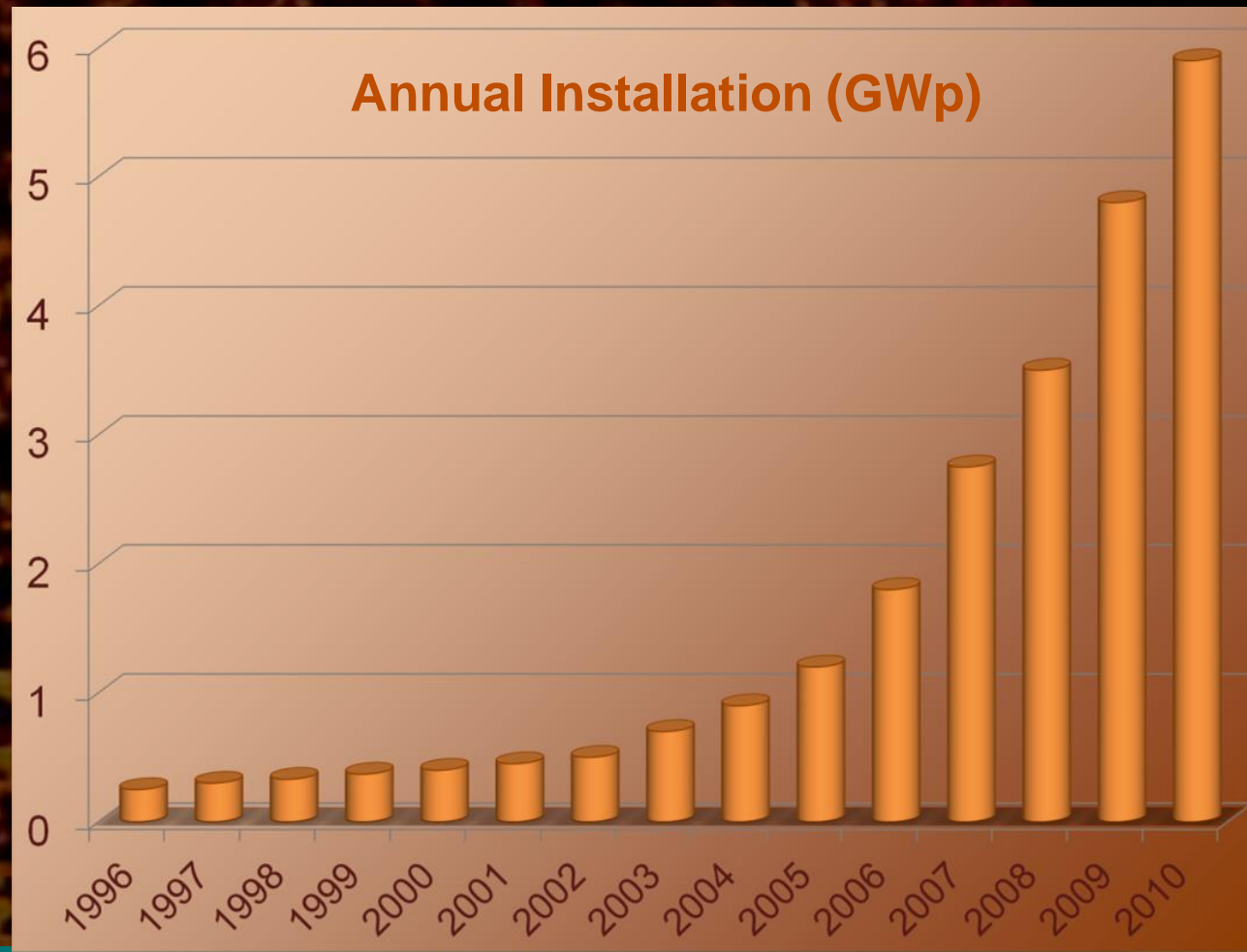
On-grid  
Residential and commercial



Allen Barnett

# Market size and growth

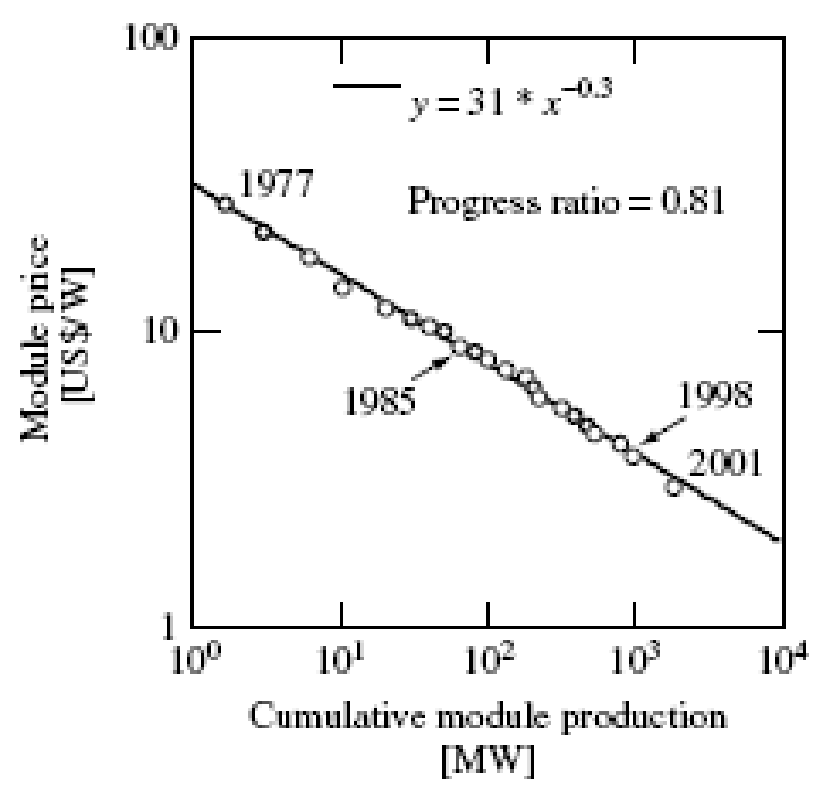
- World Market: € 15B
- Demand and supply growth: 35%/year
- Demand exceeds supply



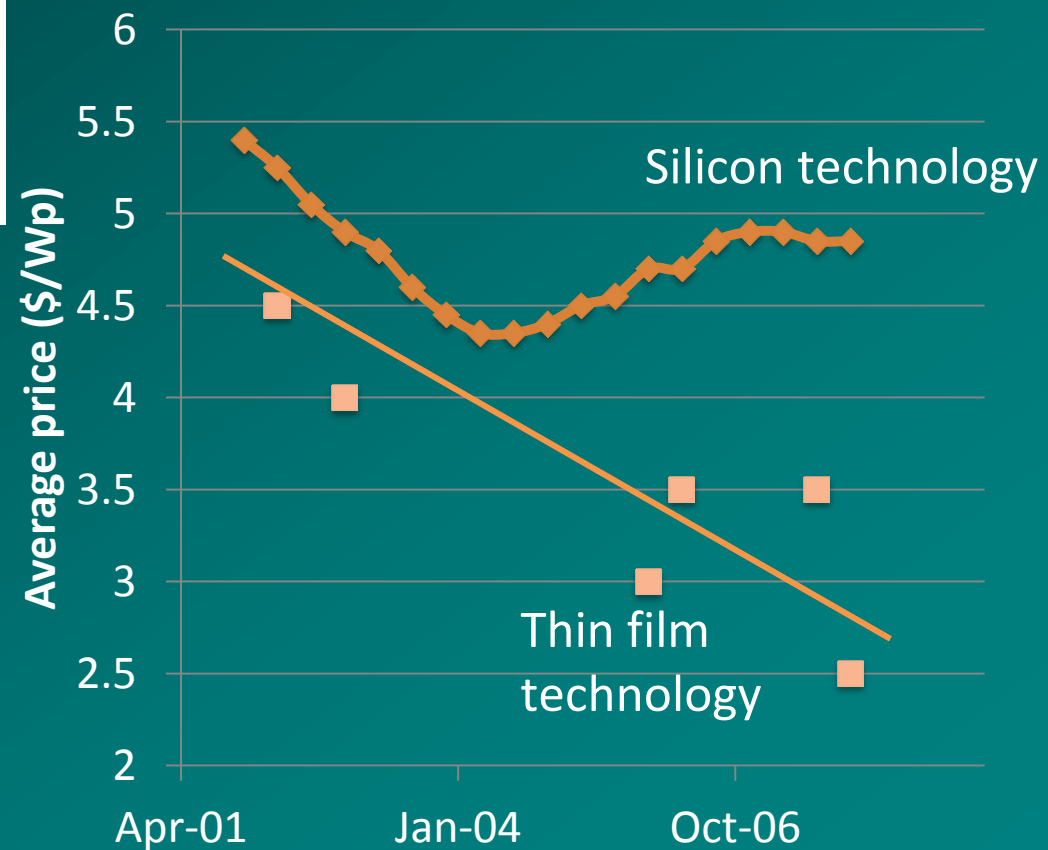
Trends in photovoltaic applications,  
Survey report of selected IEA countries  
between 1992 and 2005, report IEA-  
PVPS T1-15:2006

DOE Solar Energy Technologies  
Program, Multi-Year Program Plan 2007-  
2011, U.S. Department of Energy, Energy  
Efficiency and Renewable Energy

# Price



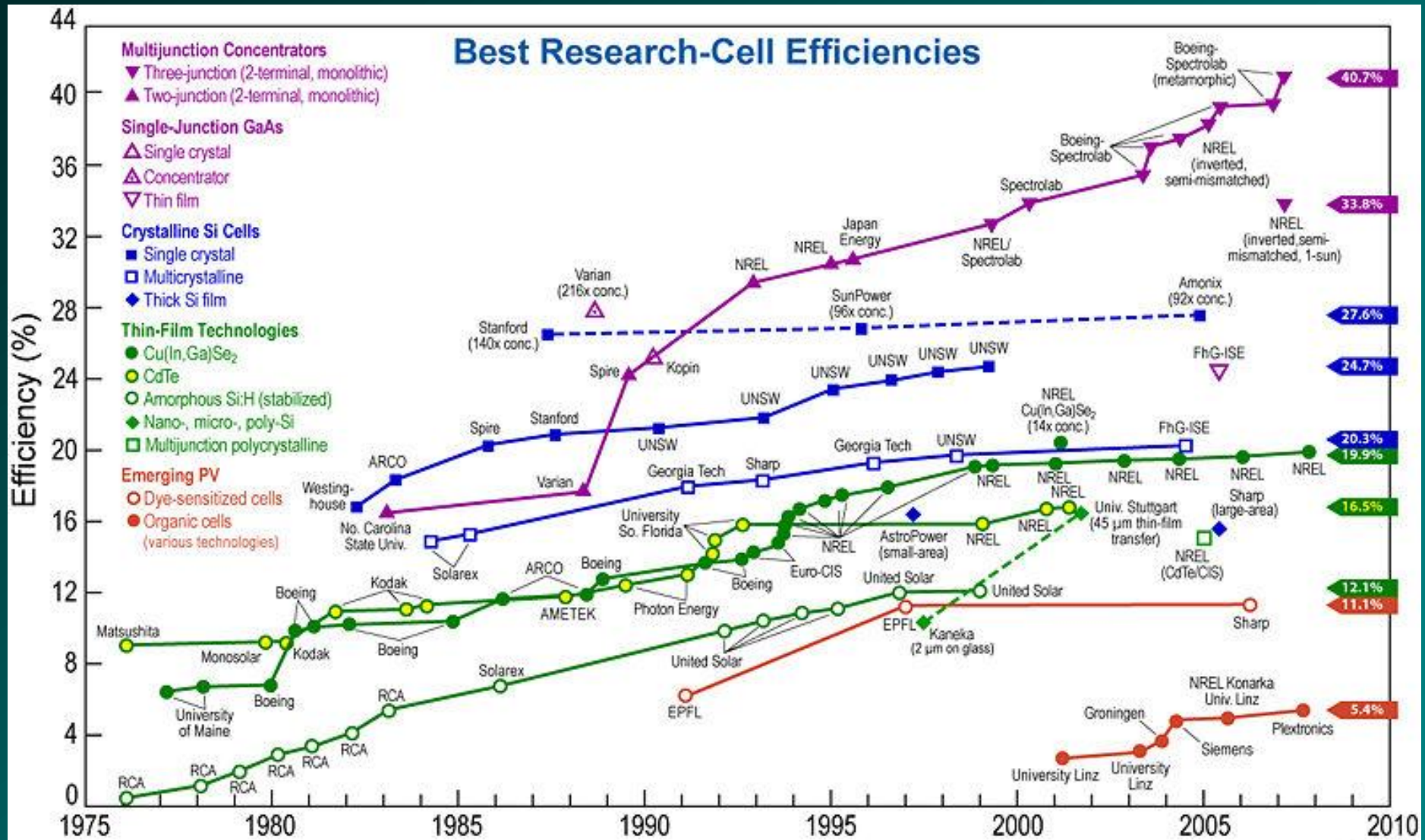
Learning curve: 80%





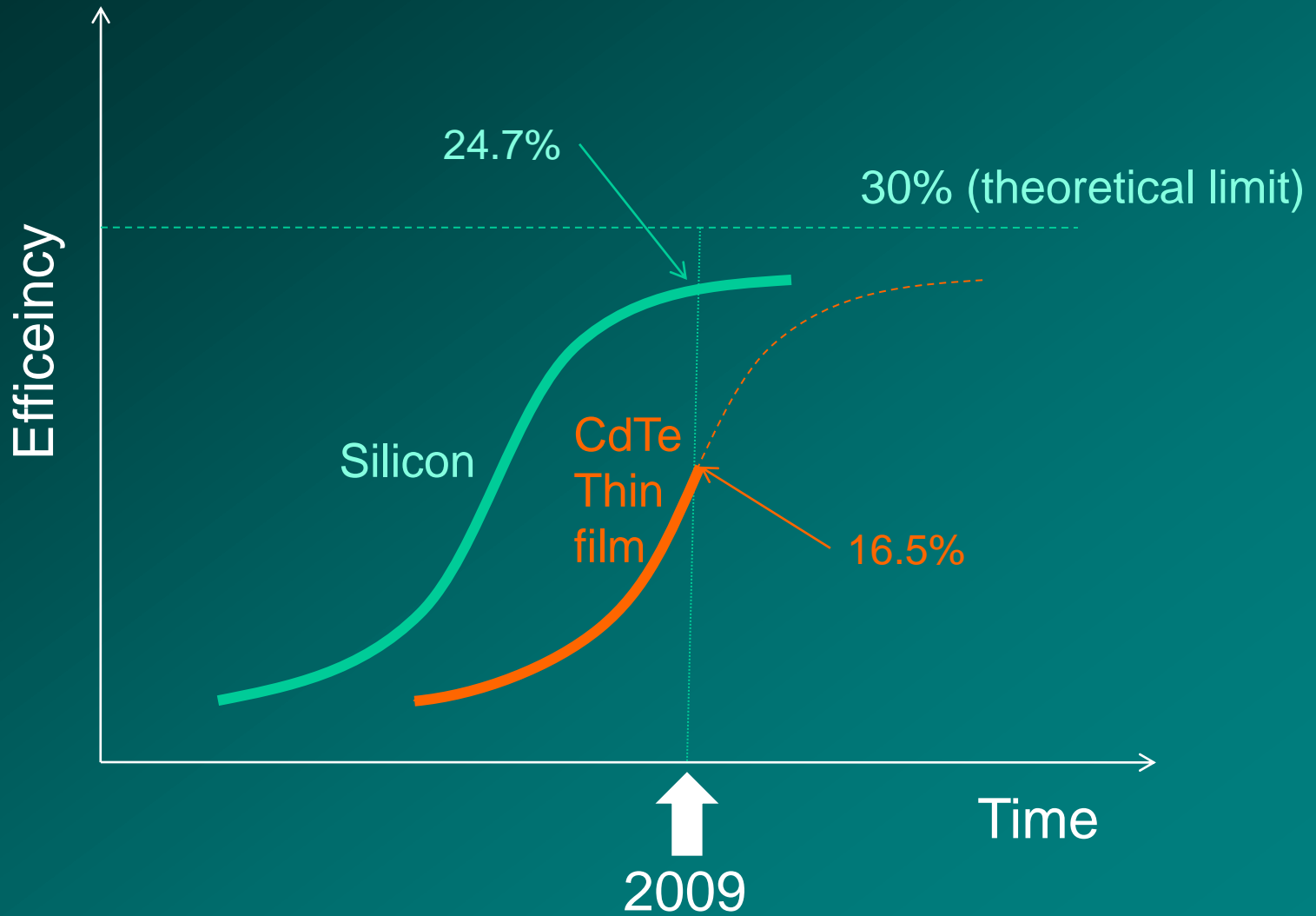
# Technological evolution

# Technology evolution: Efficiency increase



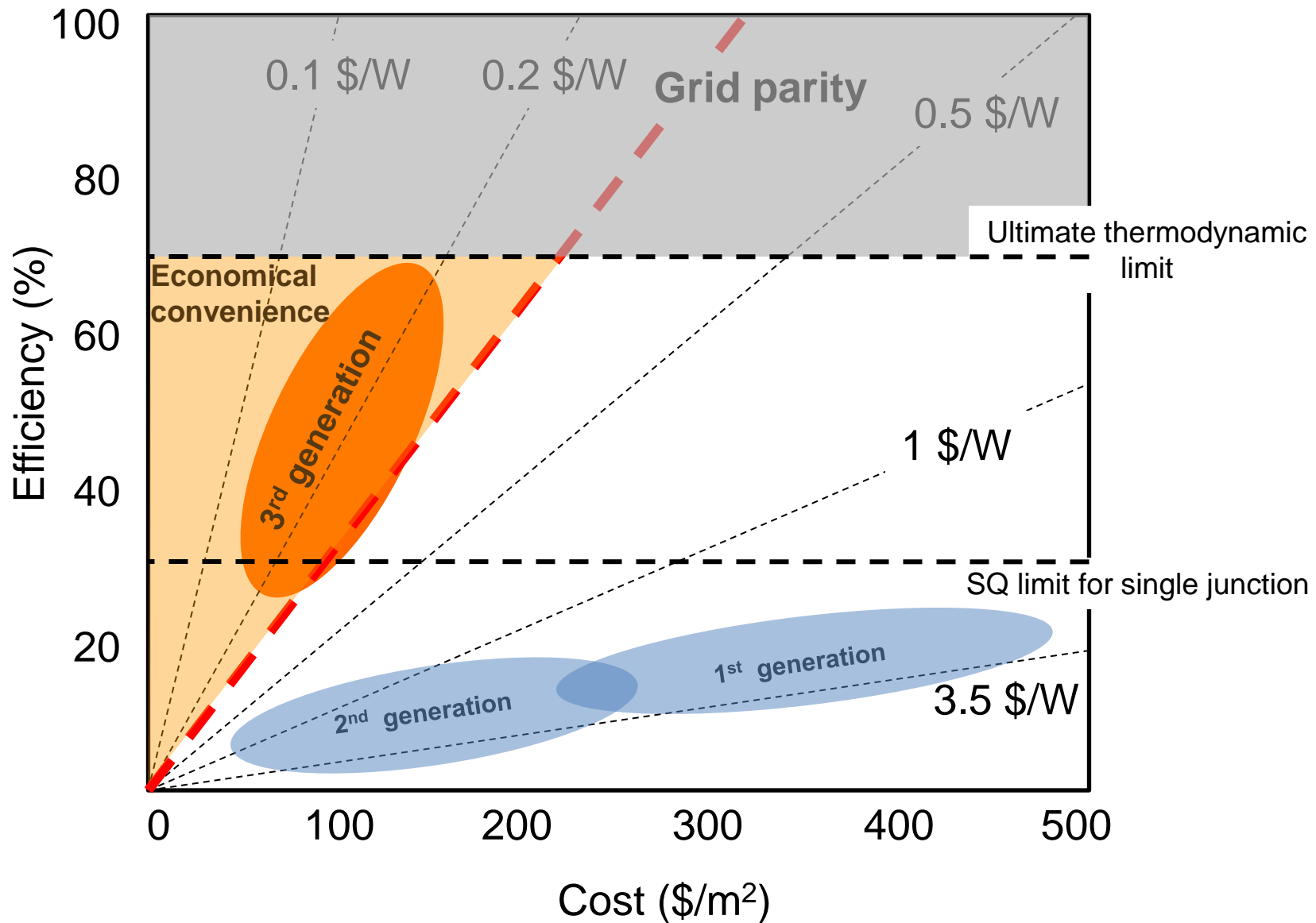
Rev. 11-07-07

# Technology evolution: Efficiency increase



# Tecno-Economical Evolution

## - Cost and Efficiency – PV Figures of Merit -



# Integration of PV



# Traditional Photovoltaic Installations





# Integration: Aesthetics

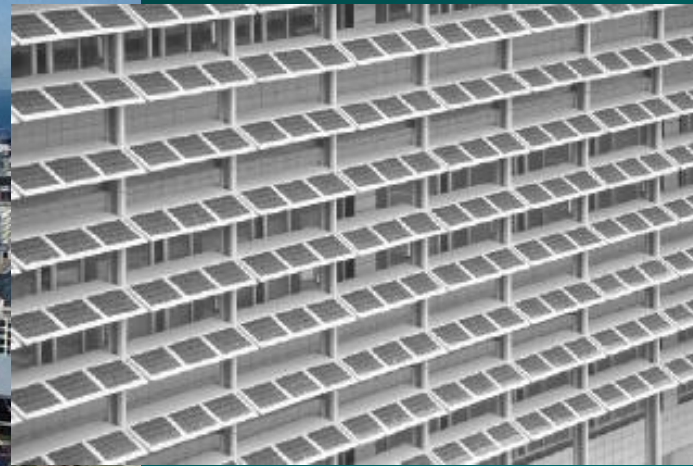


# Integration: Aesthetics





# Integration: Aesthetics & Function

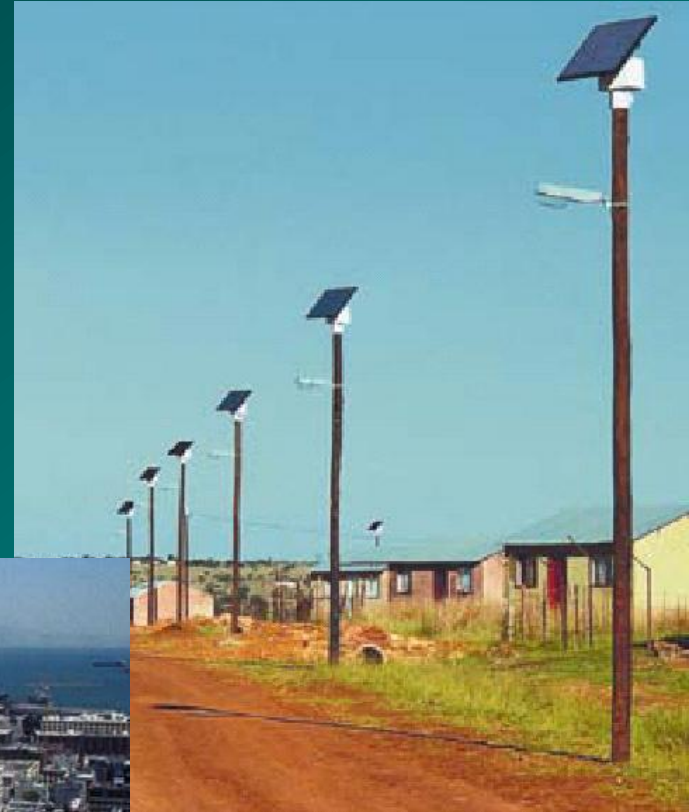




# Integration: Aesthetics & Function

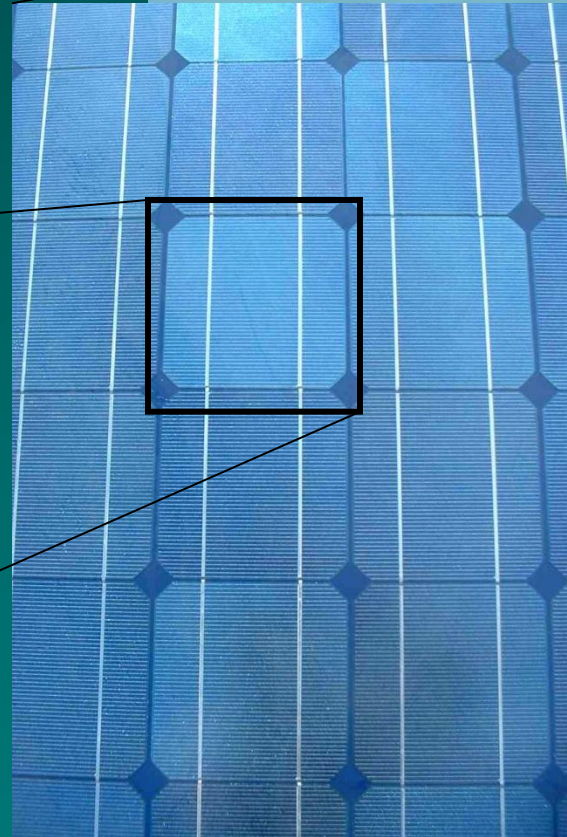
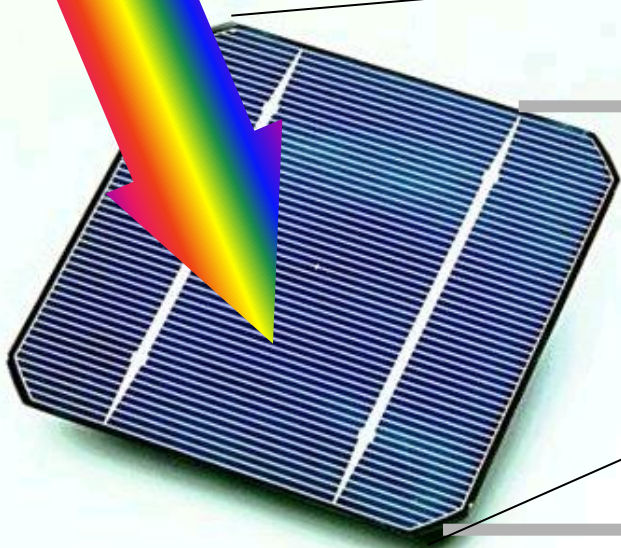


# Current PV Technologies

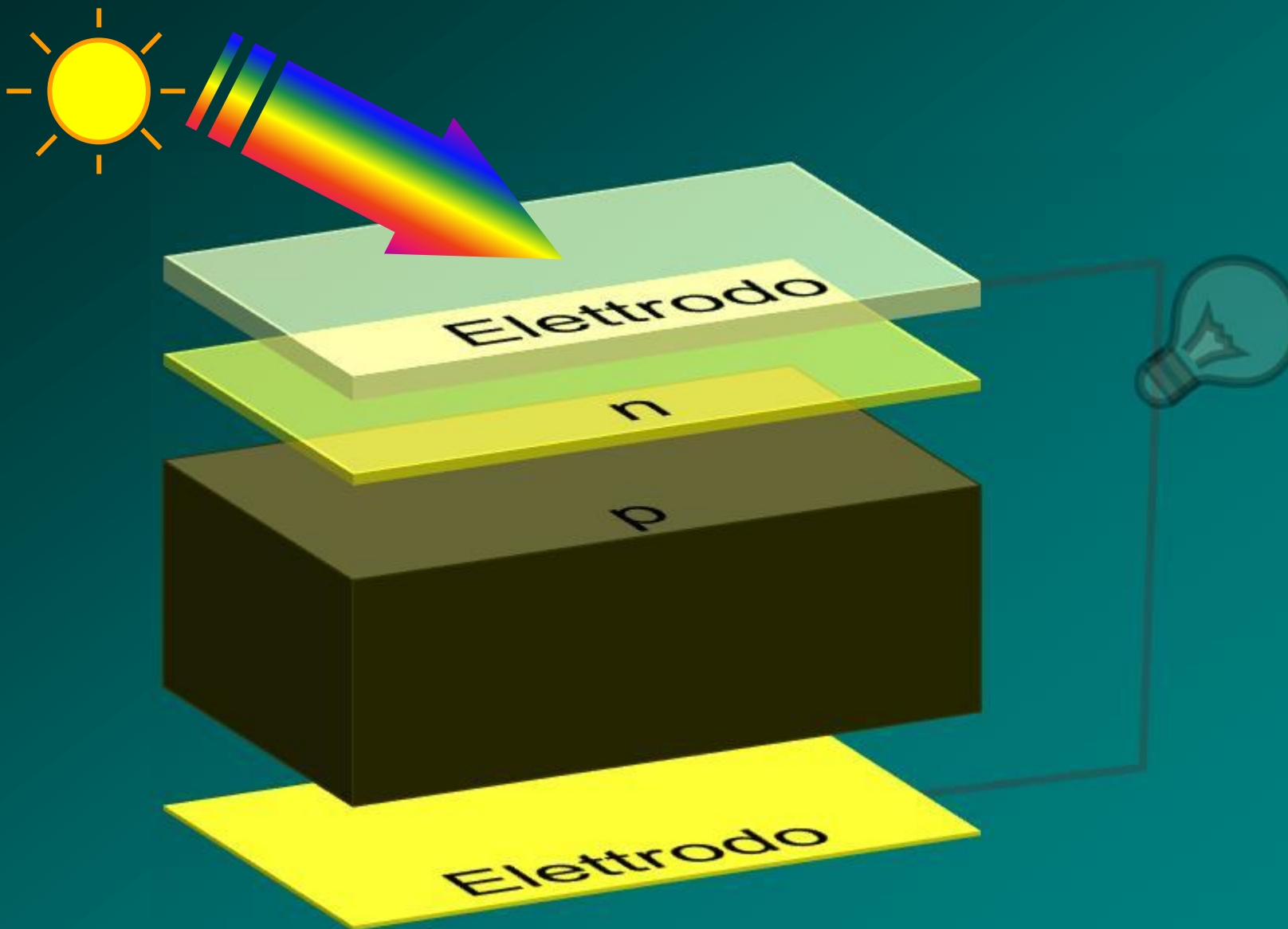




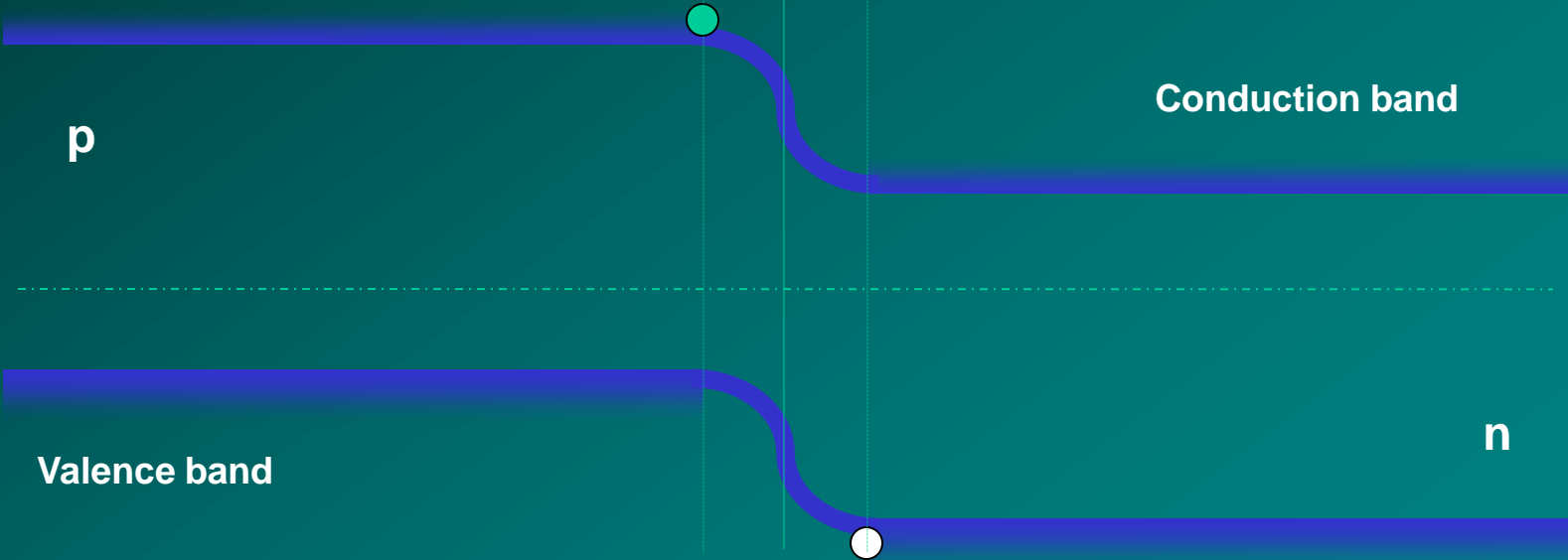
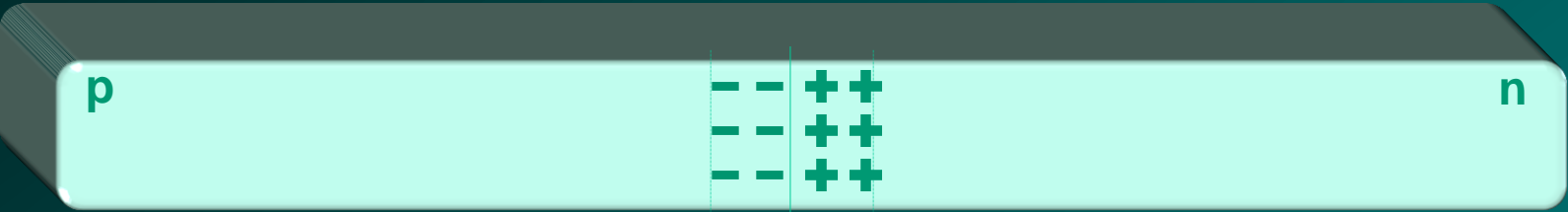
# Photovoltaic Effect



# Photovoltaic Effect



# p-n junction



Spatial coordinate

Energy

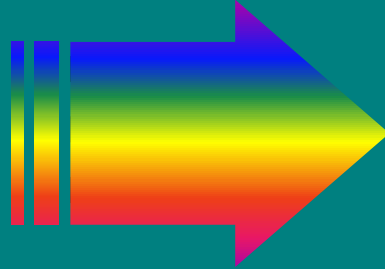
# Photovoltaic Effect

1.

Absorption of solar radiation

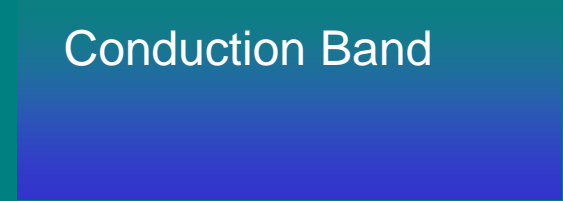


Creation of free carriers



+

Conduction Band



Valence Band



-

Energy ↑

2.

Free carrier transport and extraction



Electrical energy



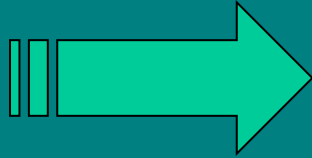
# Photovoltaic Effect Choice of materials

1.

Absorption of  
solar radiation



Creation of  
free carriers



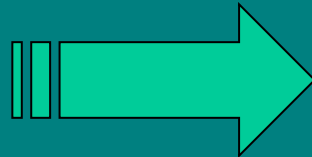
- Materials with good absorption of the solar radiation

2.

Free carrier  
extraction



Electrical energy

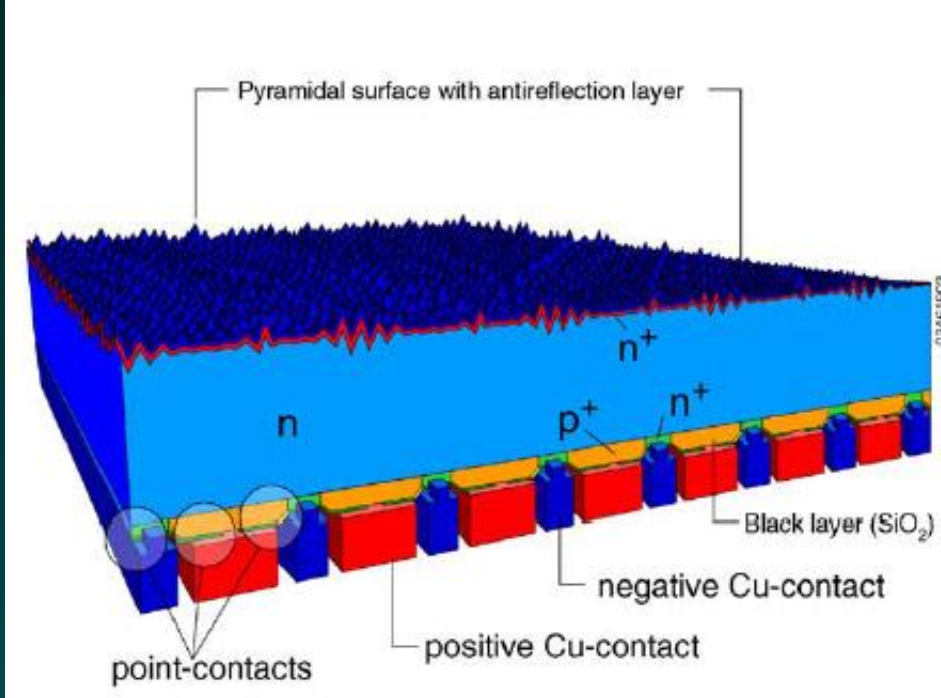


- “Perfect materials”  
(large mean free paths  
for the carriers)
- Short carrier paths

# Silicon technology



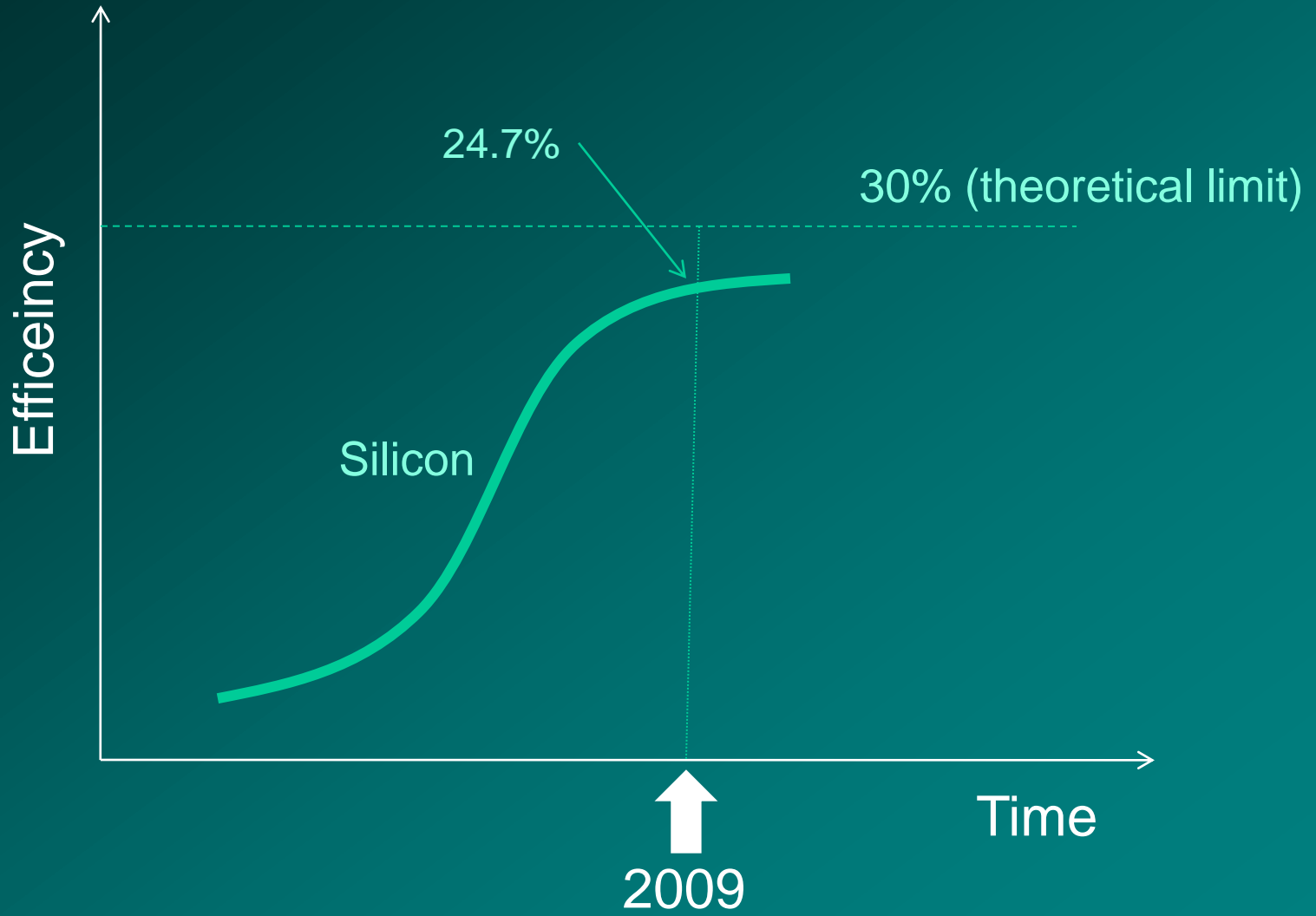
# Silicon technology – Record performance



	Single crystal silicon	Polycrystalline
Cell Record	24.7%	20.3%
Module record	22.7%	15.3%
Commercial modules	15-18%	12-15

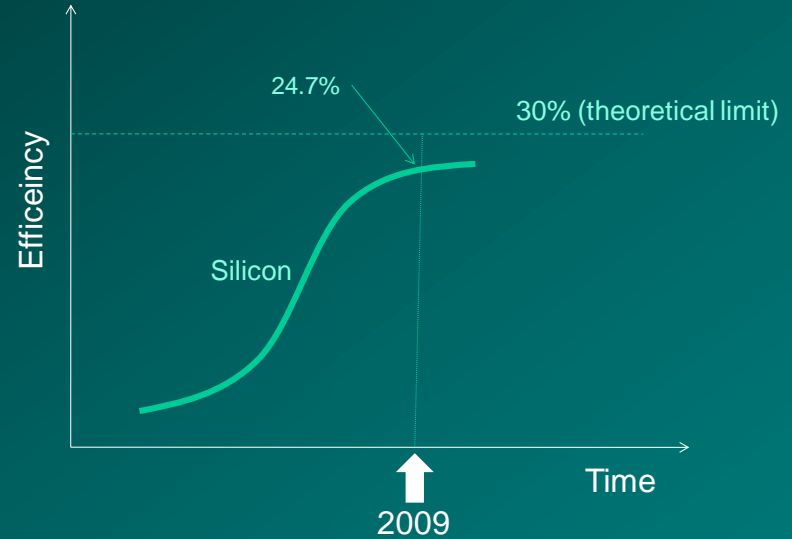


# Silicon Technology

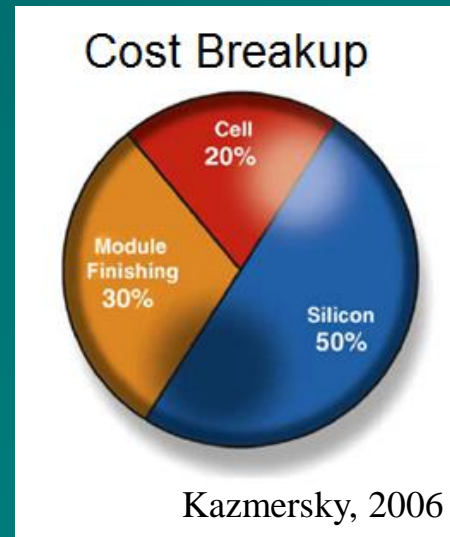


# Silicon Technology - Summary

- Mature Technology  
(max efficiency > 80% thermodynamic limit)



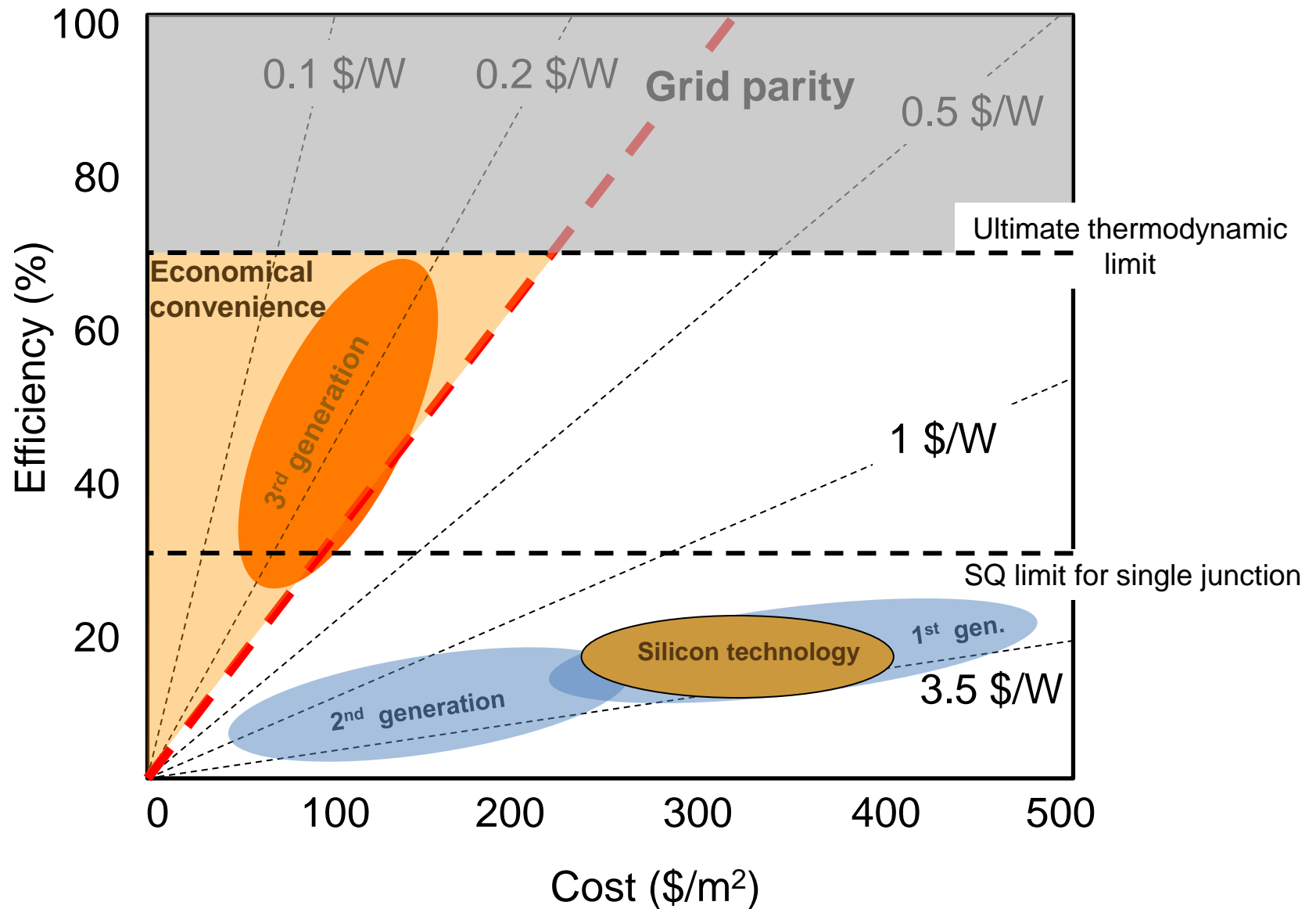
- Large quantities of pure silicon are needed  
➡ high cost of raw material



- Limitation in raw material supply

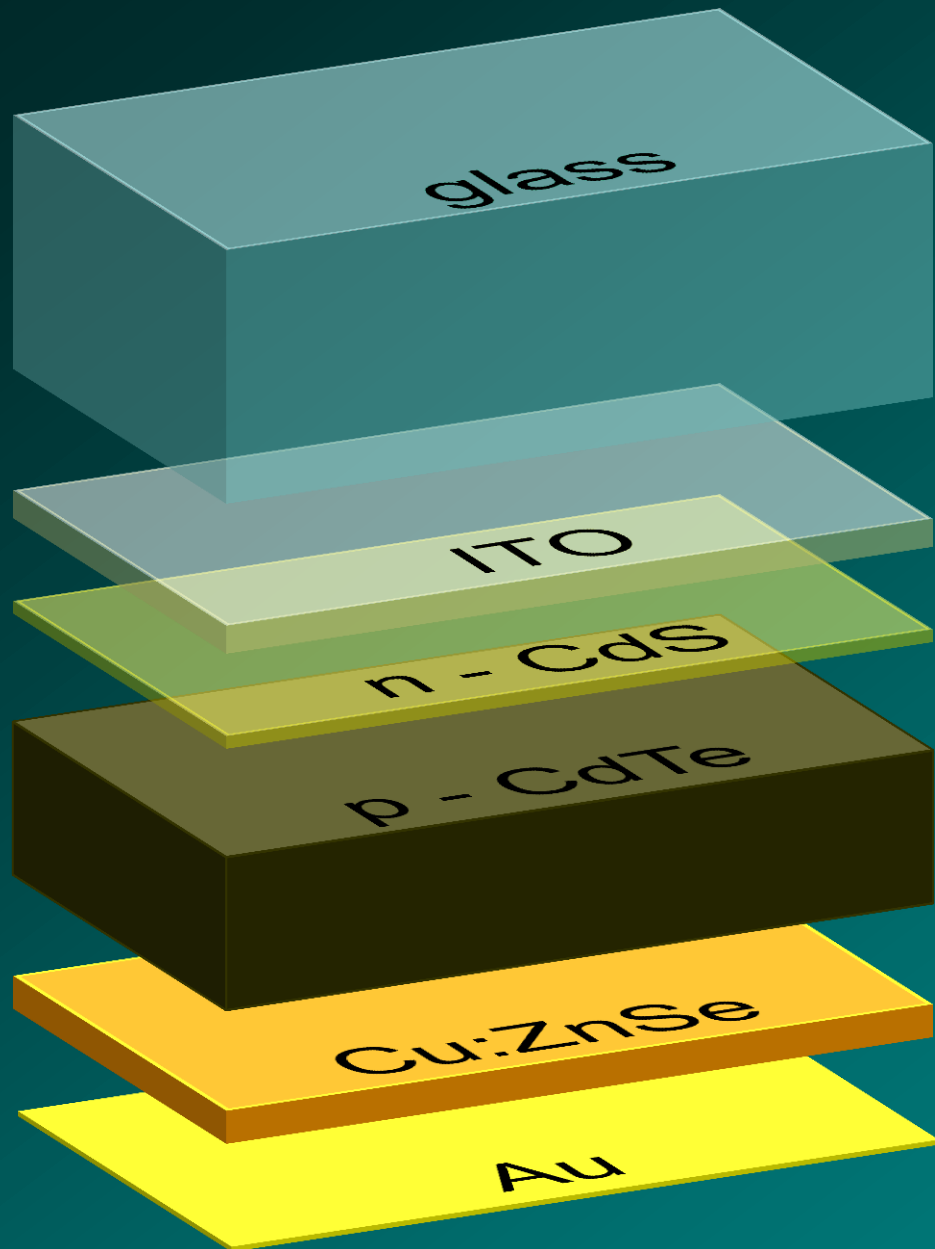
# Tecno-Economical Evolution

## - Cost and Efficiency – PV Figures of Merit -





# Thin Film Solar Cells



Materials with:

- high absorption coefficient
- good match with the solar spectrum (1.5 eV)



- Less active material is needed (thin films: 0.1 – 10  $\mu\text{m}$ )
- Lower cost
- Less problems with supply of raw materials
- Short carrier paths (perfection requirements are relaxed)

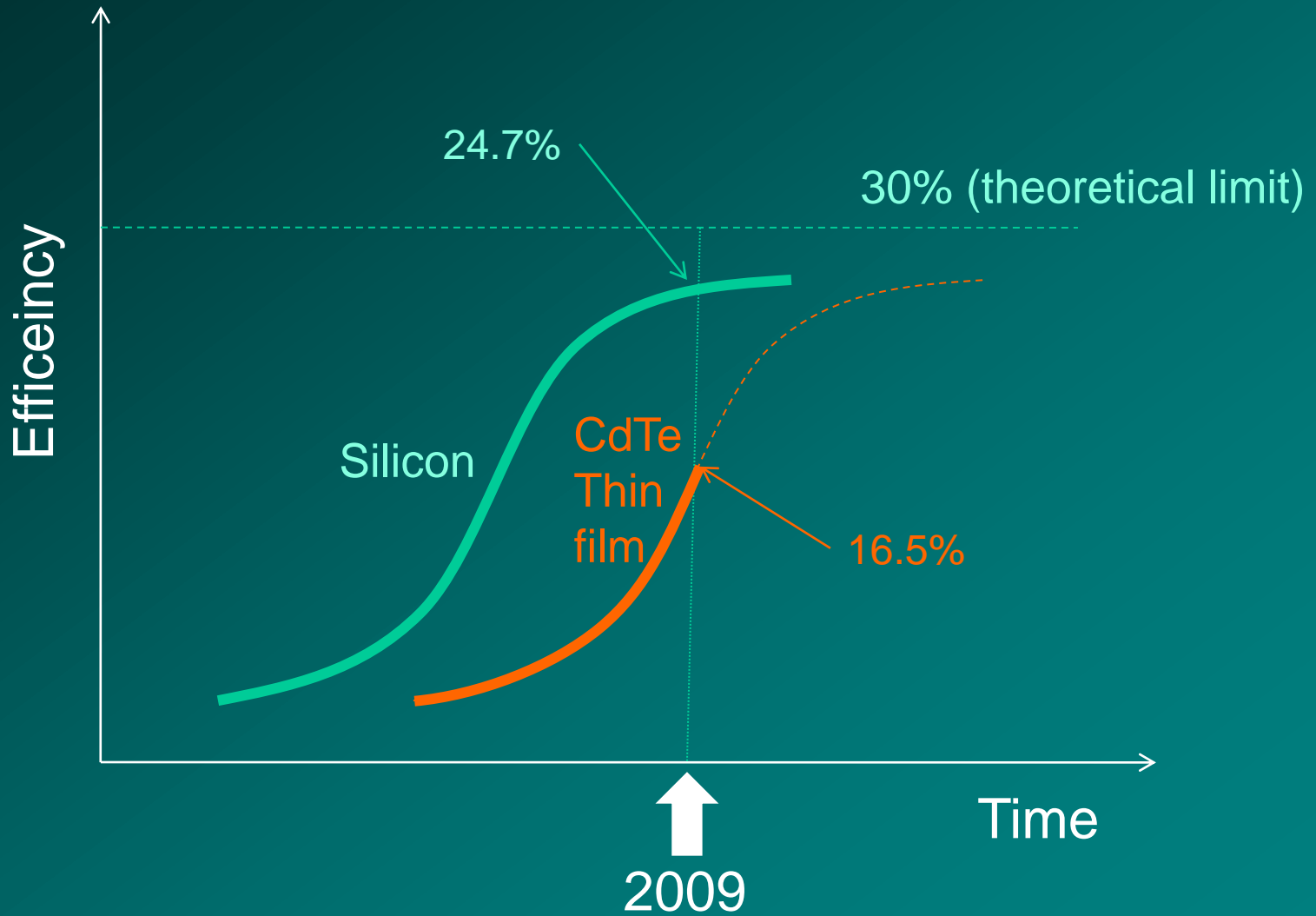
# Thin Film Solar Cells

Medium efficiency – Low Cost



	CdTe	CIGSS	Amorphous Si
Cell Record	16.5%	19.5%	9.5%
Module record	10.7%	13.4%	--
Commercial modules	8-10%	--	4-7%

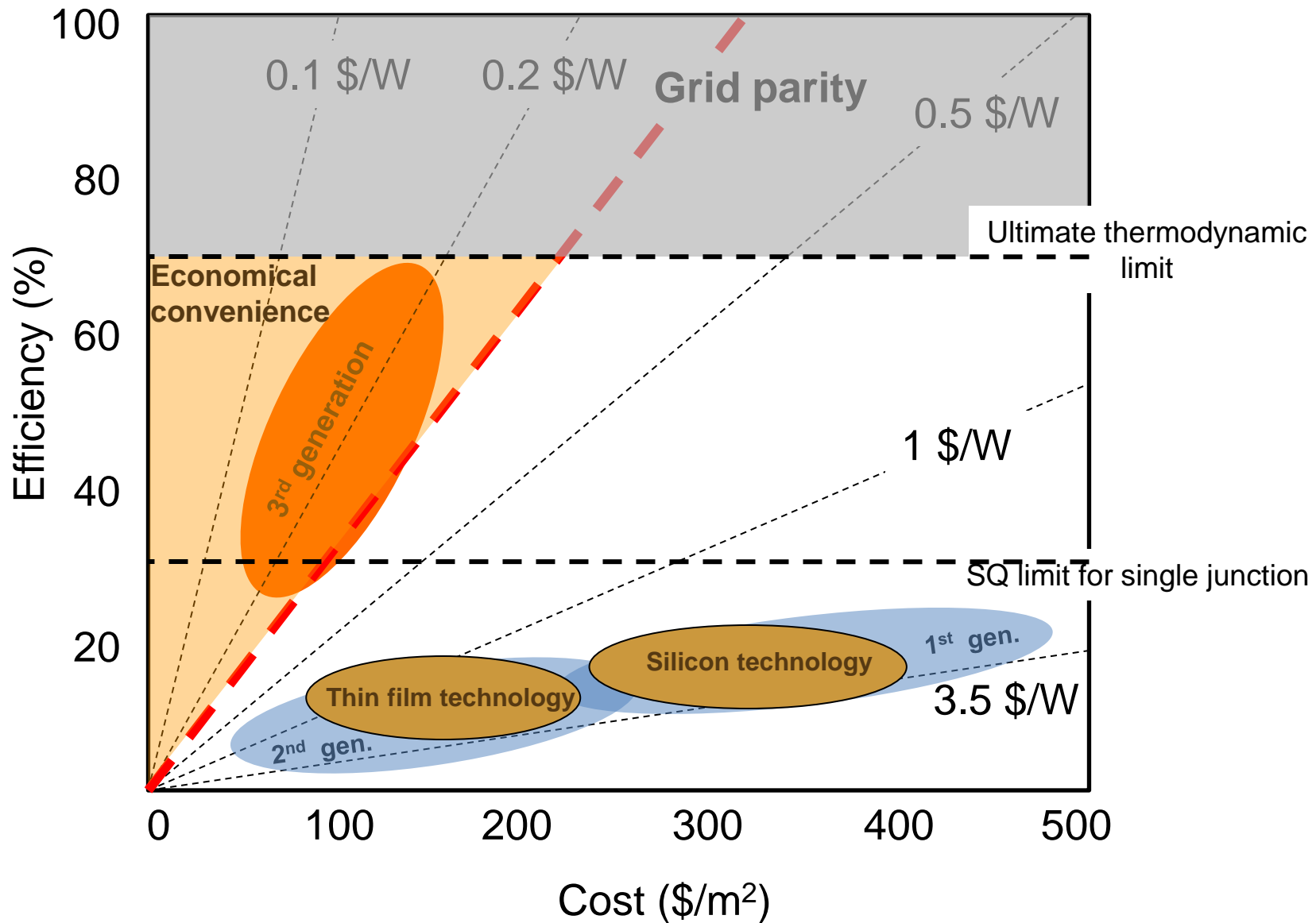
# Technology evolution: Efficiency increase





# Tecno-Economical Evolution

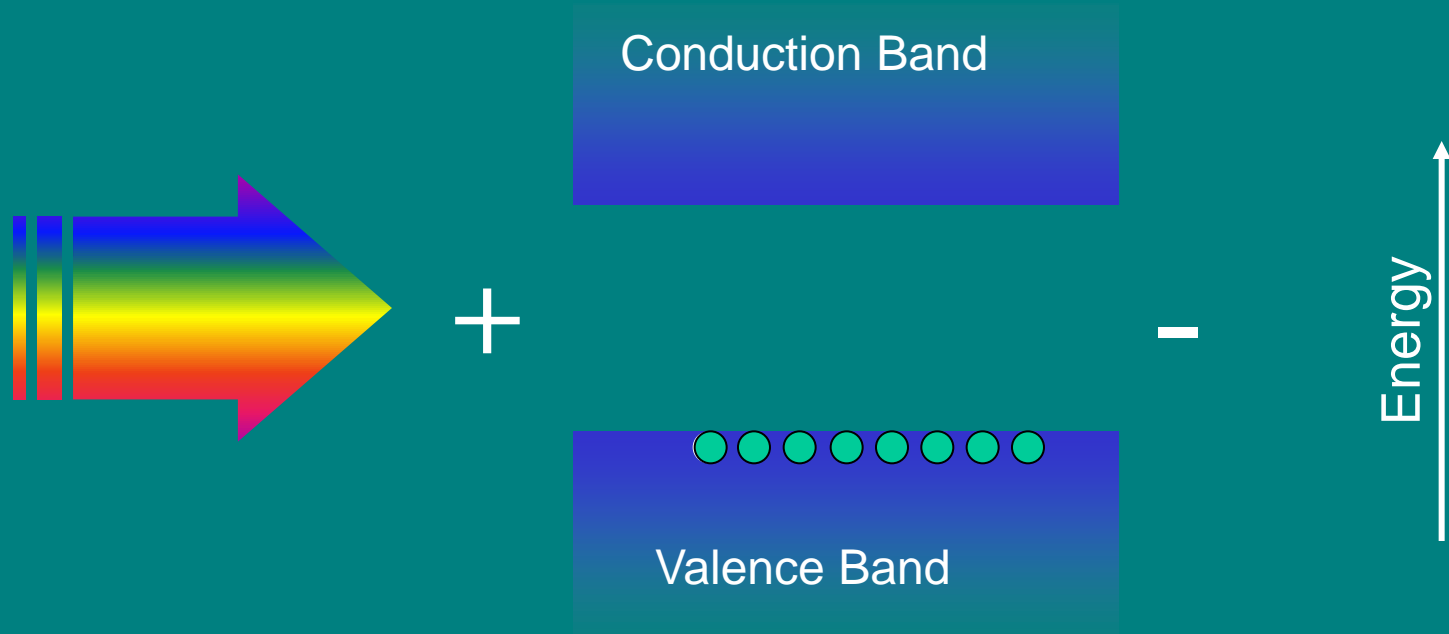
## - Cost and Efficiency – PV Figures of Merit -



# Thin Film Solar Cells

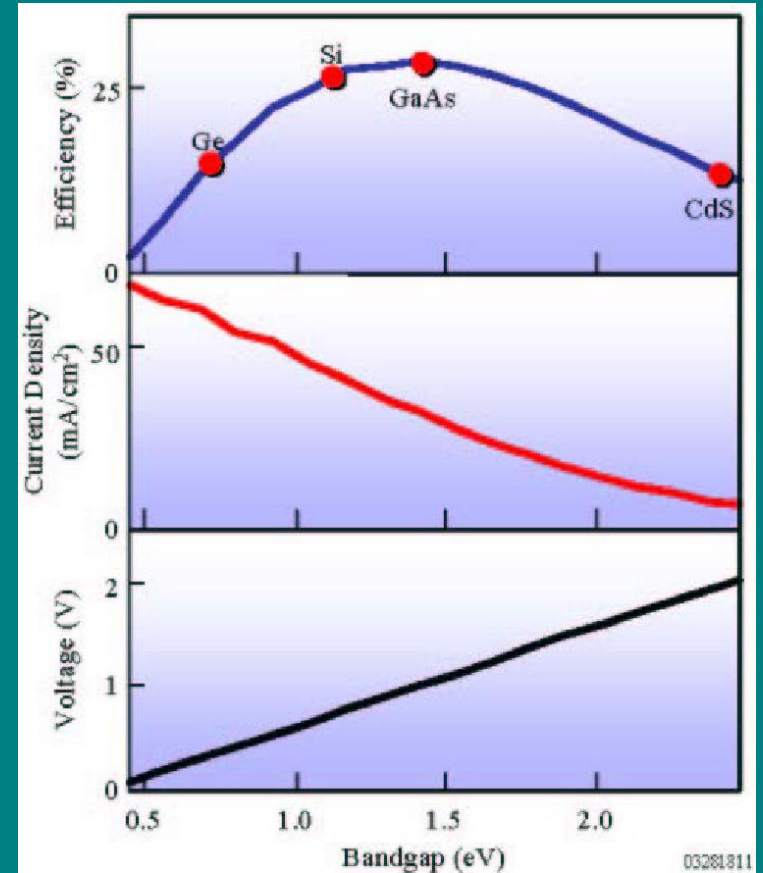
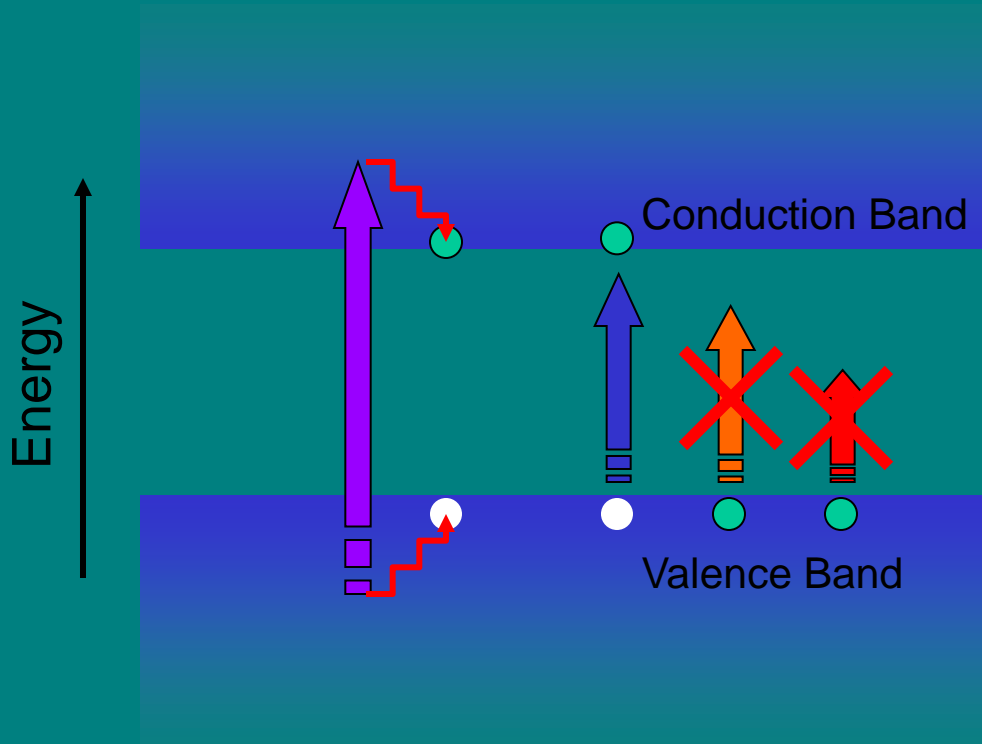
- **Young Technology**(max efficiency is 30-40% of thermodynamic limit)
- **Films can be deposited on various substrates**  
(flexible, architectural elements for building integration, etc.)
- **Low Cost**
- **Thermodynamic limit is still 30%**
- **Nanotechnology-based films are currently reaching the market**

# PV efficiency: Thermodynamic limit



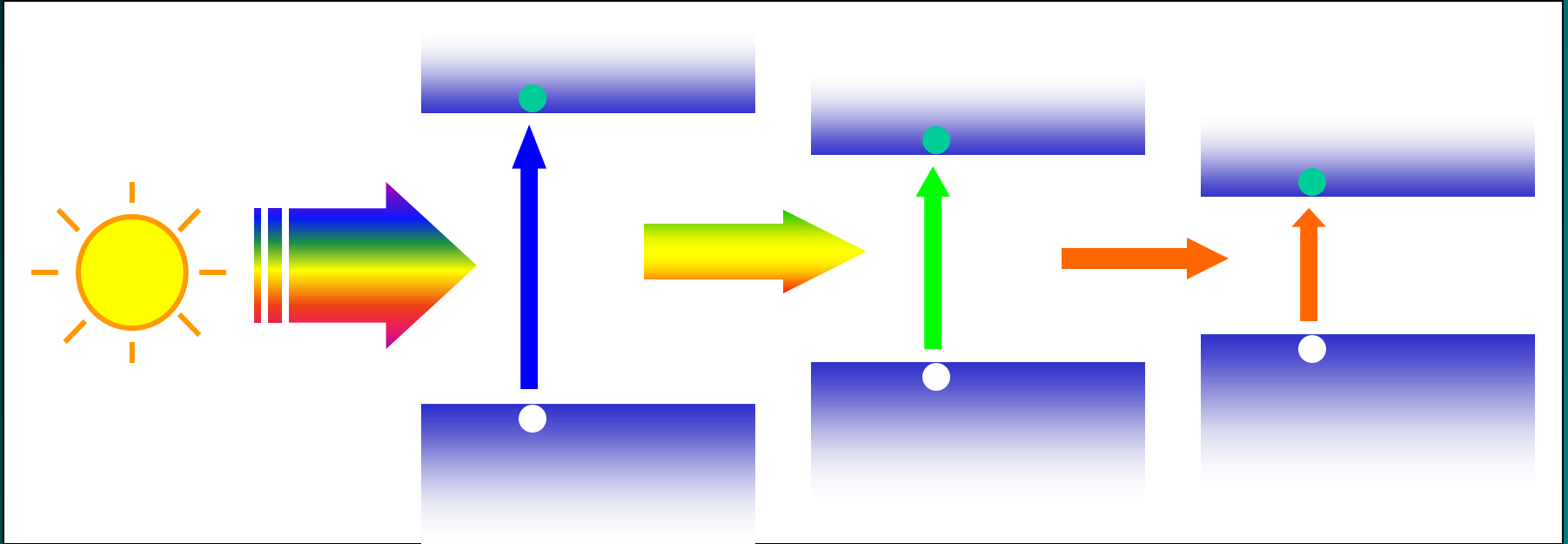


# PV efficiency: Thermodynamic limit



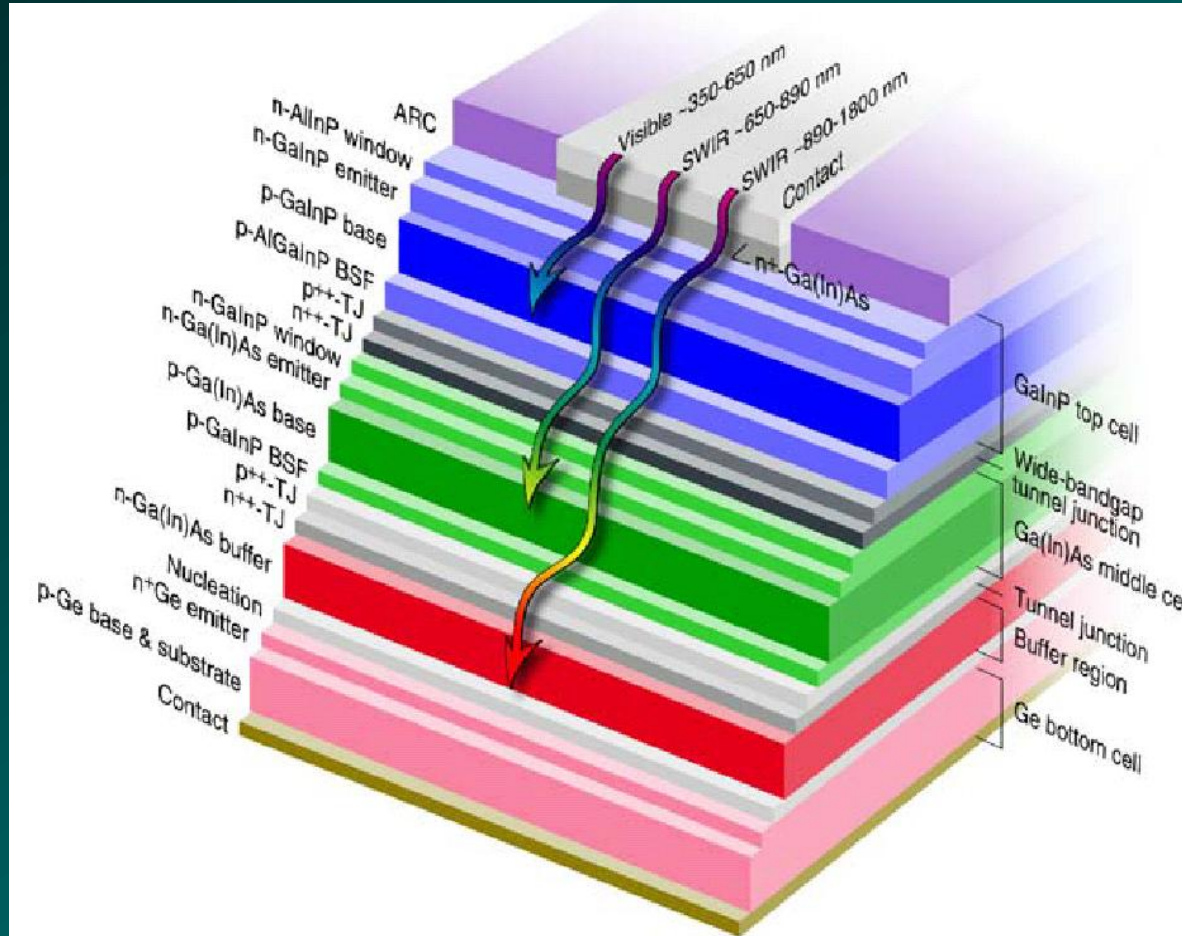
Max efficiency: 30%

# Beyond The Single Junction Limit: Tandem cells



More efficient use of the solar spectrum

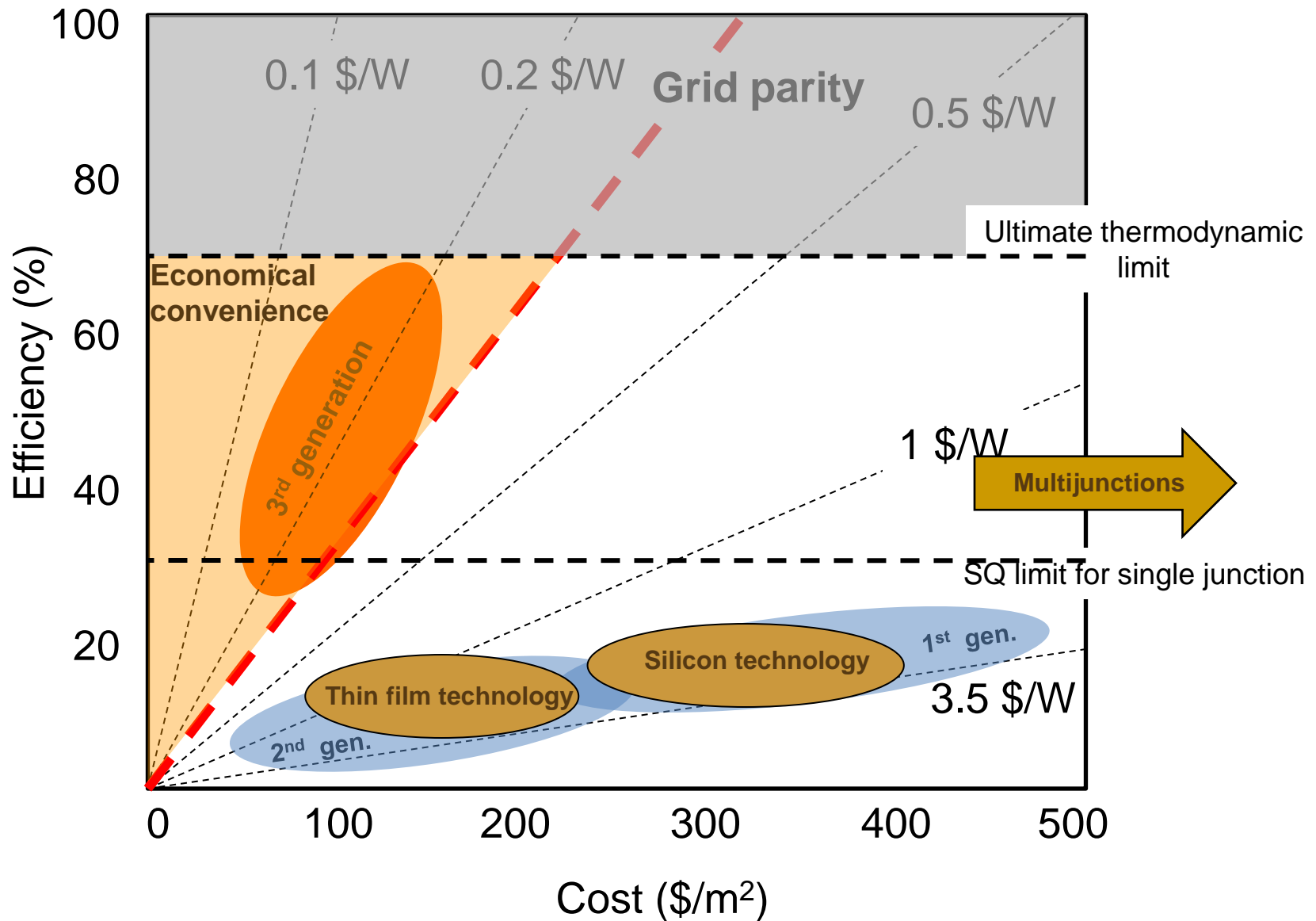
# Tandem Cells



- Current efficiency record > 40%
- Multijunction cells – very expensive
- Aerospace applications or terrestrial concentration


# Tecno-Economical Evolution

## - Cost and Efficiency – PV Figures of Merit -

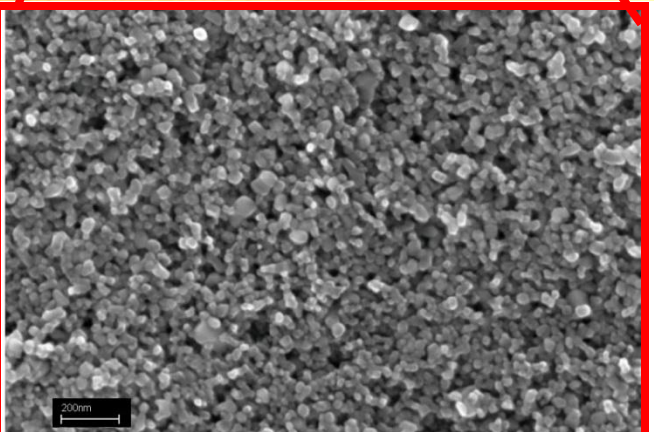
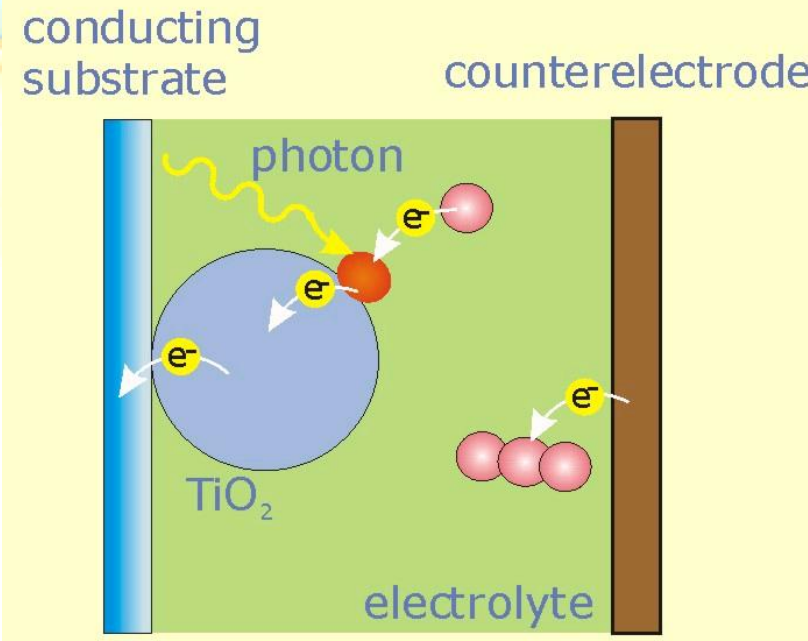
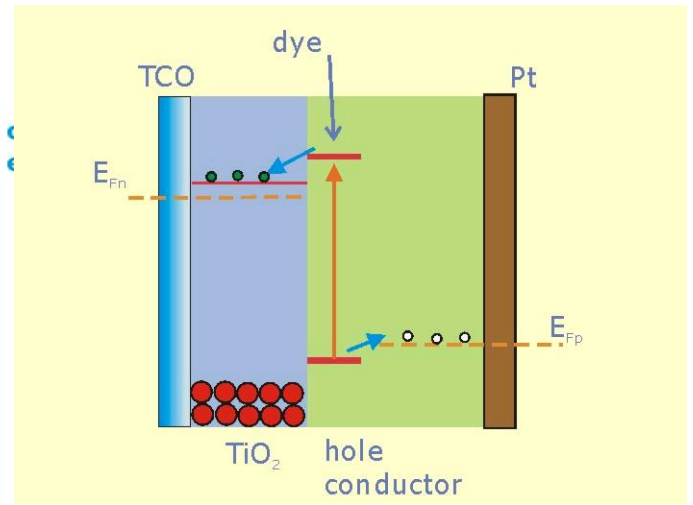
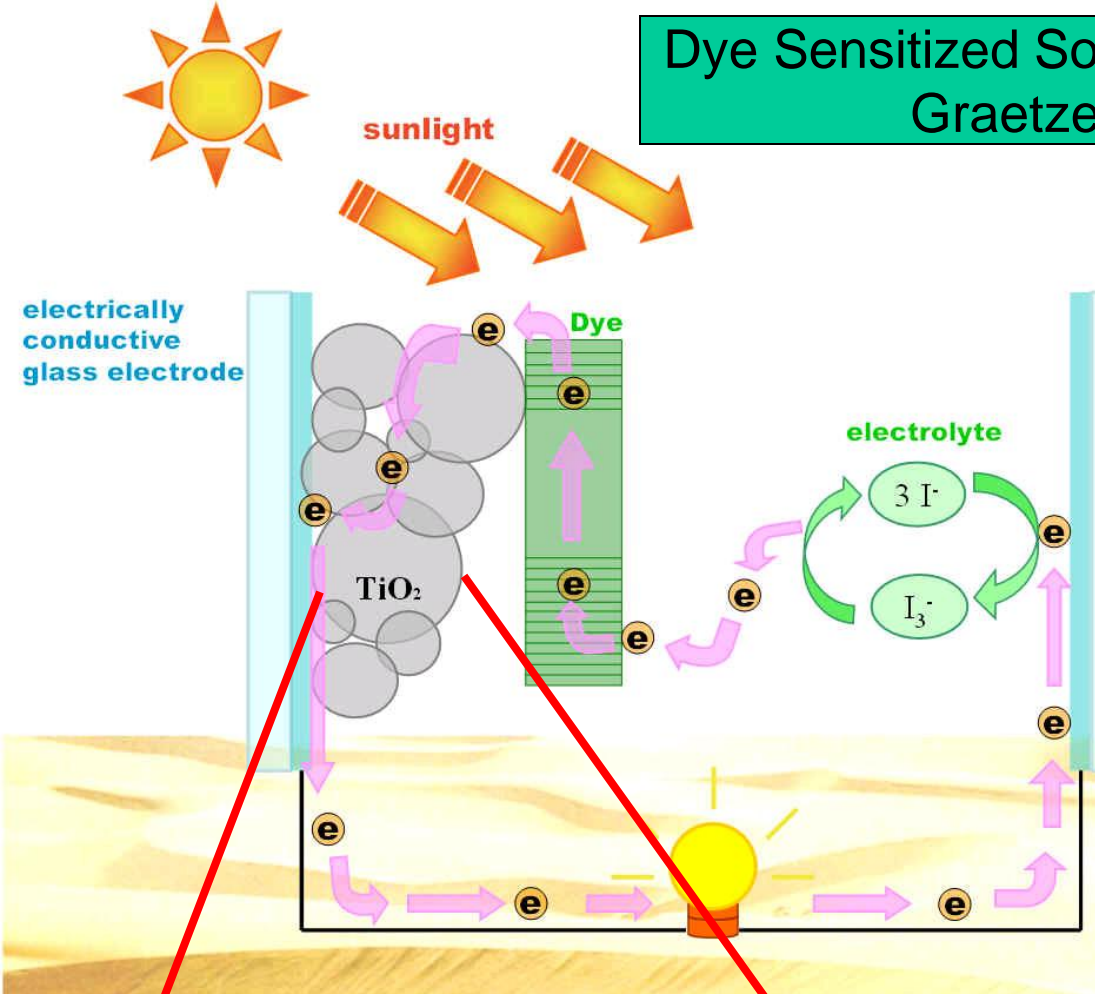




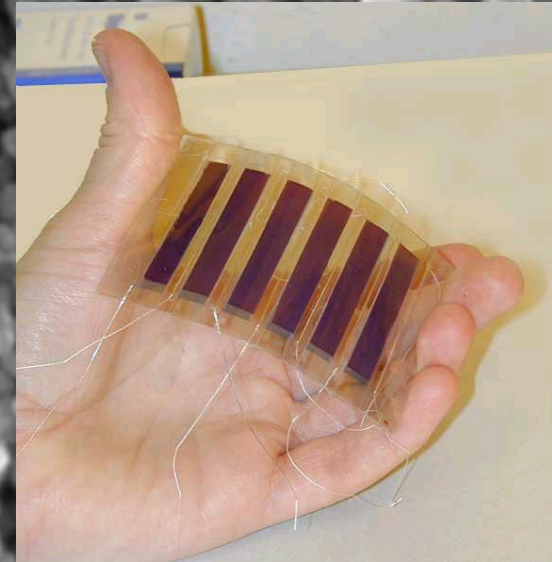
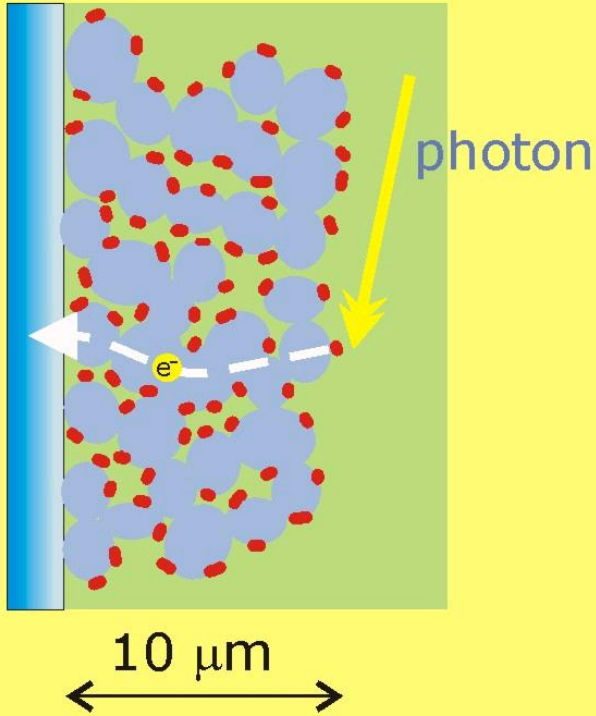
# Why nanotechnology?

- Morphological advantages (surface area)
  - Phenomena that govern optoelectronic properties of materials **occur at the nanoscale**
  - Phenomena at the nanoscale are governed by the laws of quantum mechanics
-  new opportunities for controlling material properties

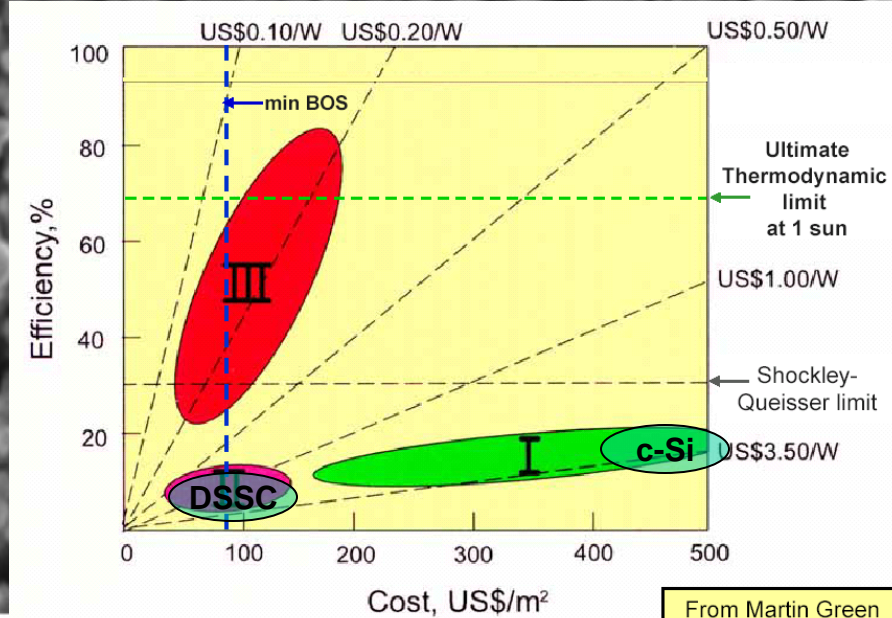
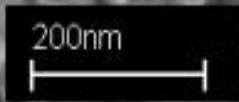
# Dye Sensitized Solar Cell (DSSC) Graetzel Cell



# Dye-sensitized solar cell (DSSC) – Grätzel cell



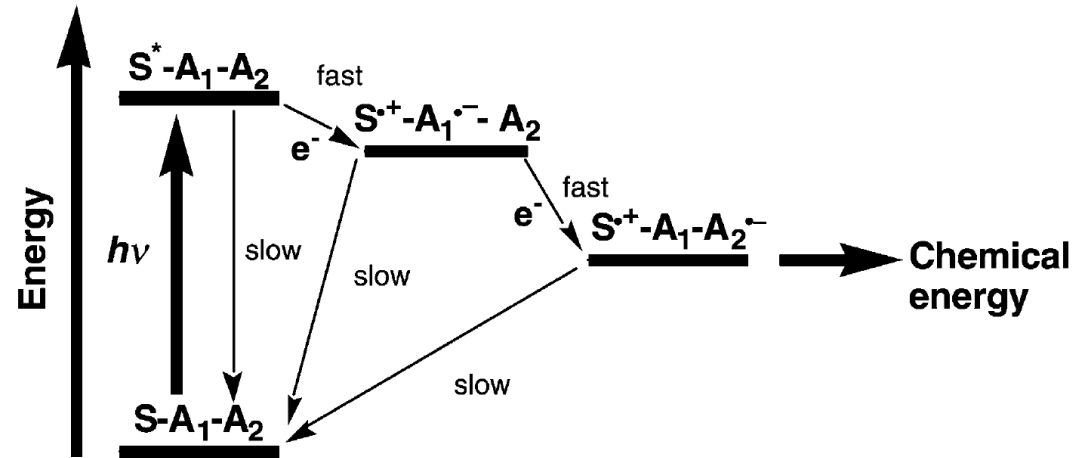
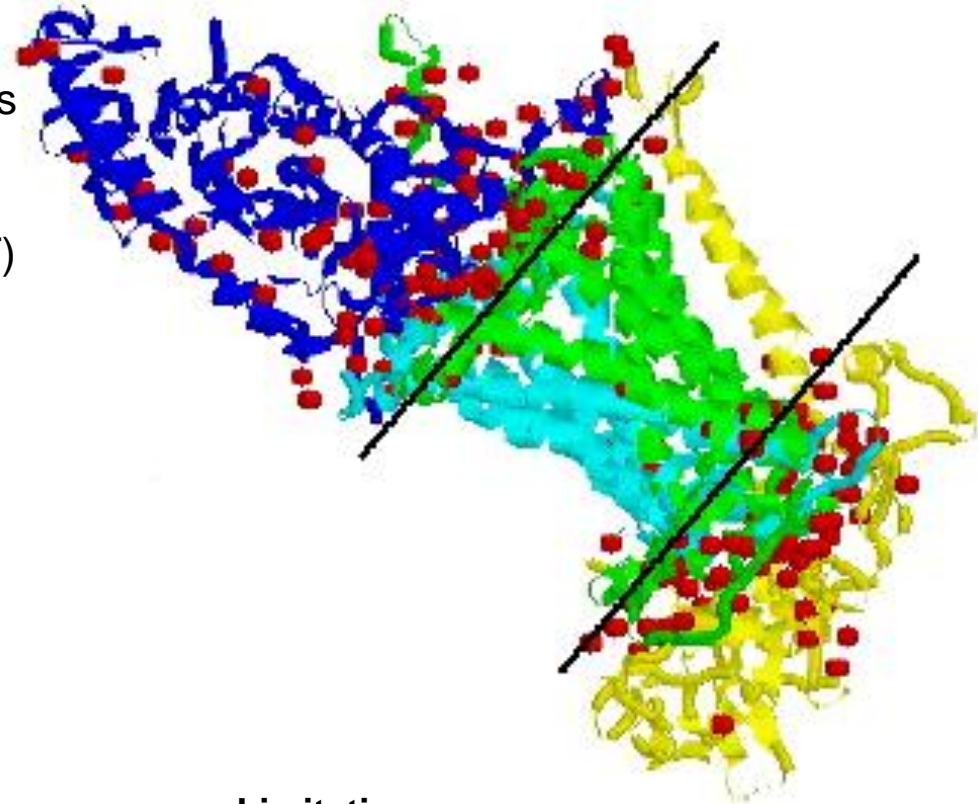
- Efficiency ~ 5 - 10%
- Liquid electrolyte





# Photosynthesis

- Energy is absorbed by the *antenna* complexes
- Cascade of **energy** transfer between donors and acceptors embedded in antennas (FRET)
- Energy is funneled to the reaction center
- Subsequent multistep **electron** transfer
- This creates a charge-separated state which lasts for 10s of  $\mu$ s or more, with a  $\sim 100\%$  QE

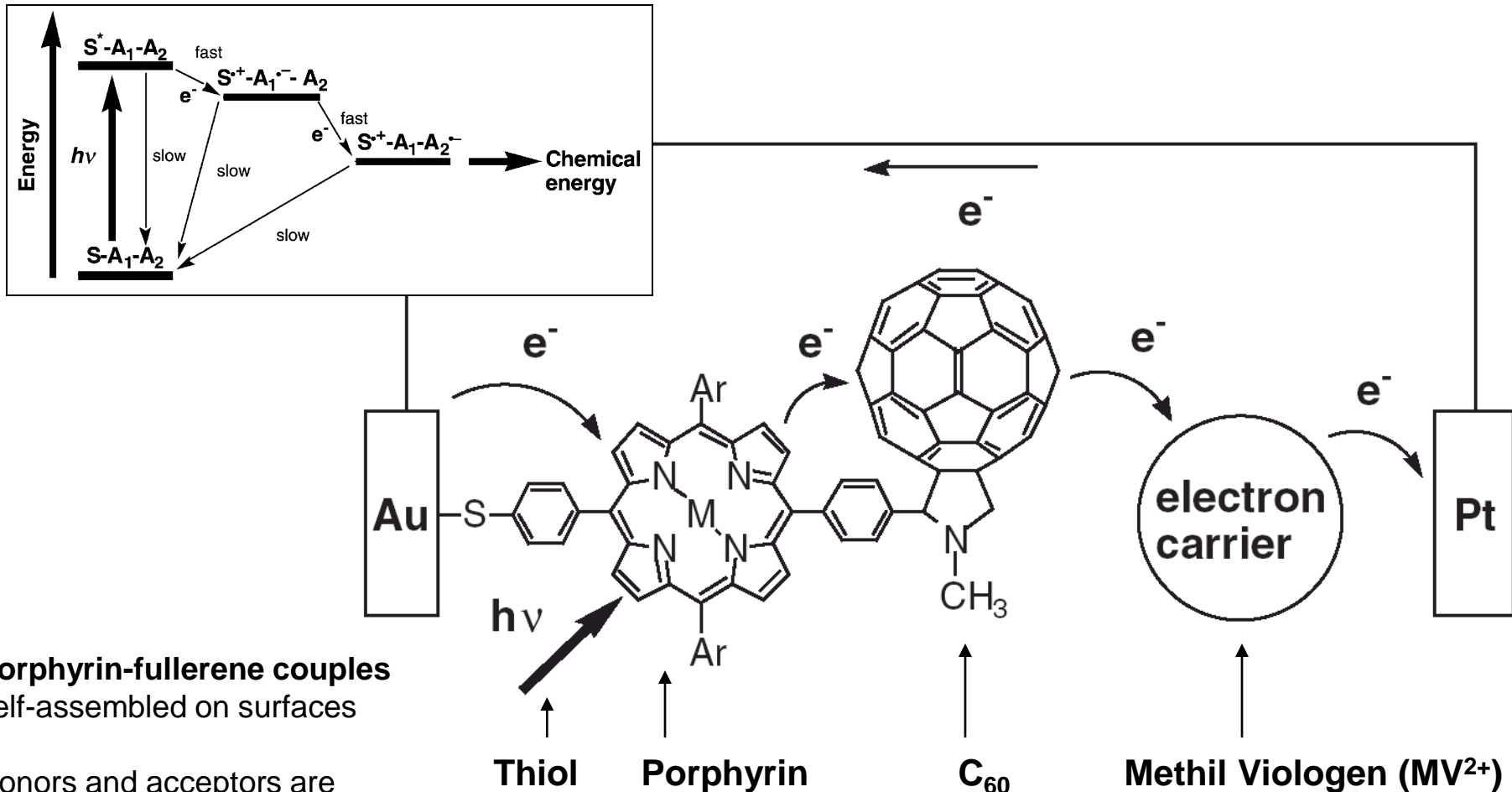


## Limitations

- Absorption is only efficient at specific wavelengths
- To reach the charge-separated state the electron needs to spend energy
- Energy converted in chemical energy  $\sim 9\%$



# Artificial Photosynthesis: Basic Example



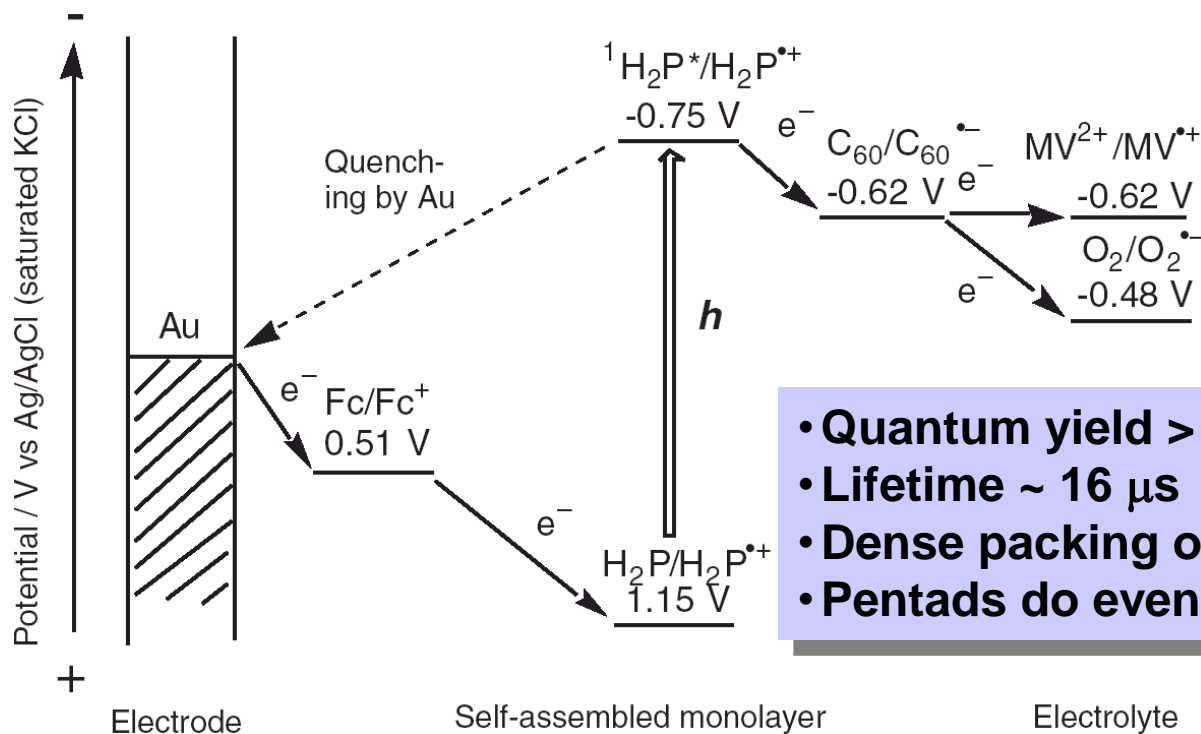
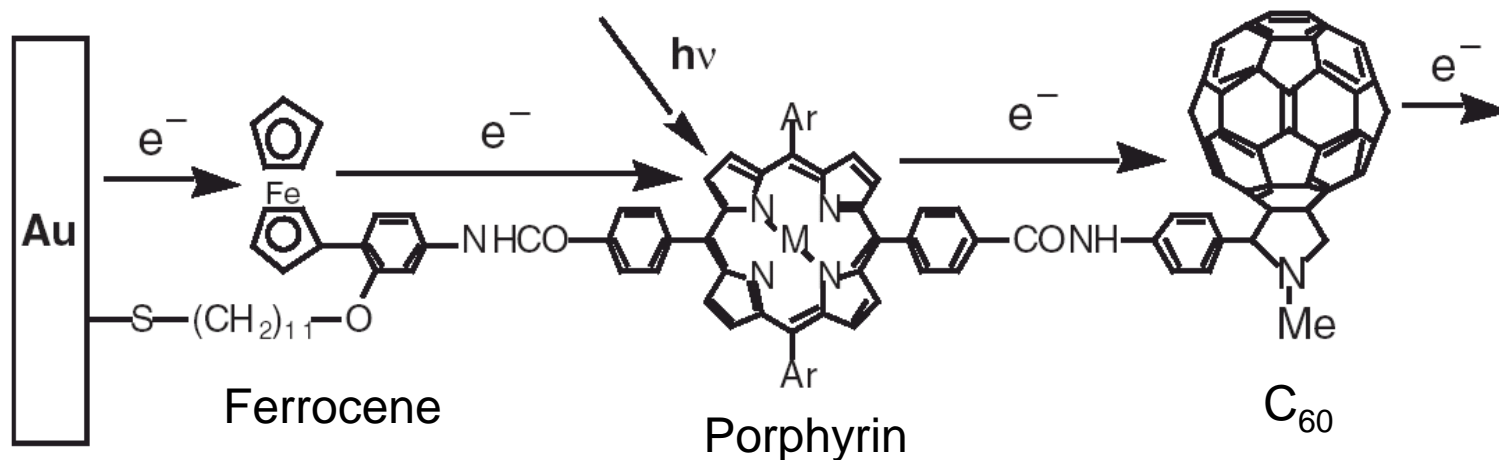
- **Porphyrin-fullerene couples** self-assembled on surfaces
- Donors and acceptors are bonded covalently

- **Quantum yield: 0.5%**
- **Lifetime 0.77  $\mu$ s**
- **Loose packing on the surface**

# Artificial Photosynthesis Requirements

- Appropriate redox potentials and excitation energy for donors and acceptors (*quantum yield*)
- Small reorganization energy  $\lambda$  ( $-\Delta G_{CS} \sim \lambda$  and  $-\Delta G_{CR} \gg \lambda$ ) to favor forward electron transfer (*charge separation time*)
  - Distance between donors and acceptors
  - Solvent characteristics
  - Vibrational modes of the molecules

# Artificial Photosynthesis: A more efficient scheme

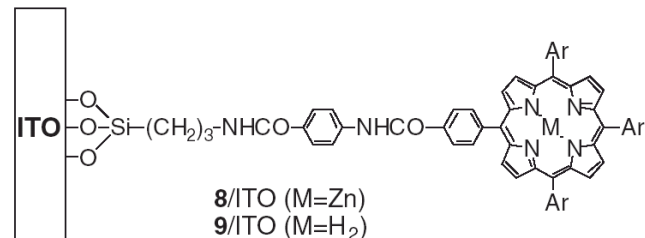
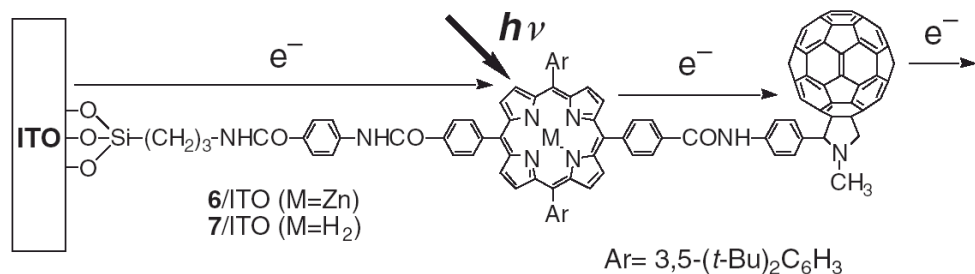


- Quantum yield > 25%
- Lifetime ~ 16  $\mu$ s
- Dense packing on the surface
- Pentads do even better

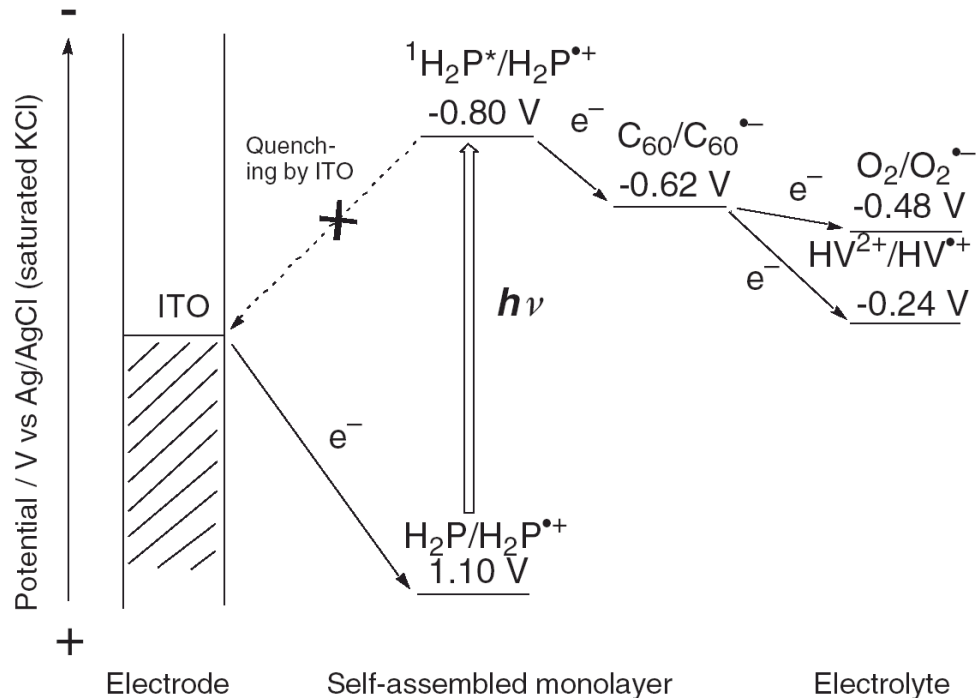




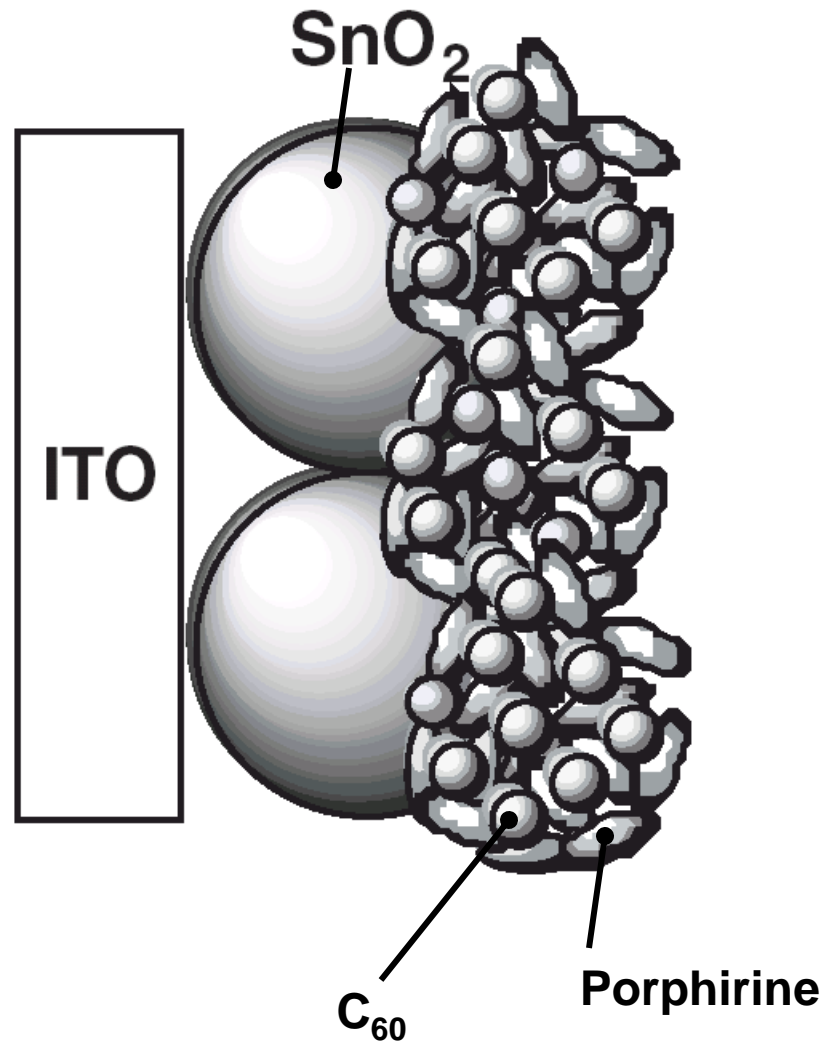
# Artificial Photosynthesis on Transparent Conductive Oxide (ITO)



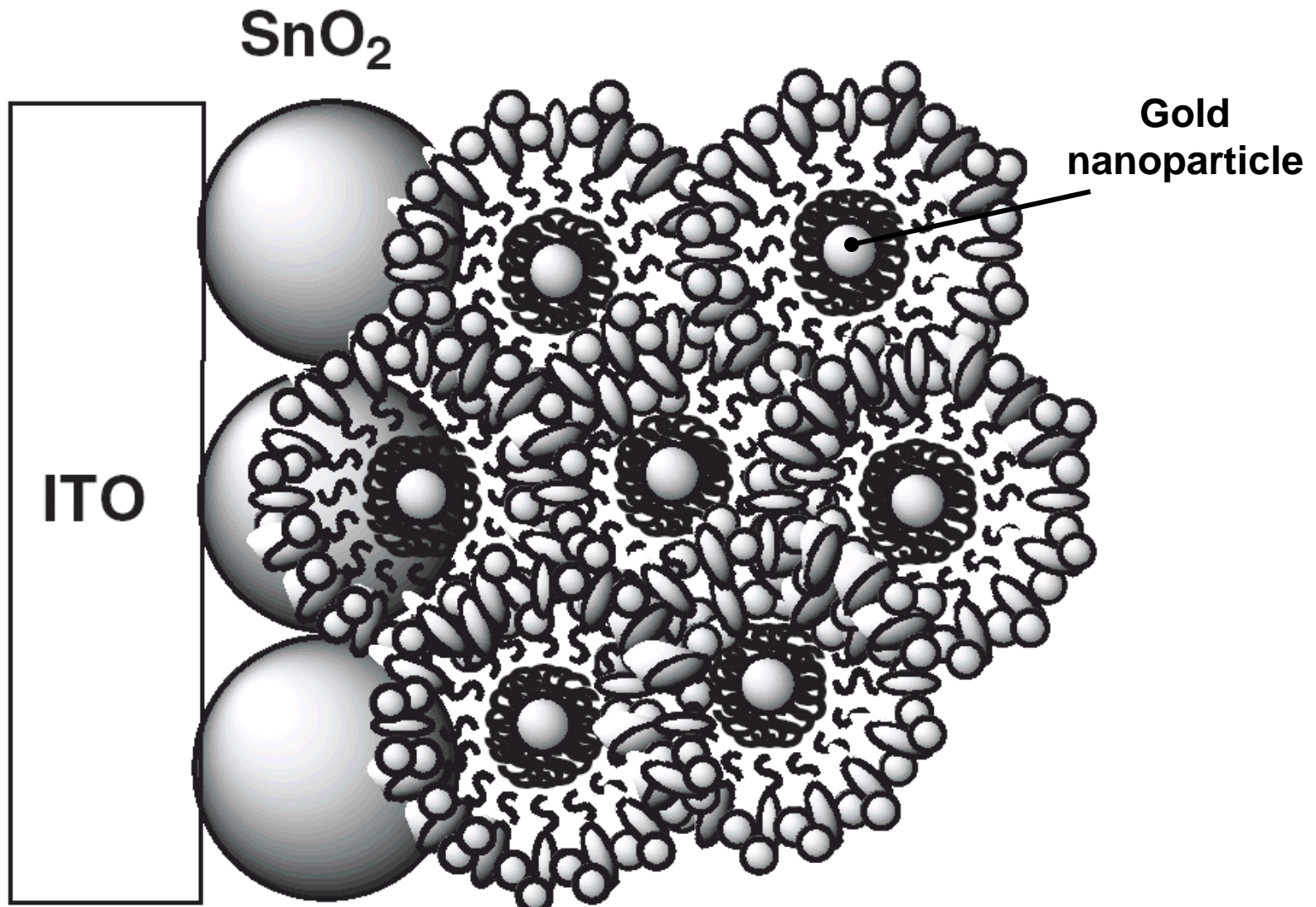
- Avoids quenching by electrode
- Transparent substrate



# Artificial Photosynthesis: Hierarchical assembly for enhancing absorption

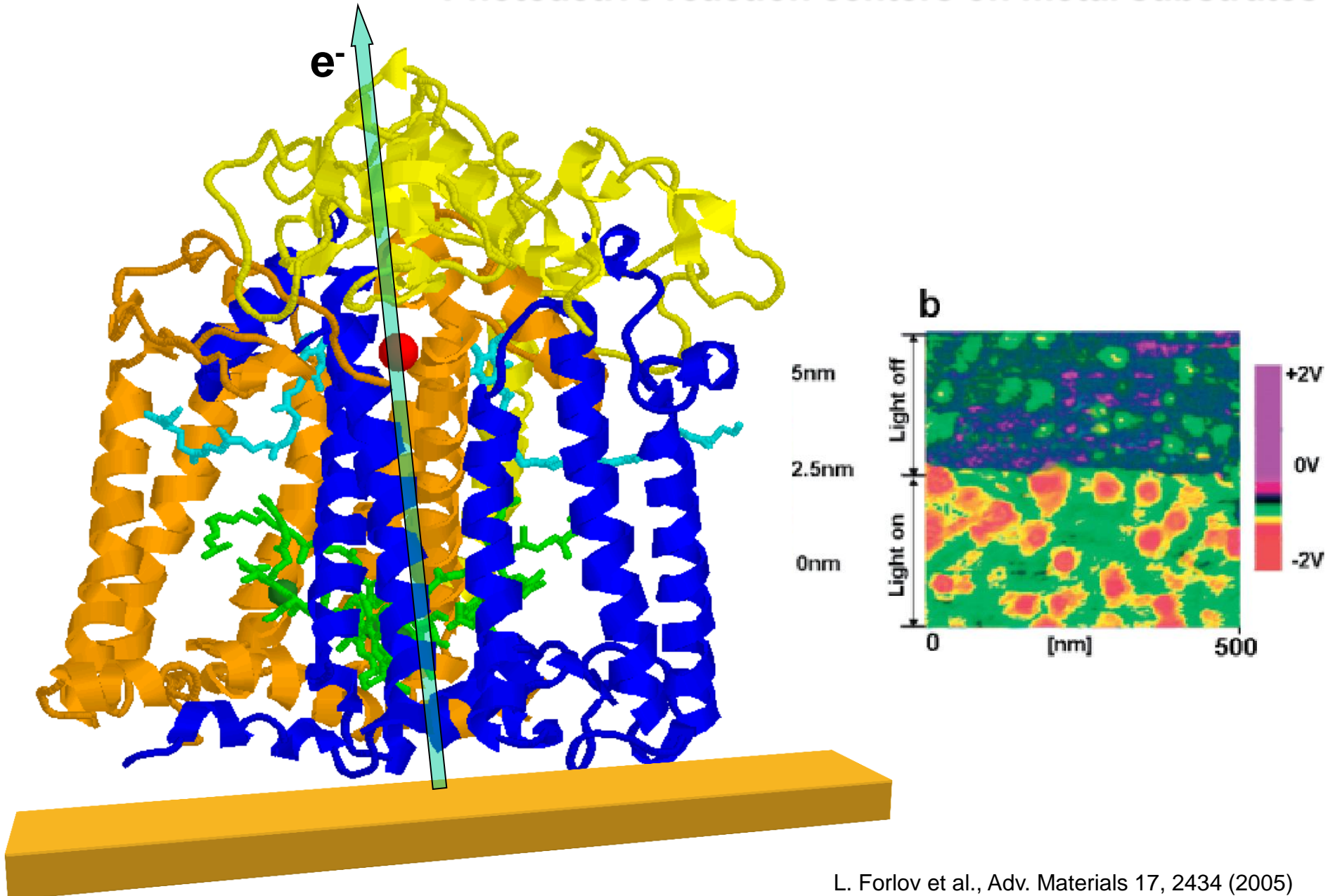


# Artificial Photosynthesis: Hierarchical assembly for enhancing absorption



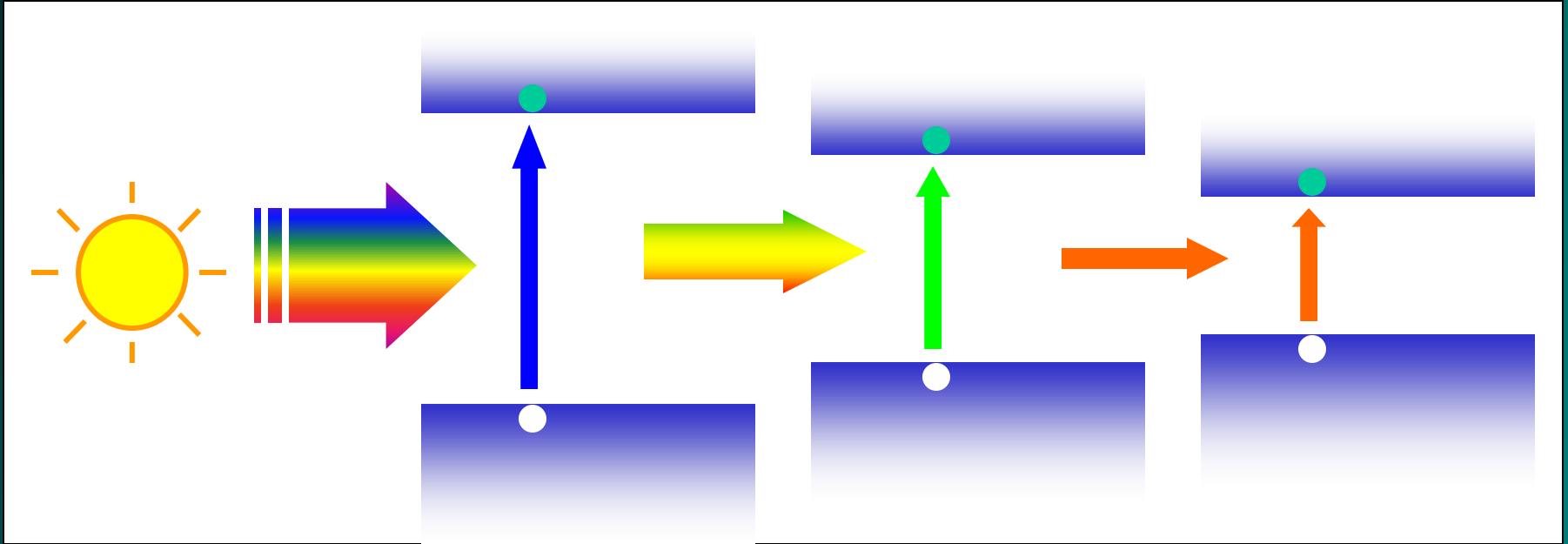
# “Stealing” from Nature

Photoactive reaction centers on metal substrates





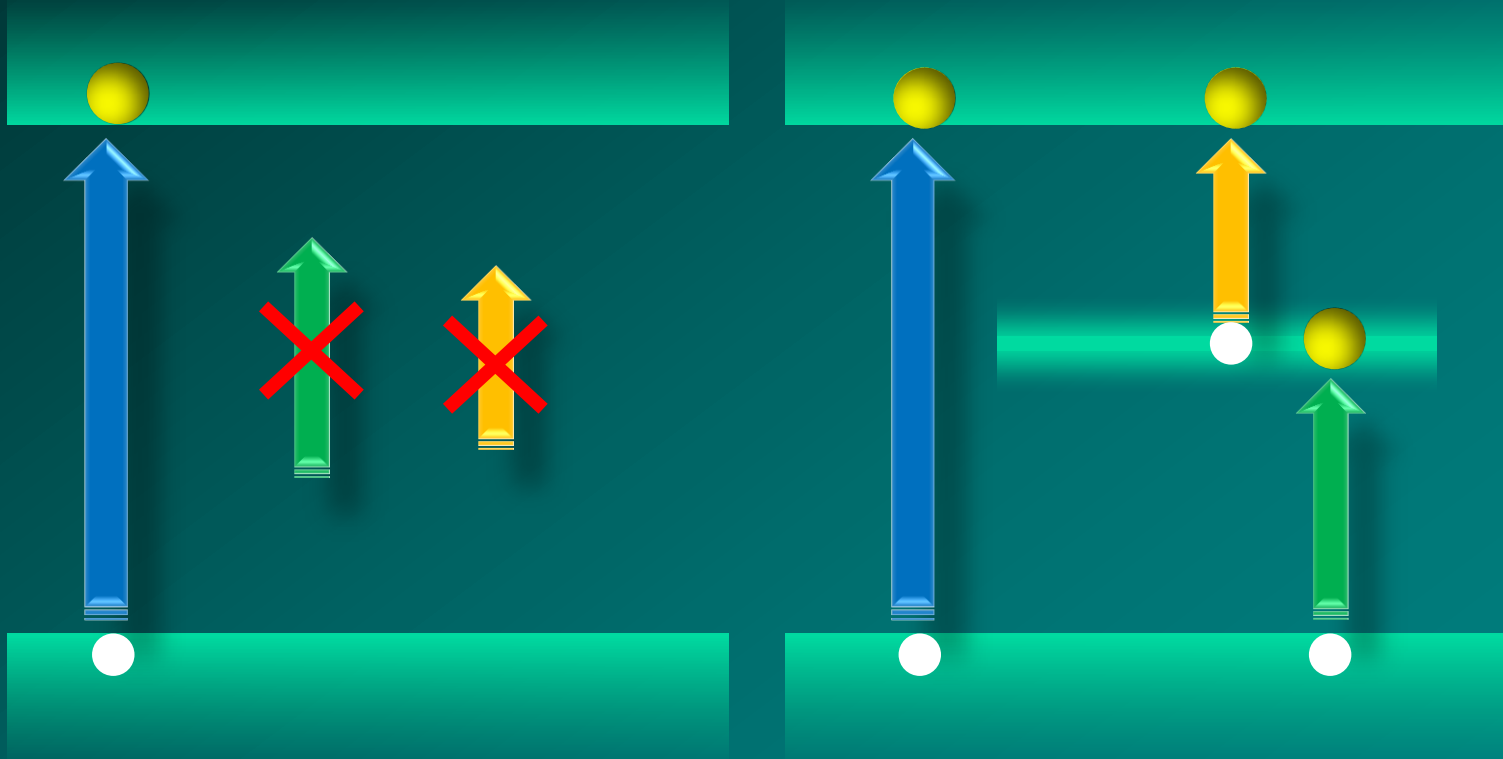
# Beyond The Single Junction Limit: Tandem cells



More efficient use of the solar spectrum

# Intermediate Band Materials

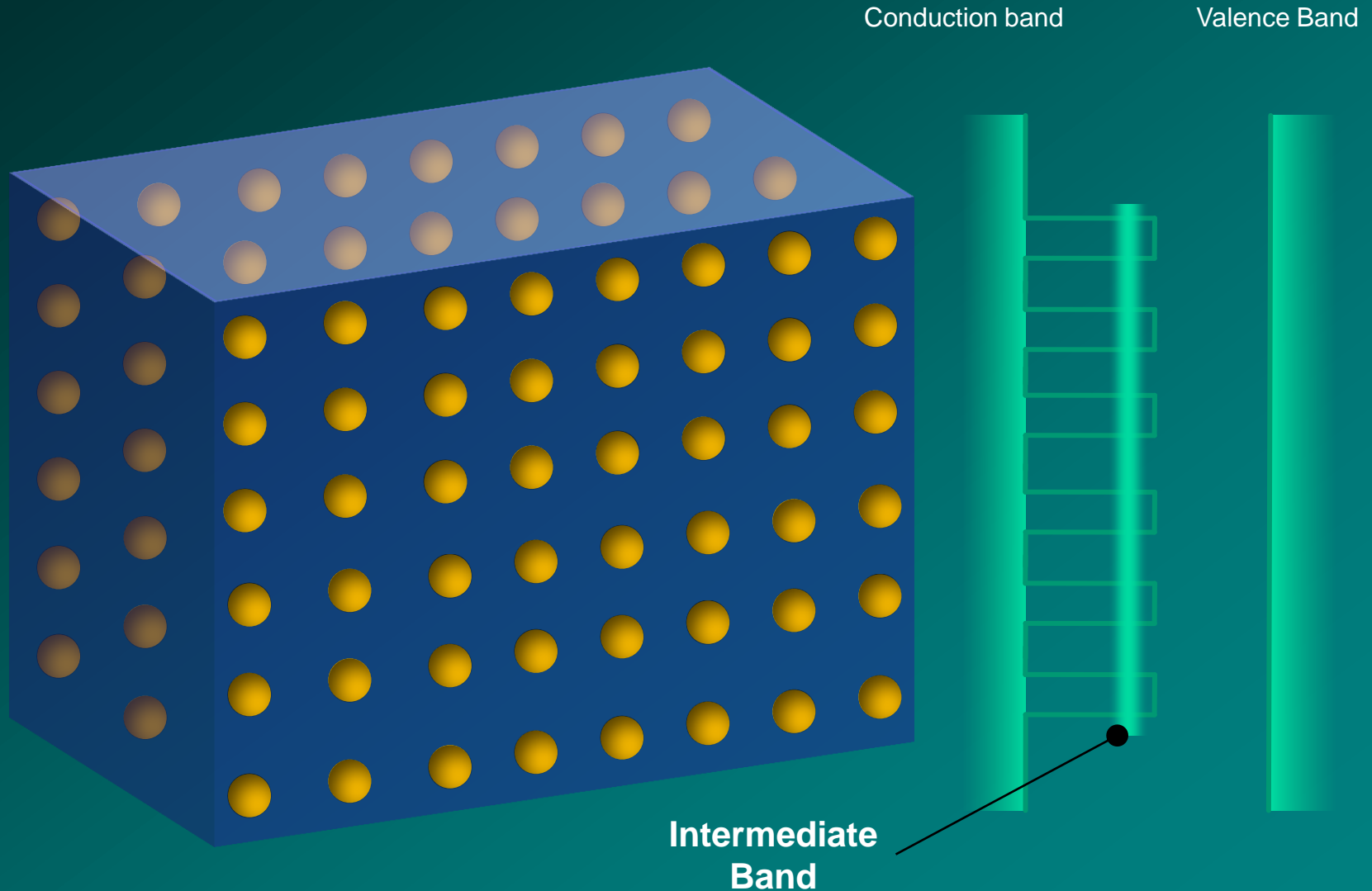
Beyond single junction limits (at low cost!)



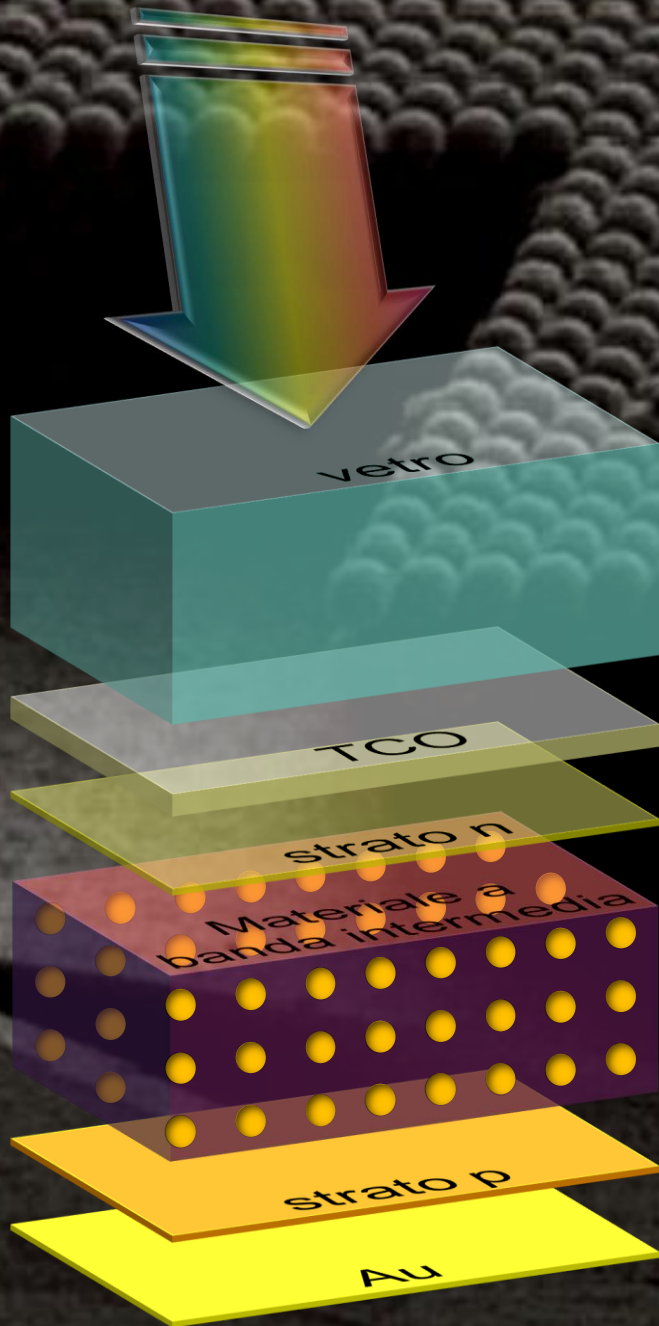
# Making an Intermediate Band Material

Quantum dots embedded in a semiconductor

Nanotechnology at the service of PV



# Photovoltaic Devices Based on Intermediate Band Materials



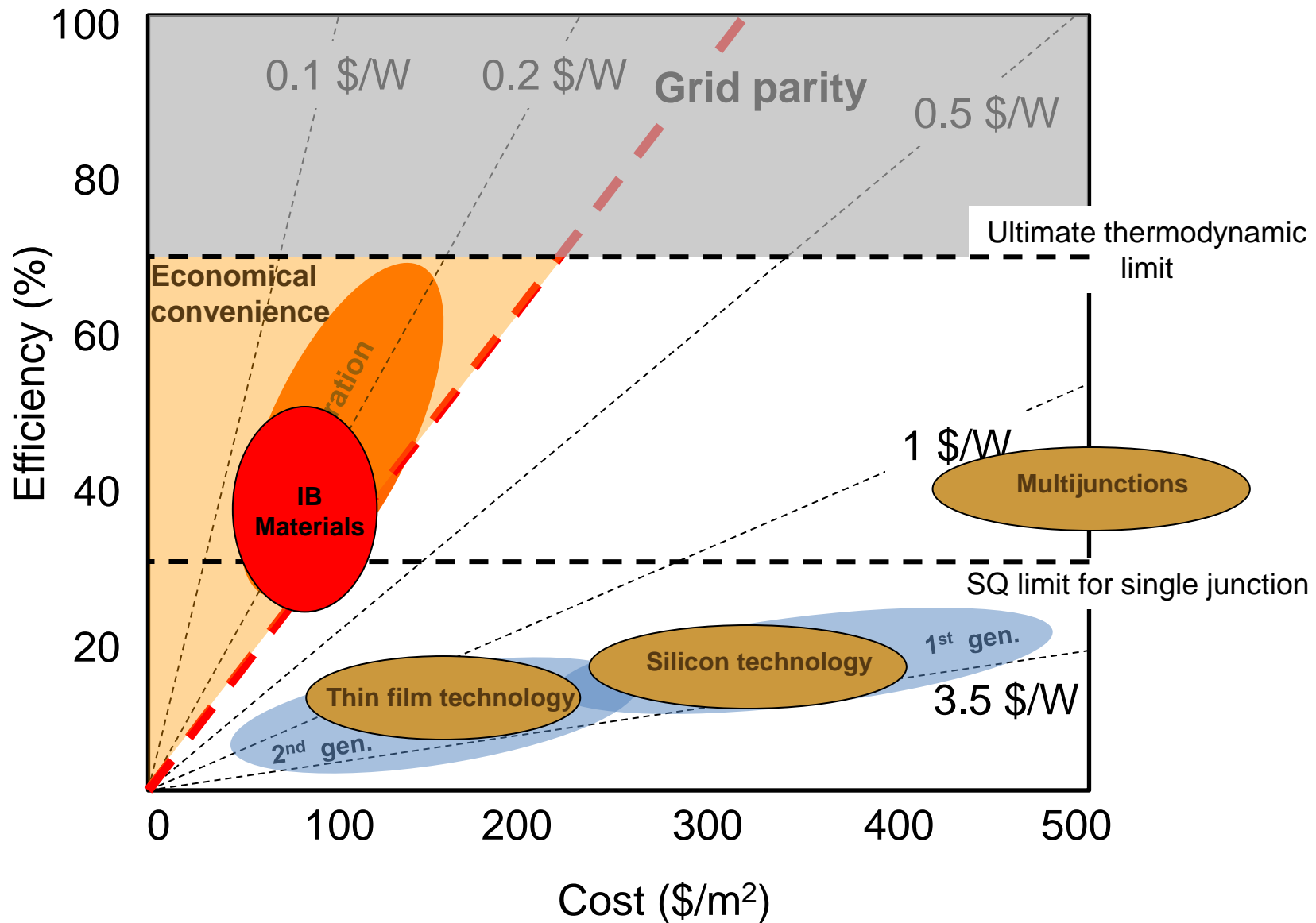
- Max efficiency 47%
- Current record for single-junction cell: 28.3%
- Scalable, low-cost production approaches
- Diversity of substrates – excellent integration (nanoinks and photovoltaic “paints”)

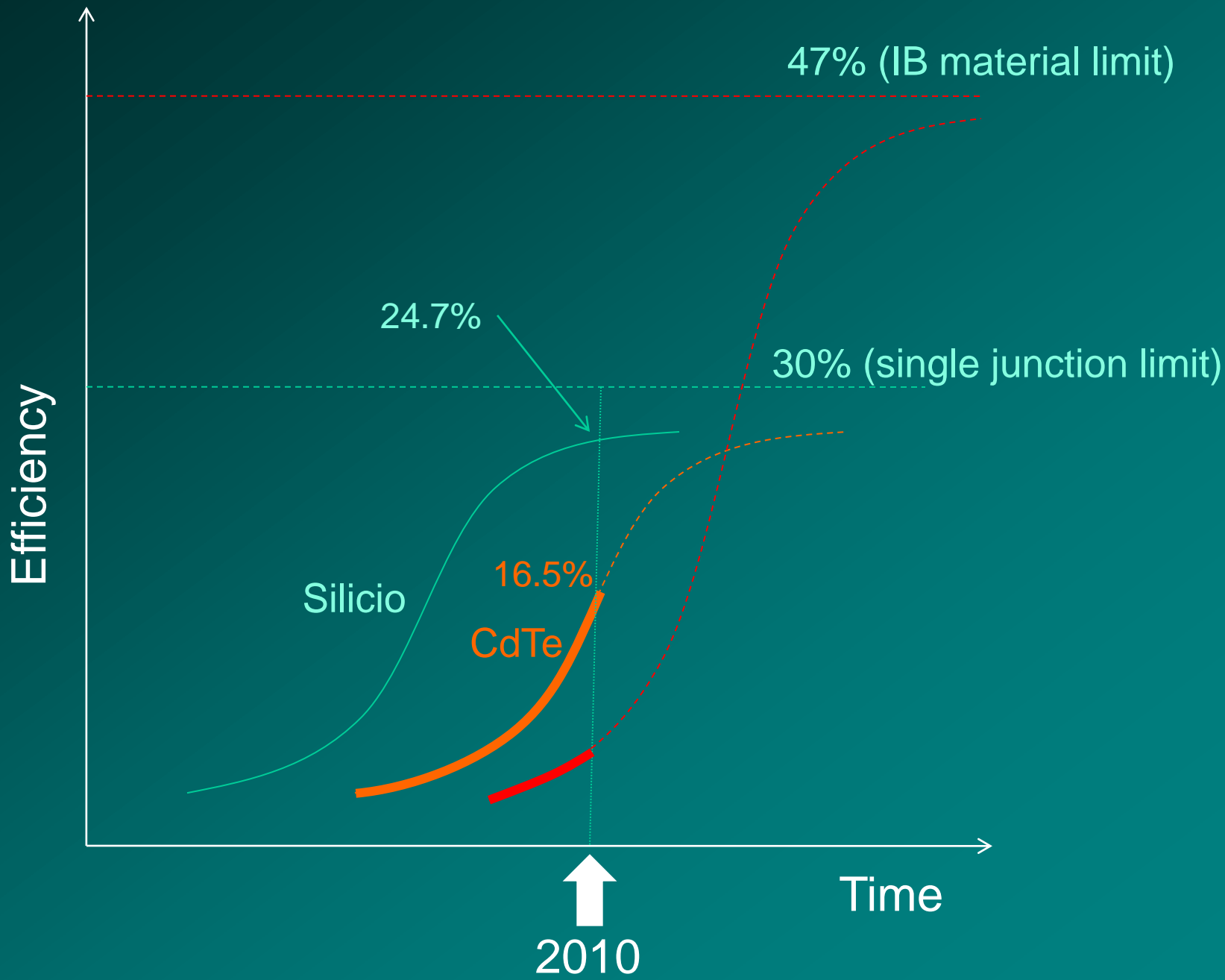
5  $\mu\text{m}$



# Tecno-Economical Evolution

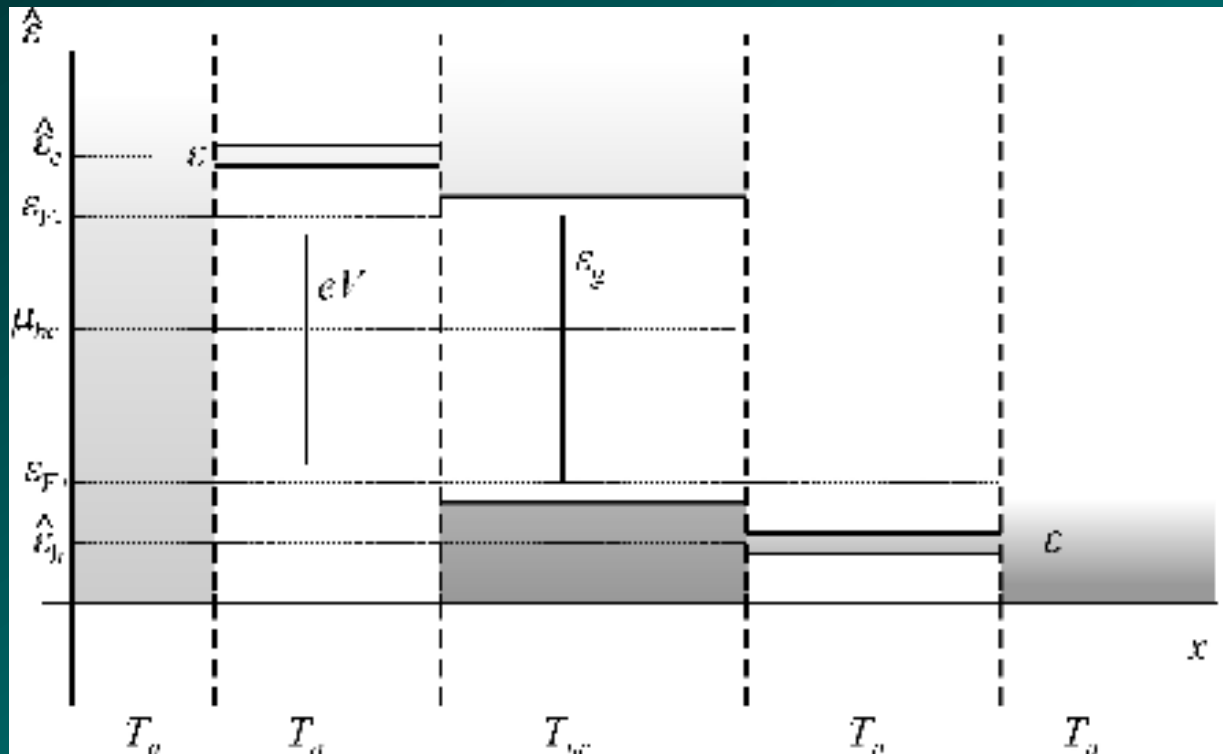
## - Cost and Efficiency – PV Figures of Merit -





# Beyond The Single Junction Limit: Other approaches

- Multiple carrier generation  
using high energy photons to extract more than one electron per photon
- Hot electron extraction  
extracting high energy photogenerated electrons before they thermalize



Thermodynamic limiting  
efficiency (both cases): 86.8%

# Properties of nanomaterials

Phenomena at the nanoscale  
are governed by the laws of quantum mechanics.



new opportunities for controlling material properties

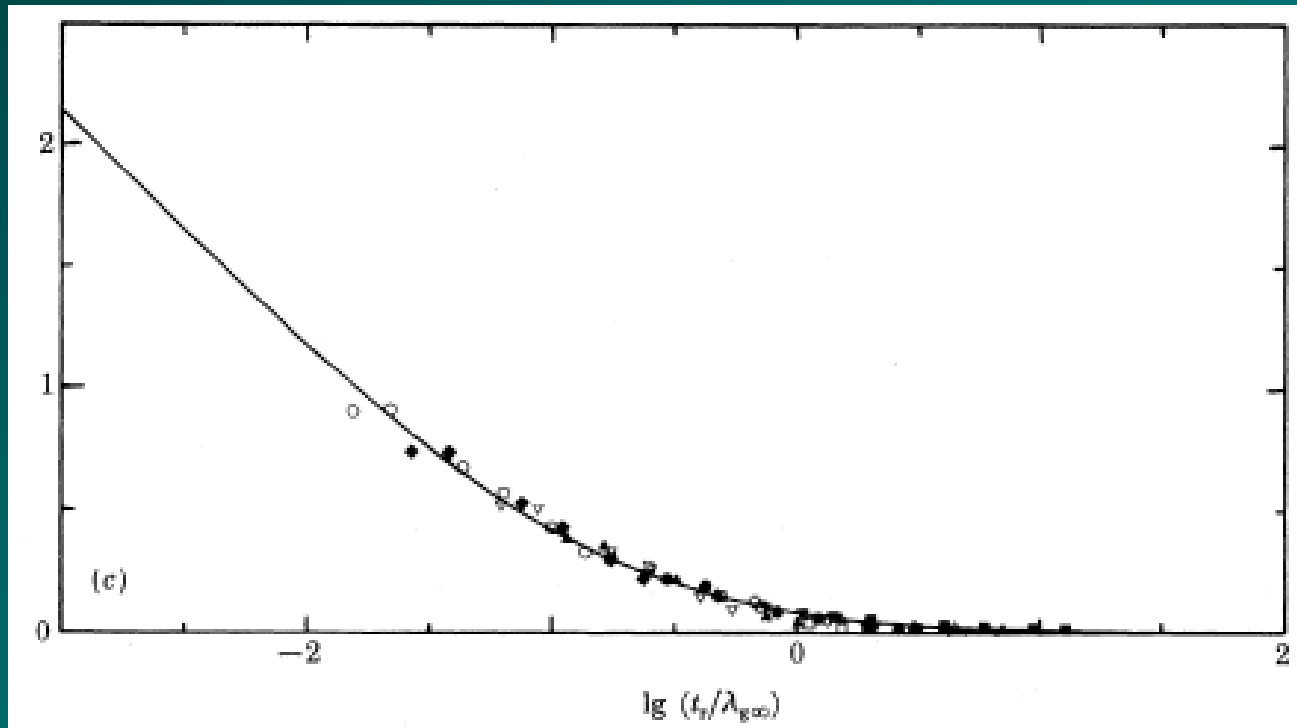
Phenomena that govern optoelectronic properties of materials  
**occur at the nanoscale**



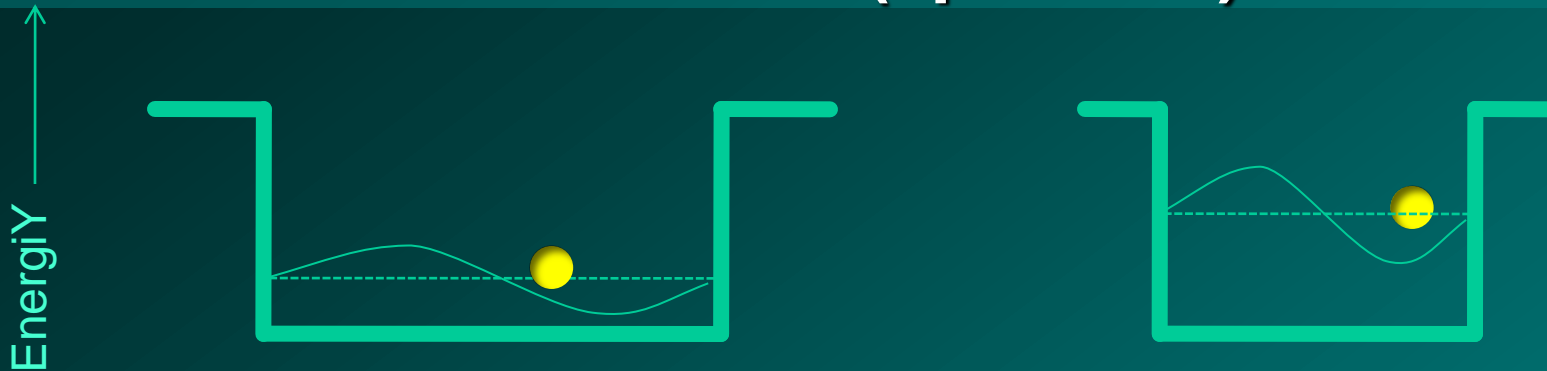
# Properties of nanomaterials

What does “nano” mean?

A material is “nano” when  
a selected property starts to differ from its bulk behavior



# Electrons in a (spherical) box



$$E = \frac{\hbar^2 \pi^2}{2m_e R^2} n^2 \quad n = 1, 2, 3, \dots$$

- Electrons can be described by waves
- Confined waves can only have a discrete set of wavelengths

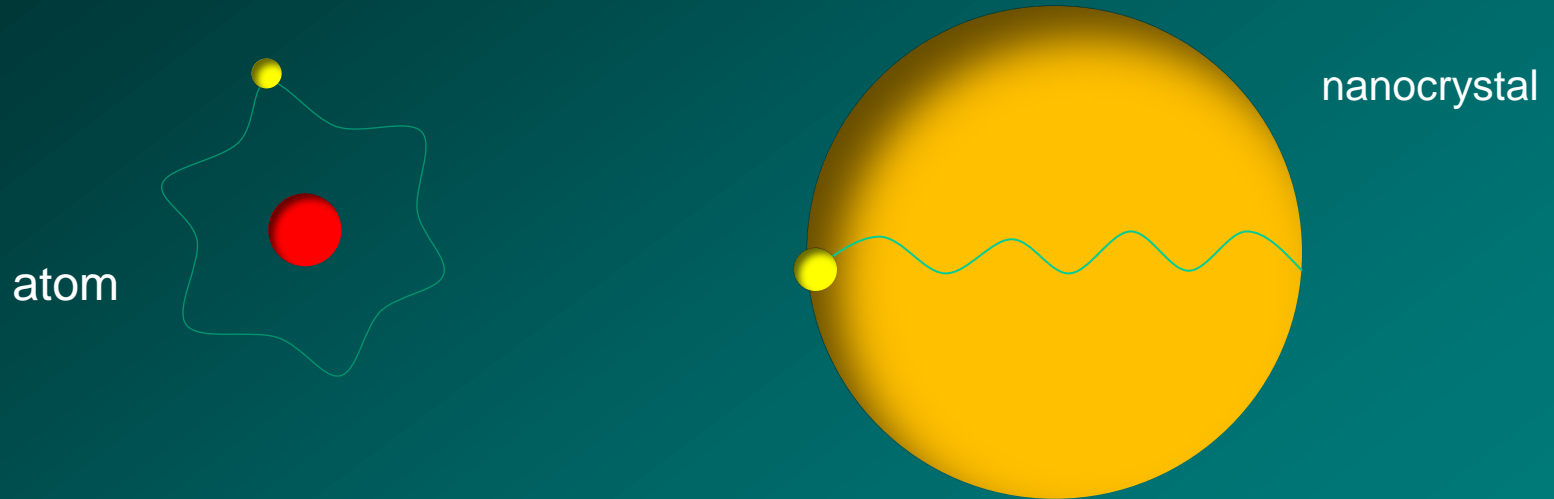


In confined systems, electrons can only assume discrete values of energy

Position of energy levels depends upon confinement (size of the box)

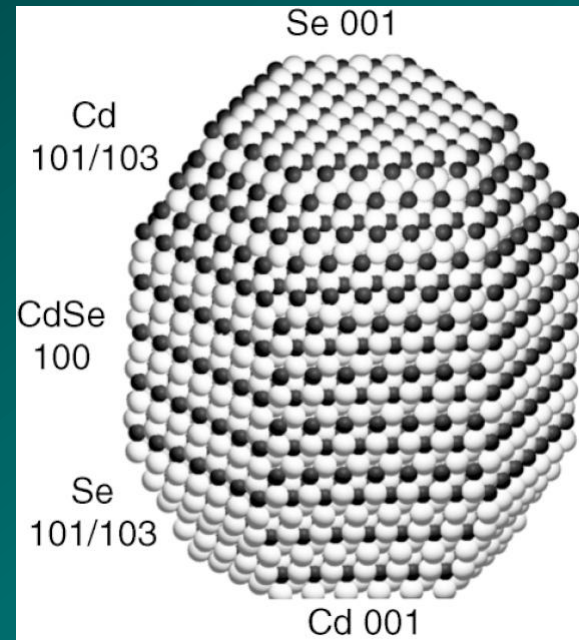
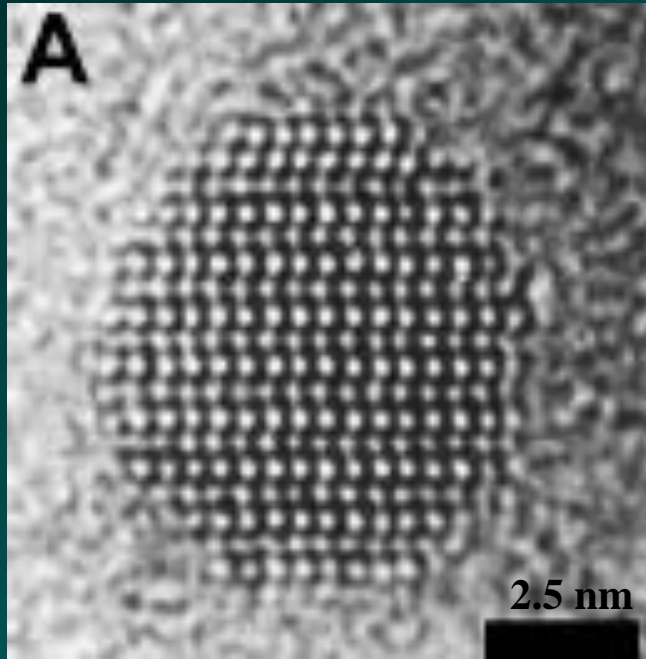
# Quantum Dots

“Artificial atoms”



**As for atoms, quantum dots have discrete electron energy levels**

# Nanocrystals

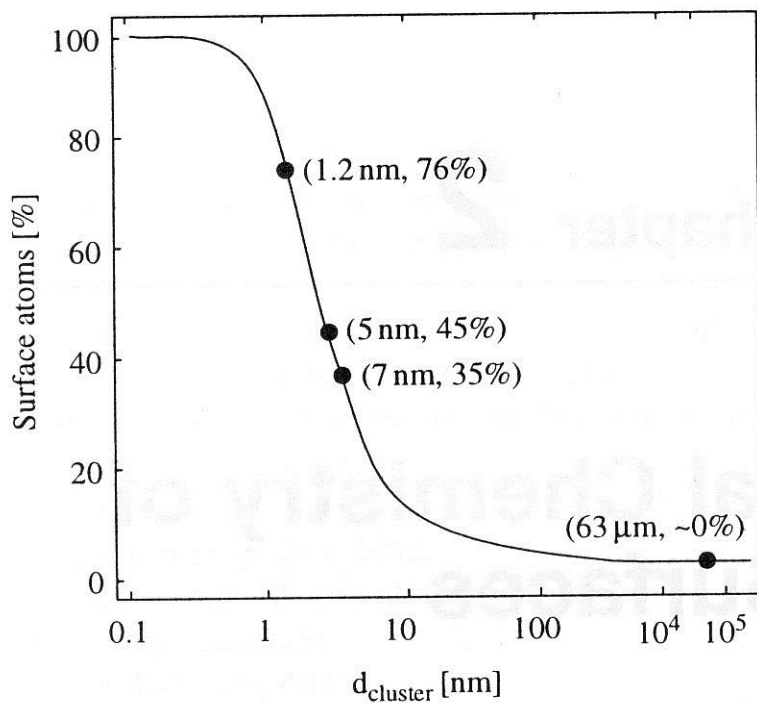


Typical size: 1 – 100 nm ( $10^2$  -  $10^5$  atoms)

Most atoms are at the surface (75% for 1 nm nanocrystals)






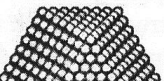
Essentially free of lattice defects

# Nanocrystals



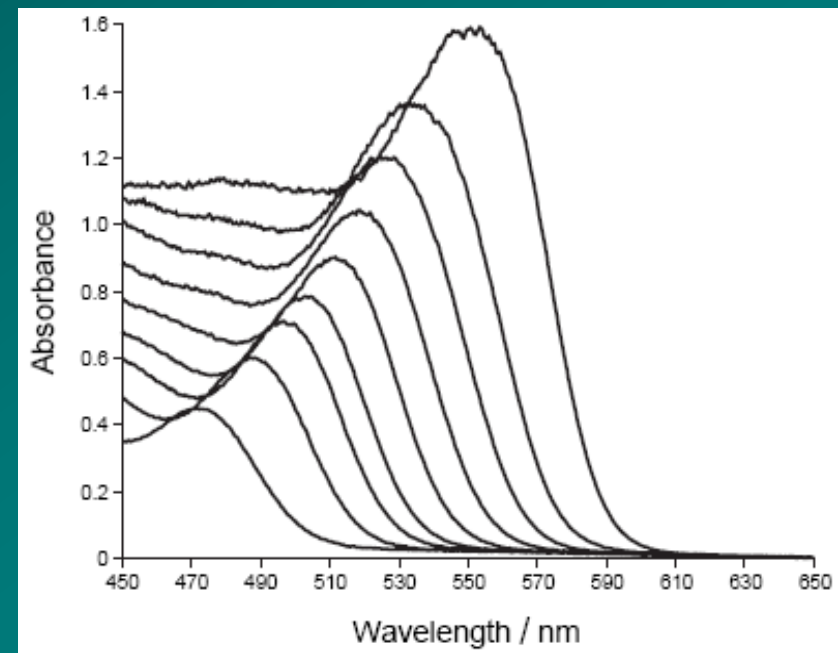
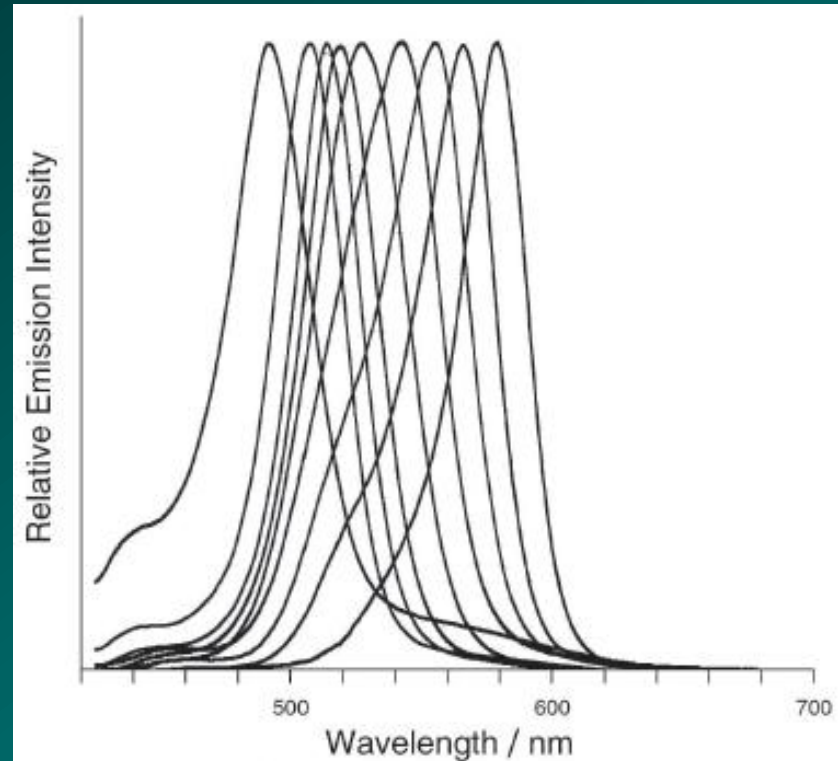
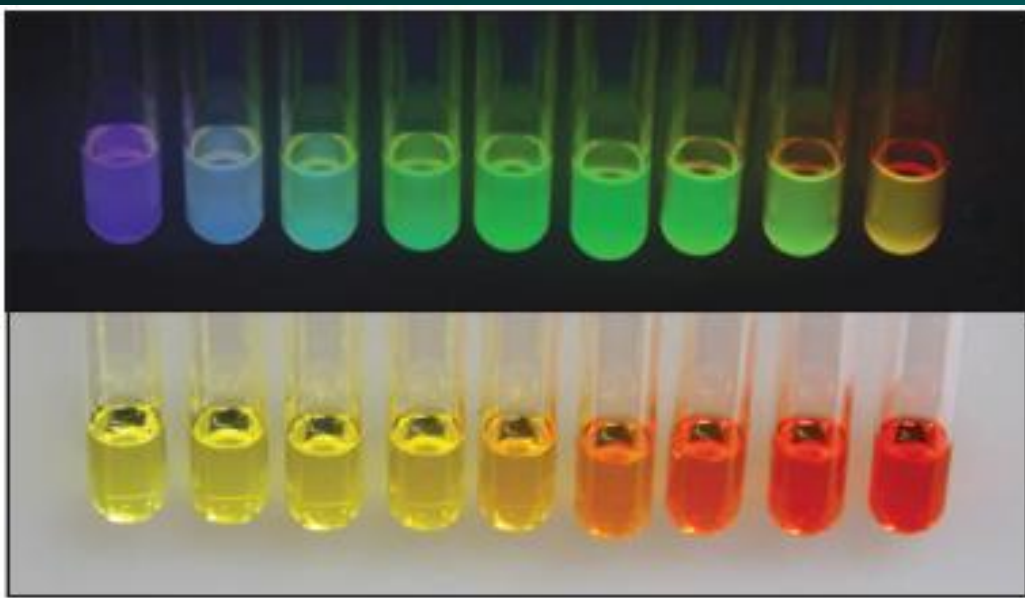
**Fig. 2.1.** The percentage of surface atoms changes with the palladium cluster [C. Nützenadel, A. Züttel, D. Chartouni, G. Schmid, and L. Schlapbach, *Eur. P.* 245 (2000).]

**TABLE 2.1** The relation between the total number of atoms in full-shell clusters and the percentage of surface atoms

Full-shell Clusters	Total Number of Atoms	Surface Atoms (%)
1 Shell 	13	92
2 Shells 	55	76
3 Shells 	147	63
4 Shells 	309	52
5 Shells 	561	45
7 Shells 	1415	35

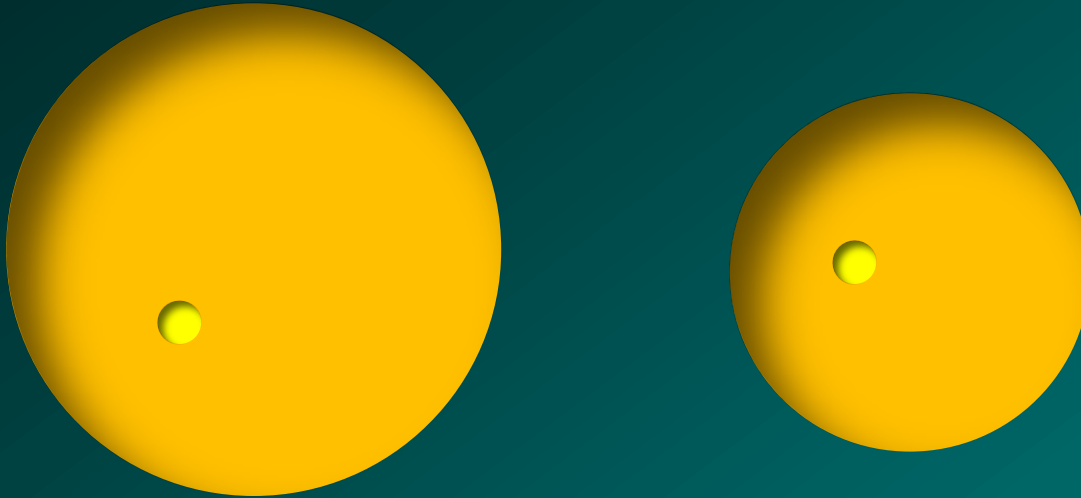


# Semiconductor nanocrystals (quantum dots): Optical properties

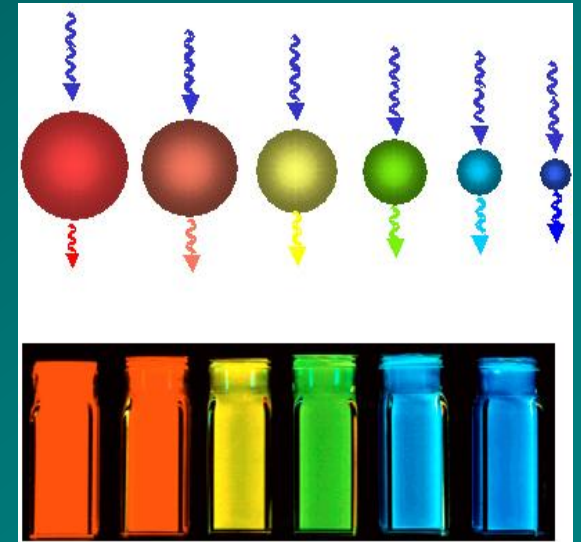
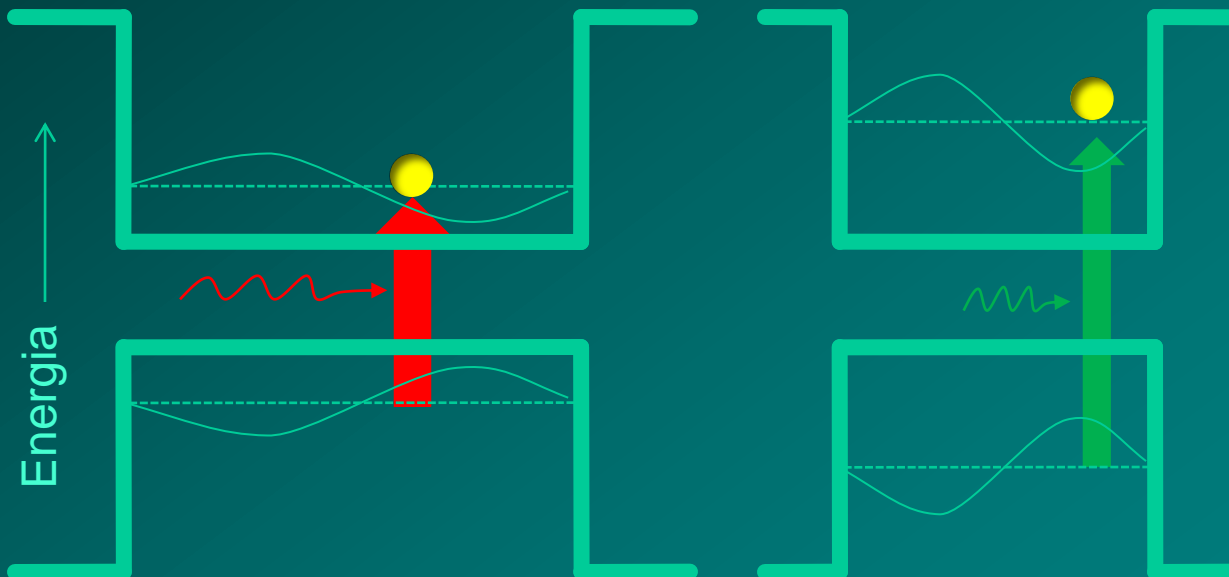


# Quantum dot absorption and emission

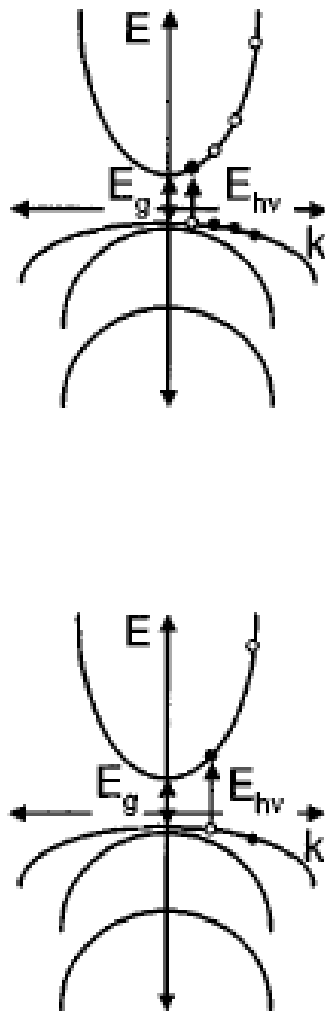
Dependence on size



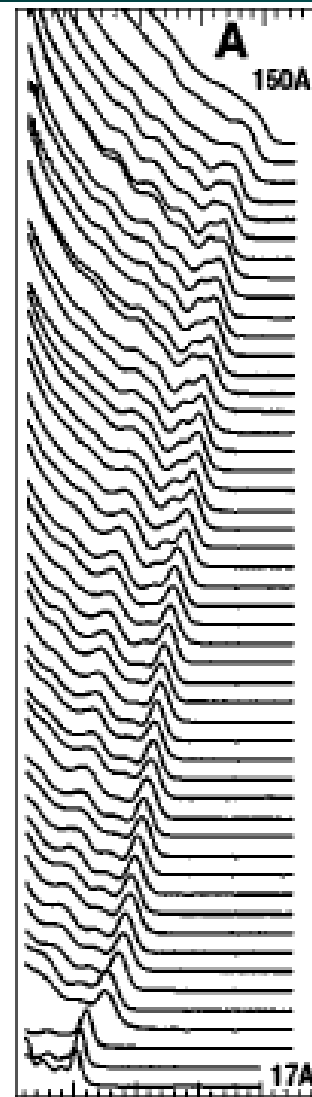
$$E_g(Q.D.) = E_{g0} + \frac{\hbar^2 \pi^2}{2m_{eh} R^2}$$



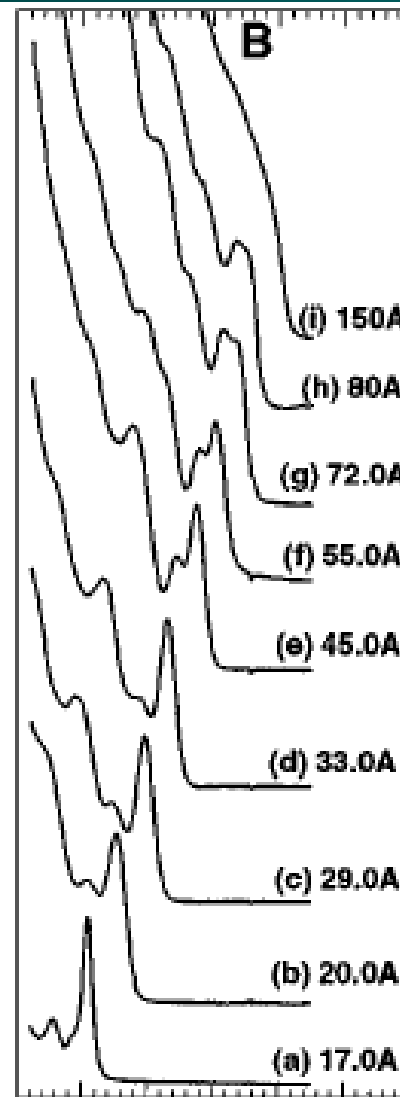
Decreasing NC Diameter ↓



Absorbance (arbitrary units)



400 500 600 700  
Wavelength nm



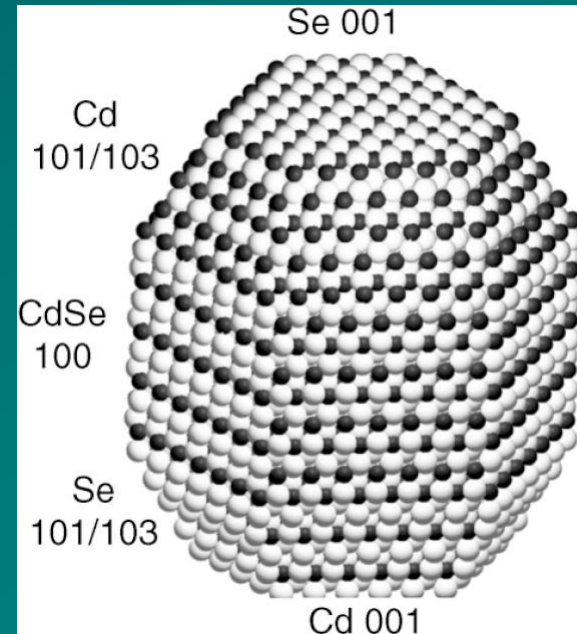
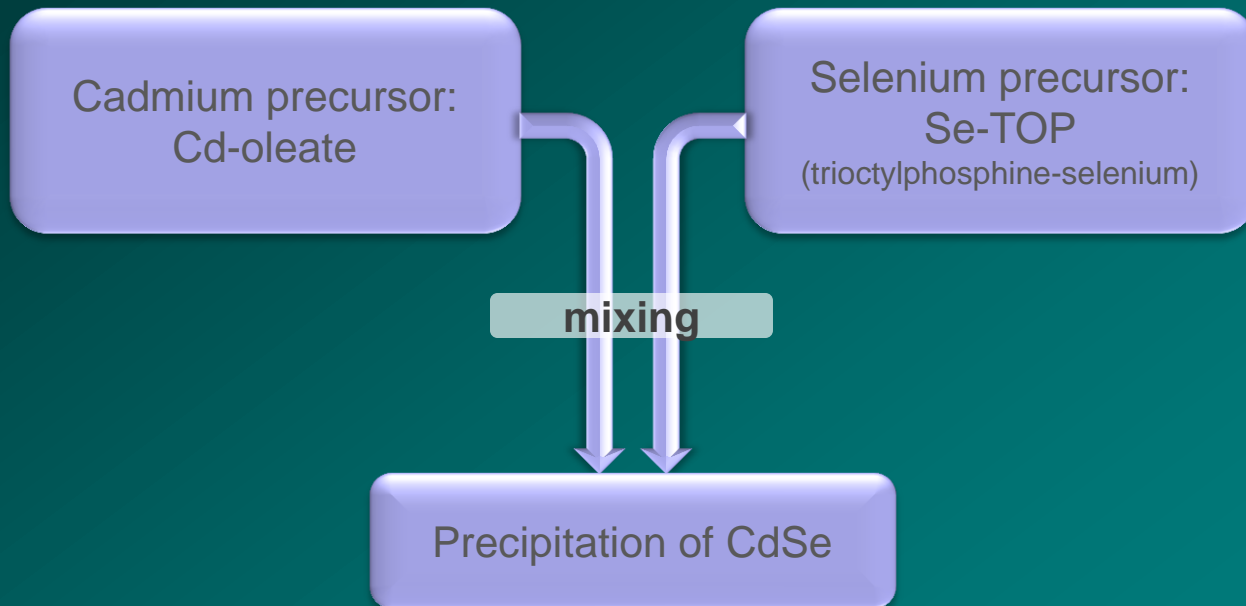
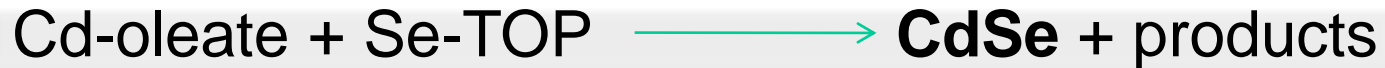
400 500 600 700 800  
Wavelength nm

Absorbance (arbitrary units)



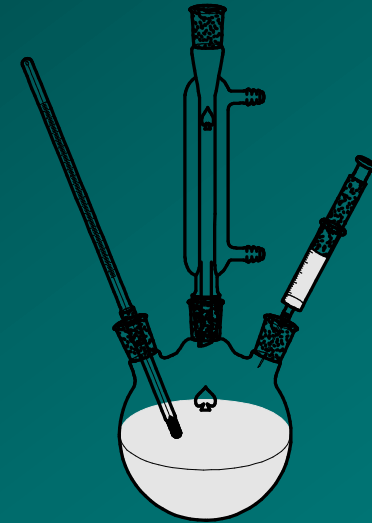
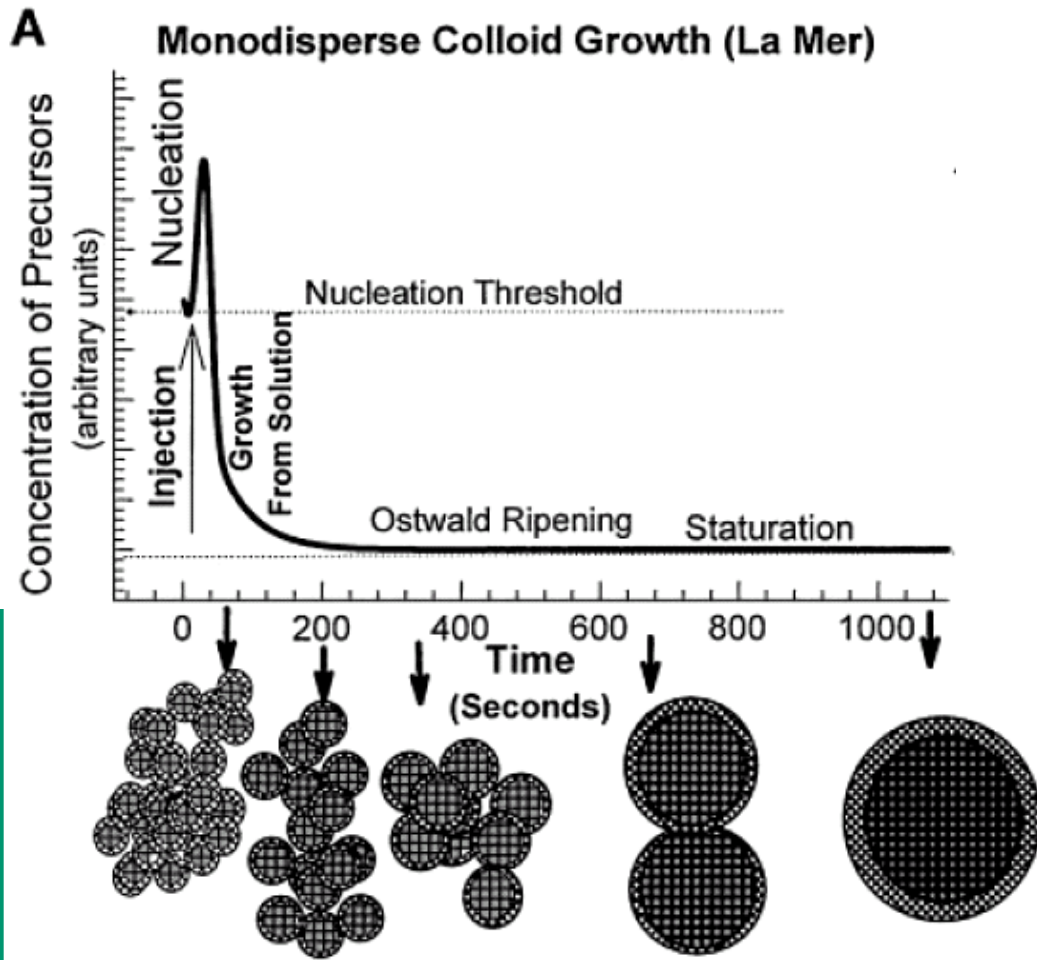
# Semiconductor Nanocrystals: Synthesis

## Colloidal synthesis of cadmium selenide





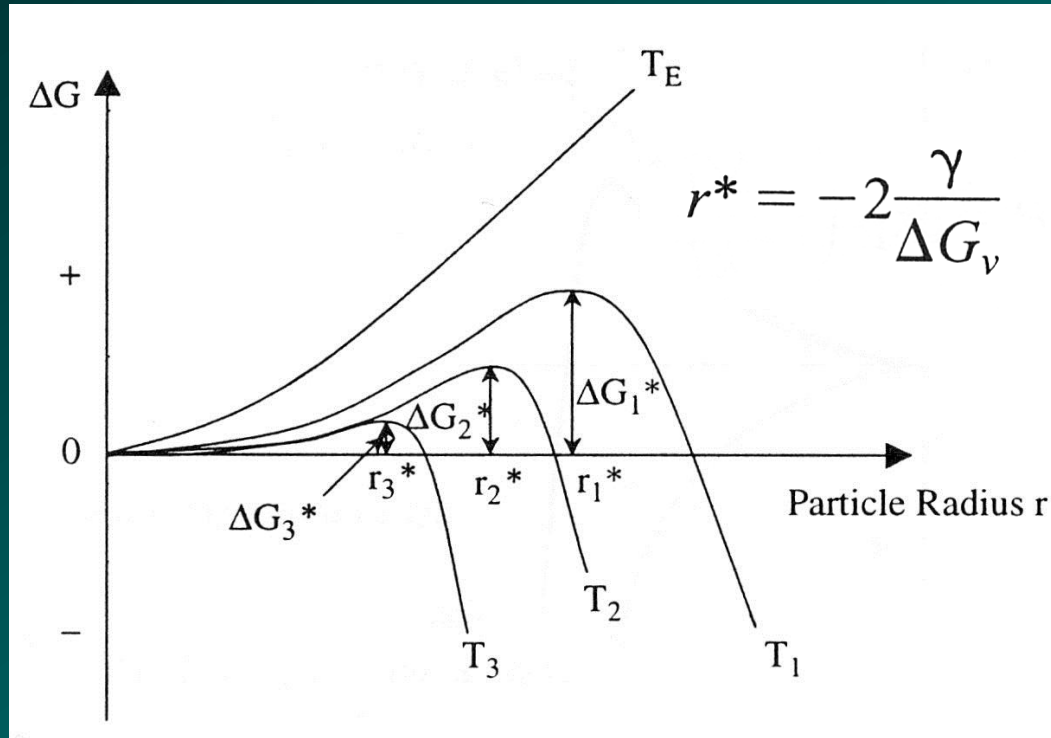
# Semiconductor Nanocrystals: Colloidal Synthesis



Key role of  
**NUCLEATION**  
and  
**GROWTH**

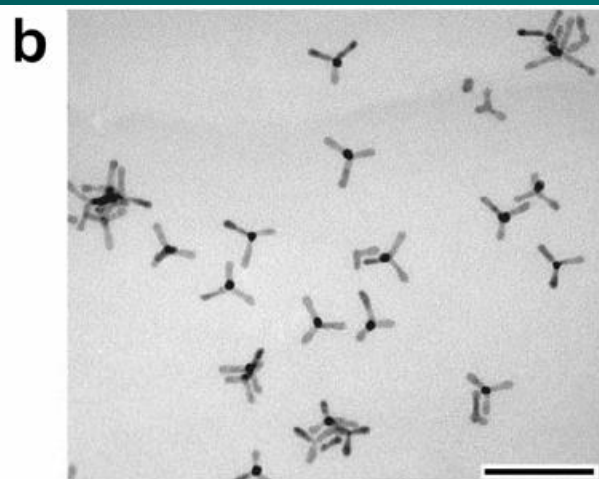
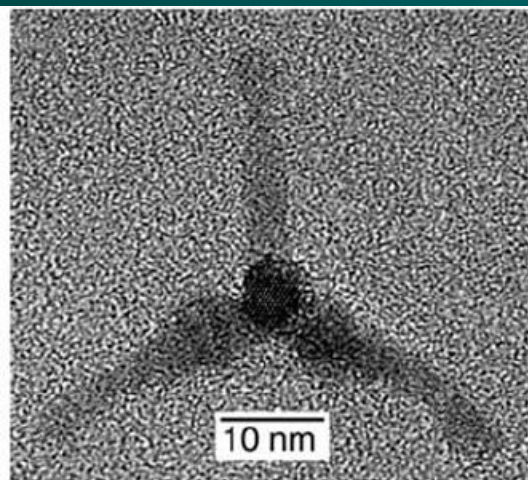
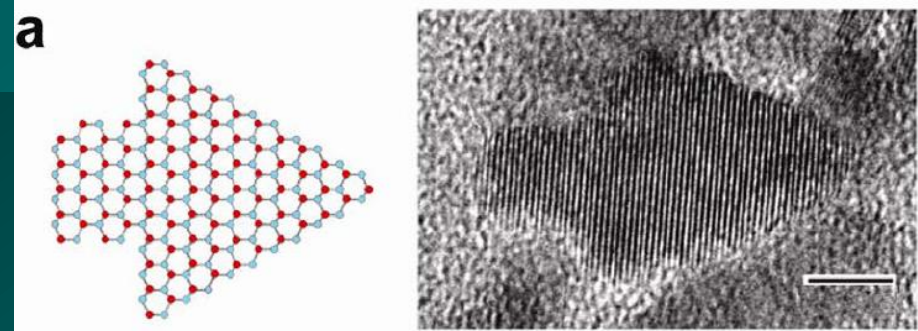
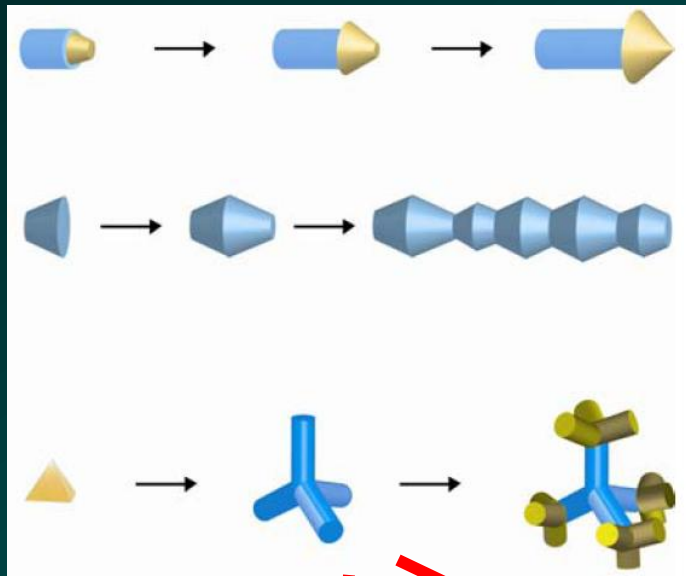
**TIME, TEMPERATURE and CONCENTRATION** control reaction kinetics  
Surfactant are needed to avoid cluster formation

# Nucleation



$$R_N = nP\Gamma = \left\{ \frac{C_o kT}{3\pi\lambda^3\eta} \right\} \exp\left(-\frac{\Delta G^*}{kT}\right)$$

# Nanocrystal shapes

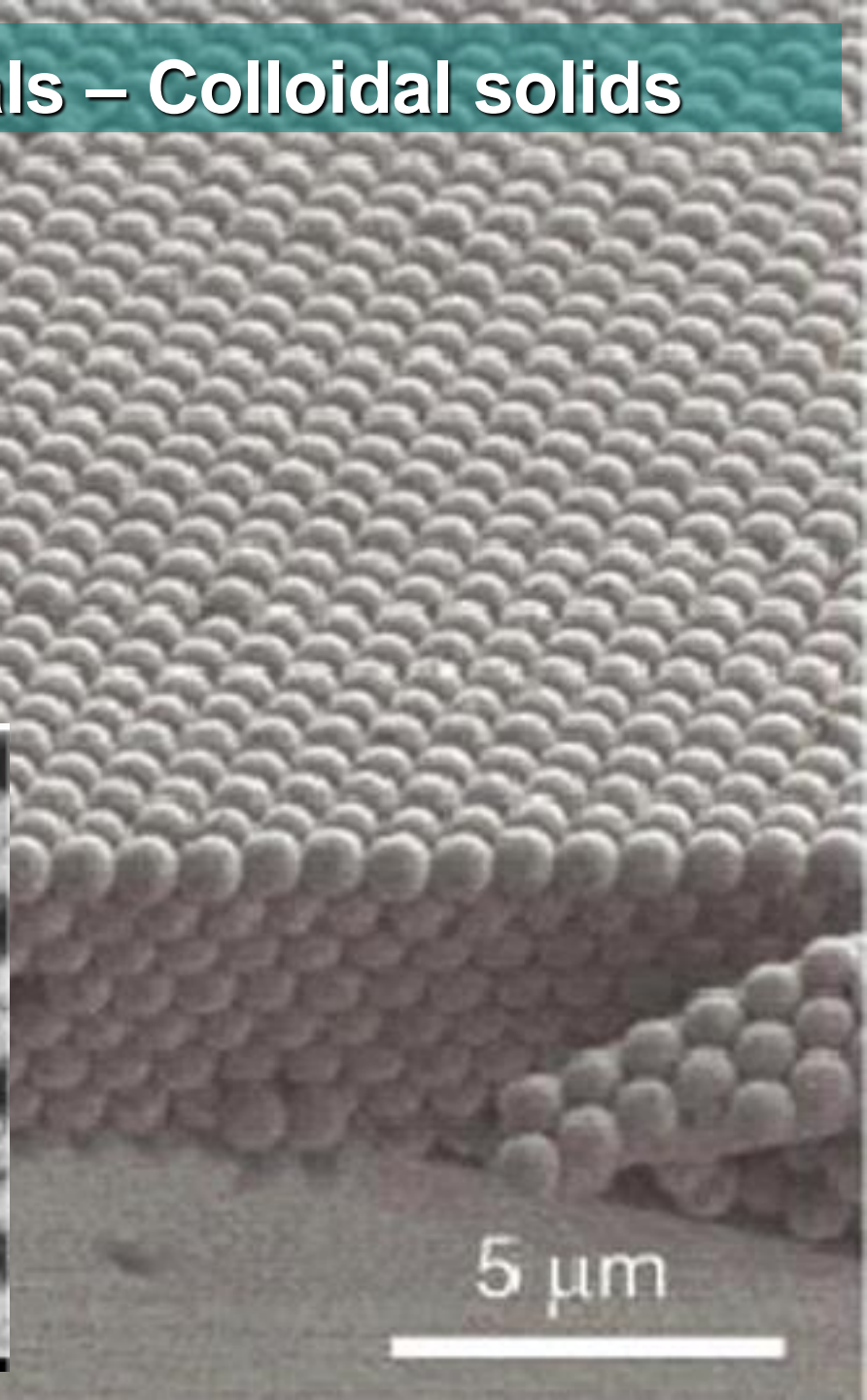
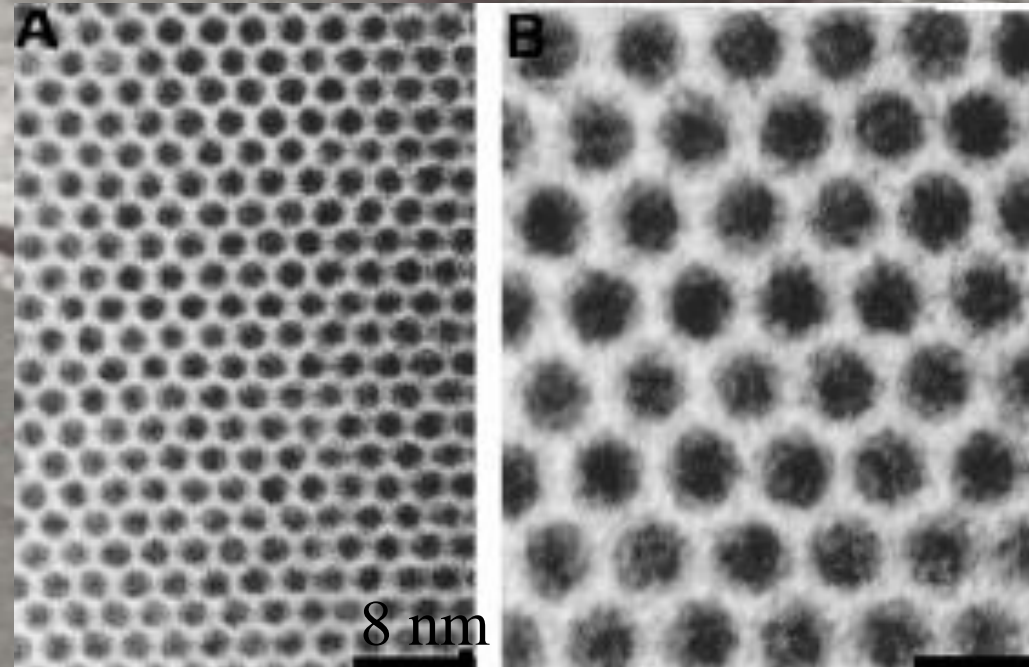


Paul Alivisatos, UC Berkeley

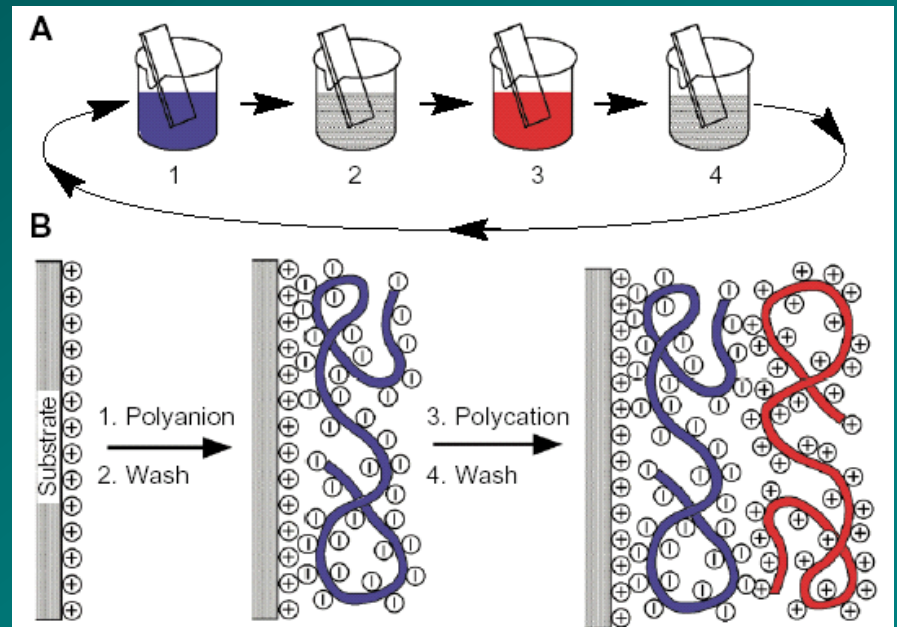
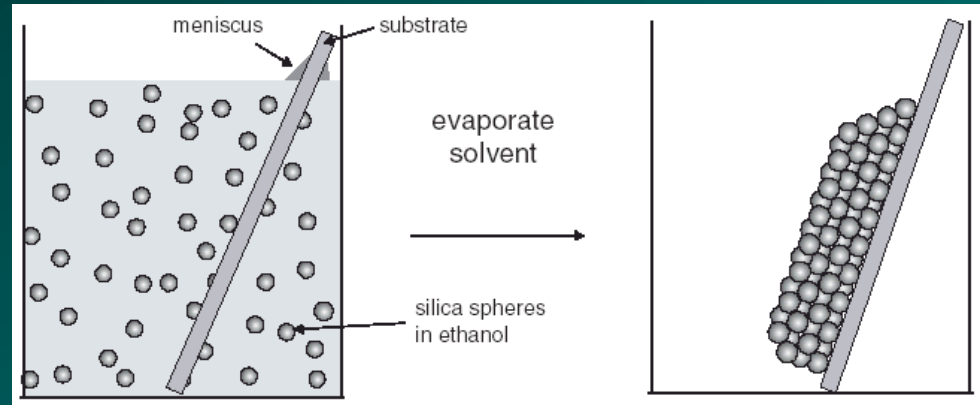
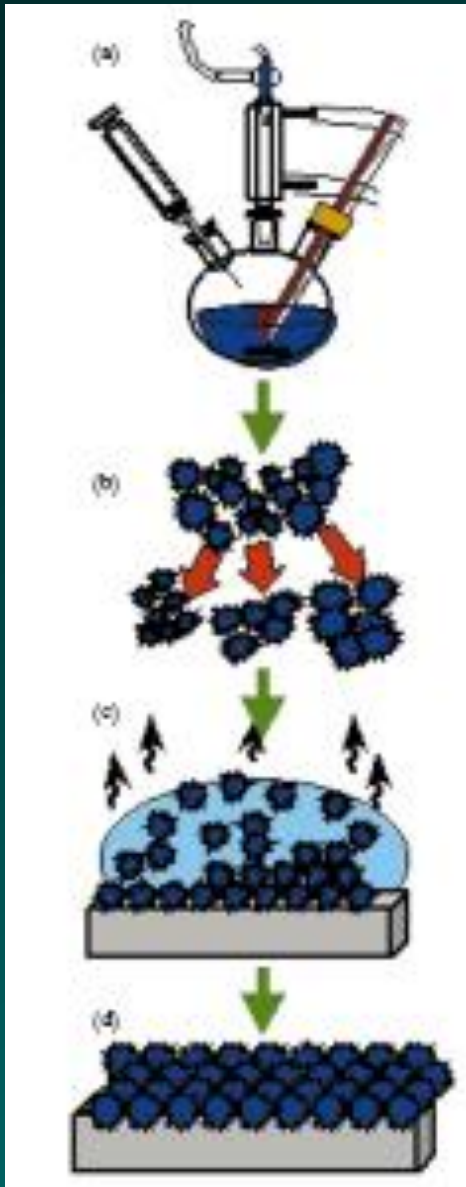


# Nanostructured materials – Colloidal solids

A chance to design novel materials with entirely new properties



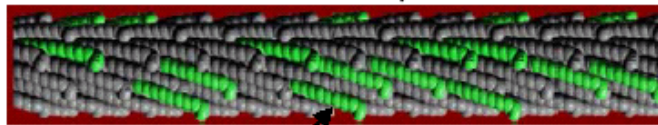
# Methods for assembling colloidal solids



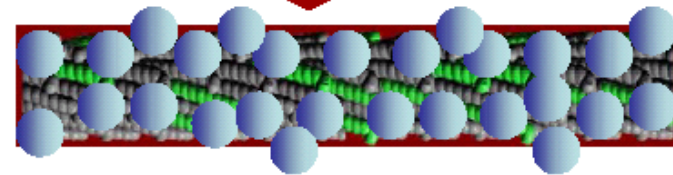


# Bio-templated nanomaterials

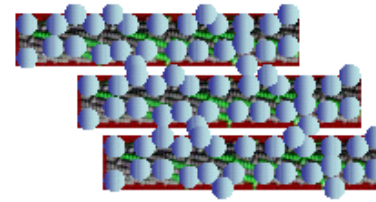
## 1. Viral template



'binding' peptides



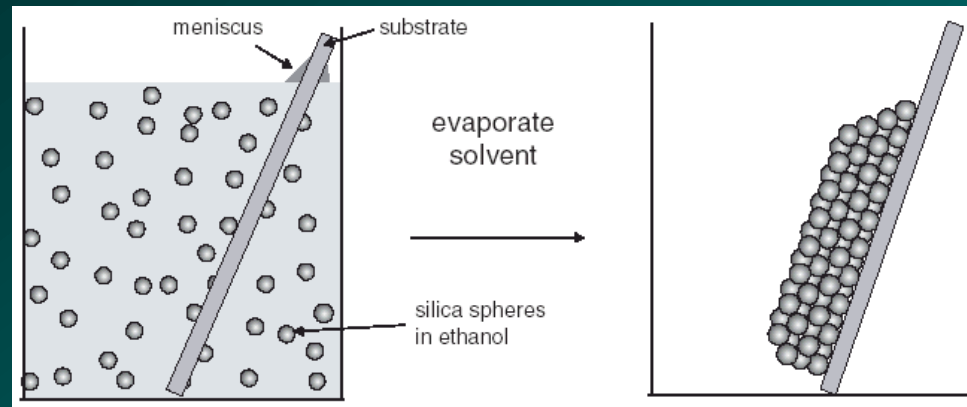
## 2. Binding of nanocrystals = 'nanorods'



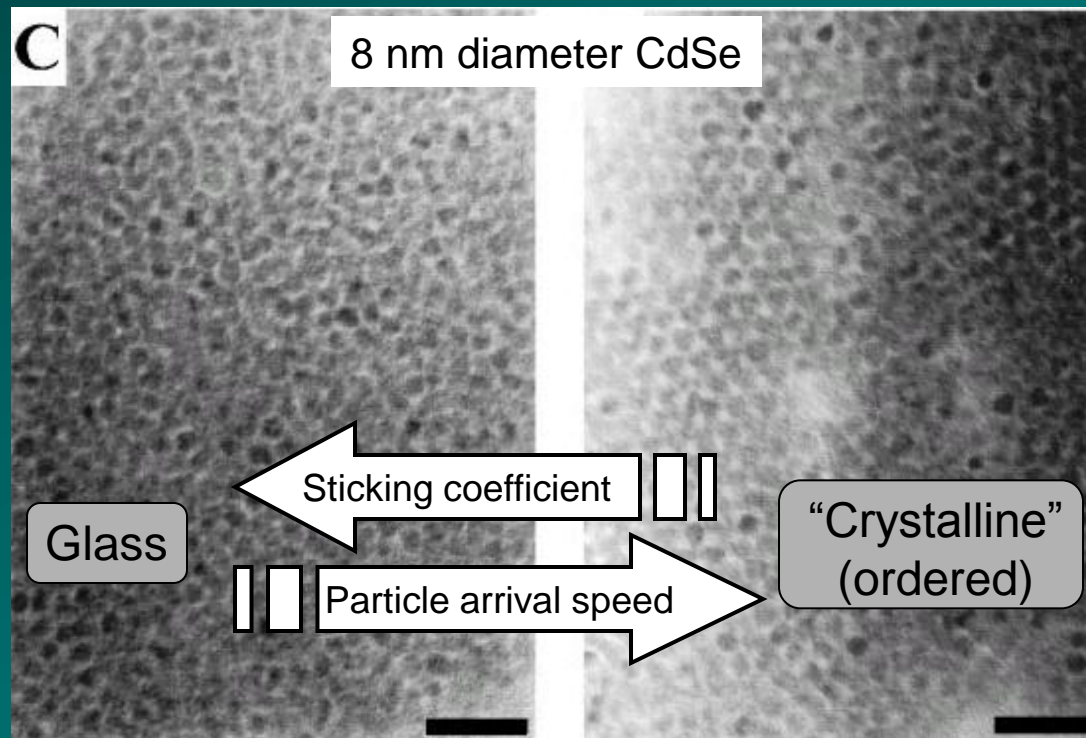
## 3. Layering of nanorods to form thin semiconductor films

- Single crystal nanorods possible (optimize nucleation, annealing)
- Can bind 2 nanocrystals for additional compositional control (e.g.  $\text{In}_x\text{Ga}_{1-x}\text{N}$ )

# Assembly and structural control

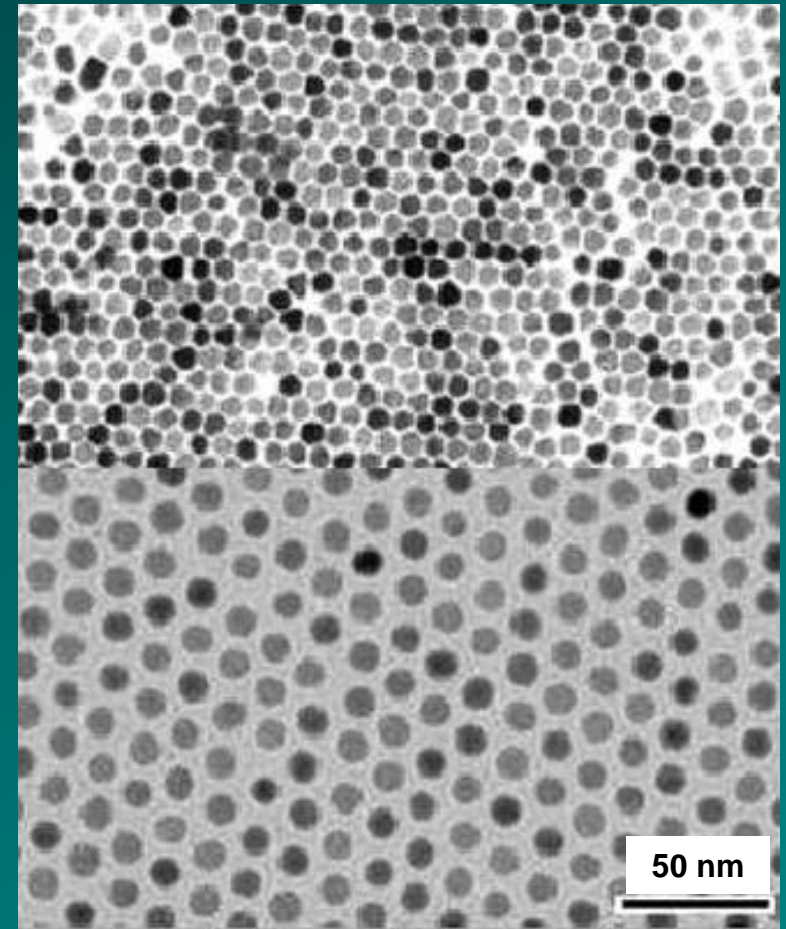
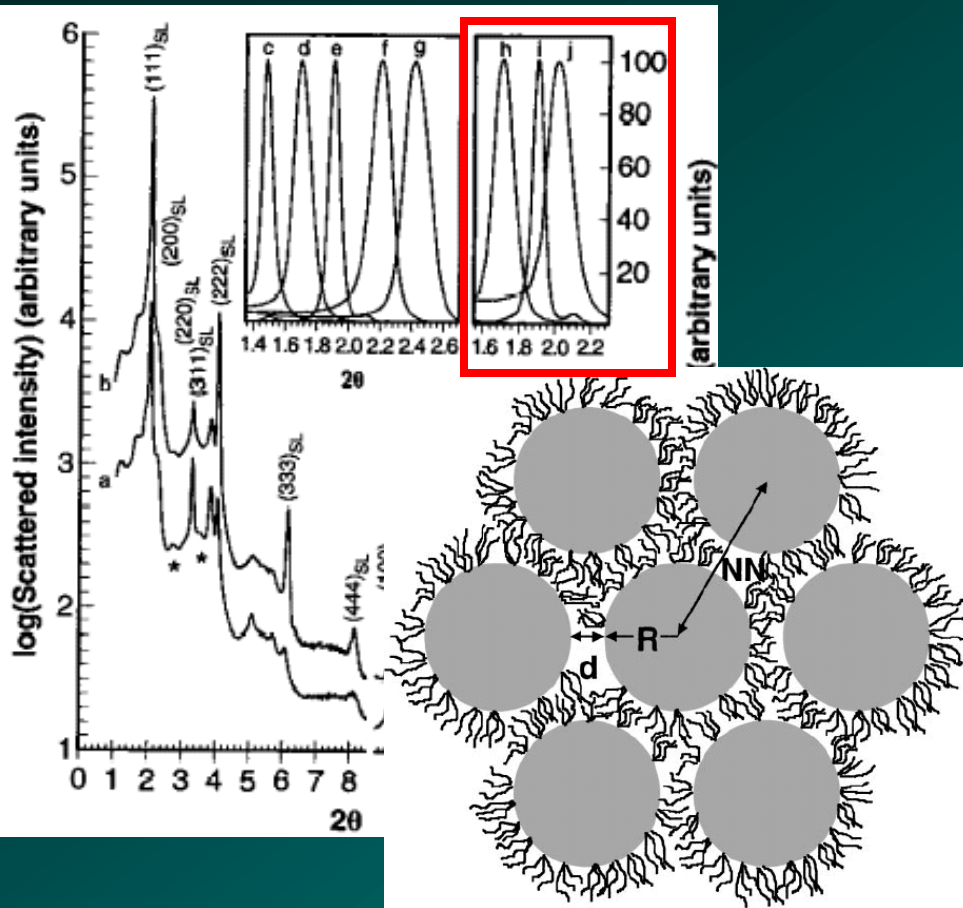


D.J. Norris, *Adv. Mater.* **16**, 1394 (2004)



C.B. Murray et al., *Annu. Rev. Mater. Sci.* **30**, 545 (2000)

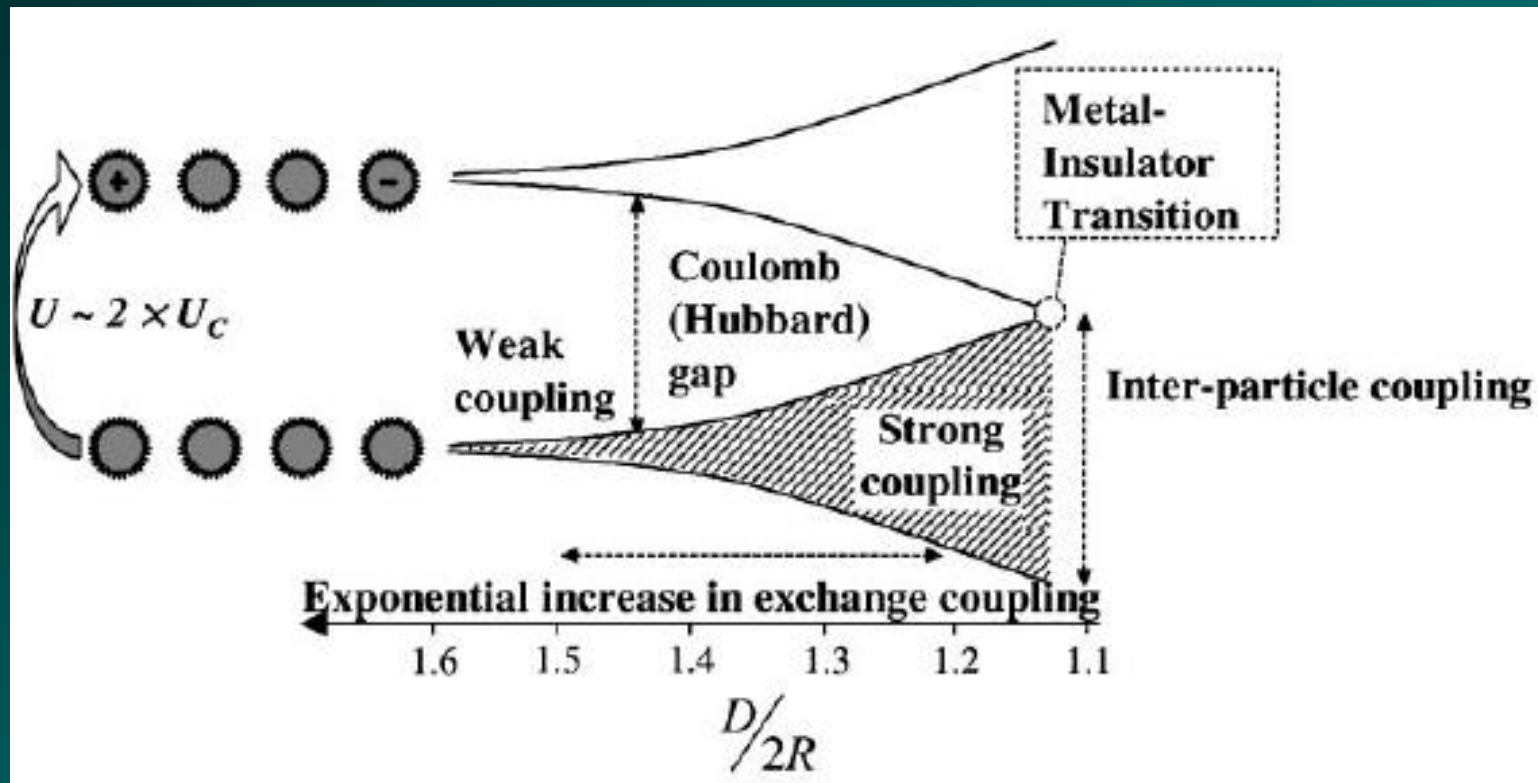
# QD-solid assembly: QD Distance Engineering



Curve	Capping agent	Atoms per chain	Interparticle distance (Å)
h	Trihexadecylphosphate	16	17
i	Trioctylphosphine calchogenide	8	11
j	Tributylphosphine oxide	4	7

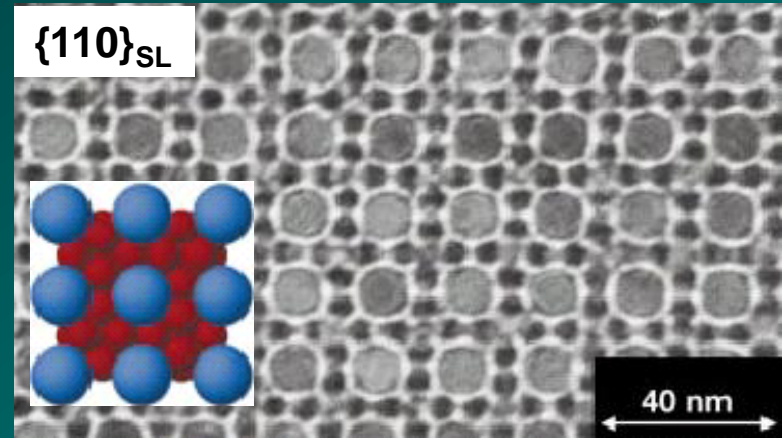
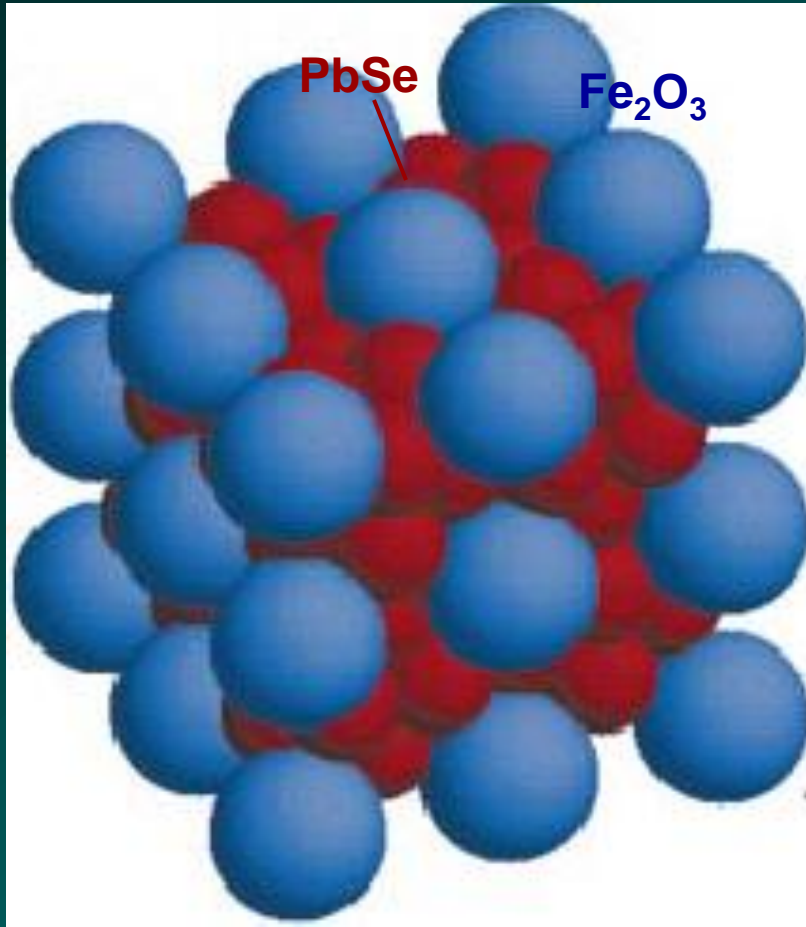
Y. Yin, A.P. Alivisatos, *Nature* **437**, 664 (2005)

# Electronic properties of colloidal solids





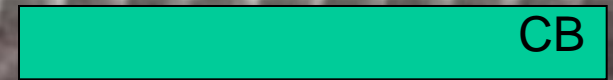
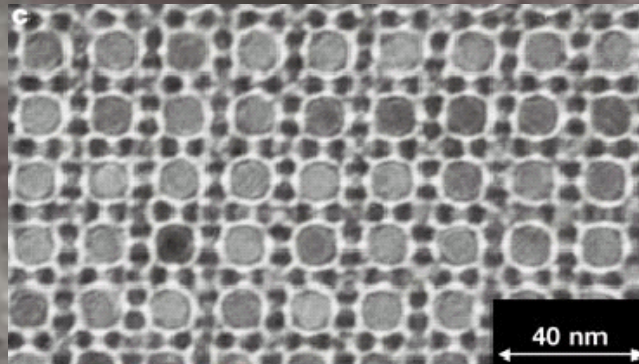
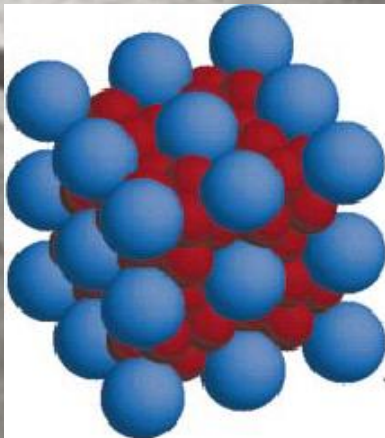
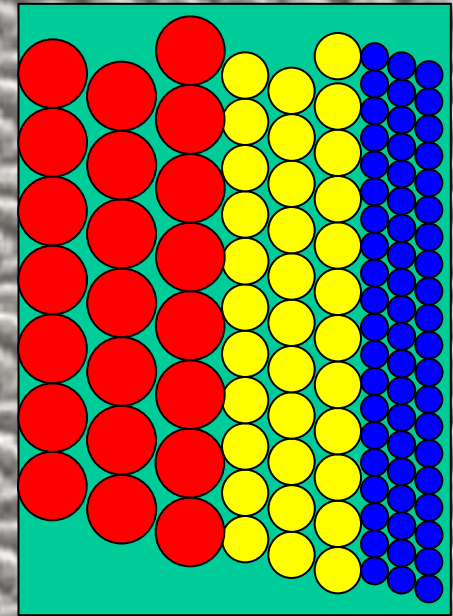
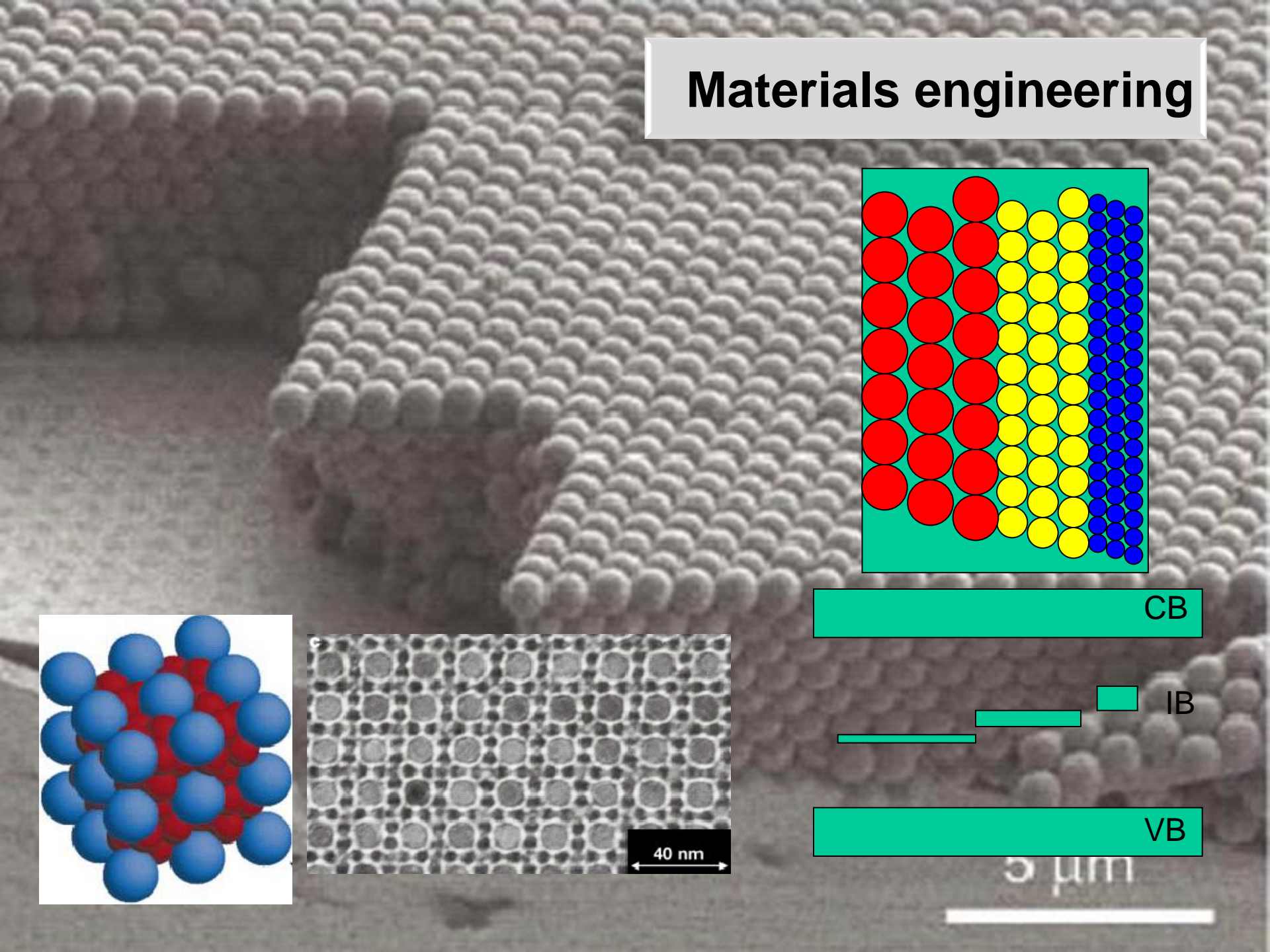
# QD-solid assembly: Bi-component QD-Solid



F.X. Redl et al., Nature 423, 968 (2003)



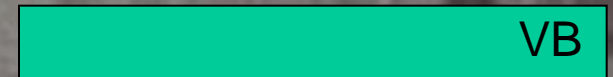
# Materials engineering



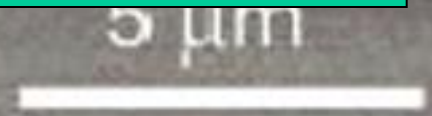
CB



IB



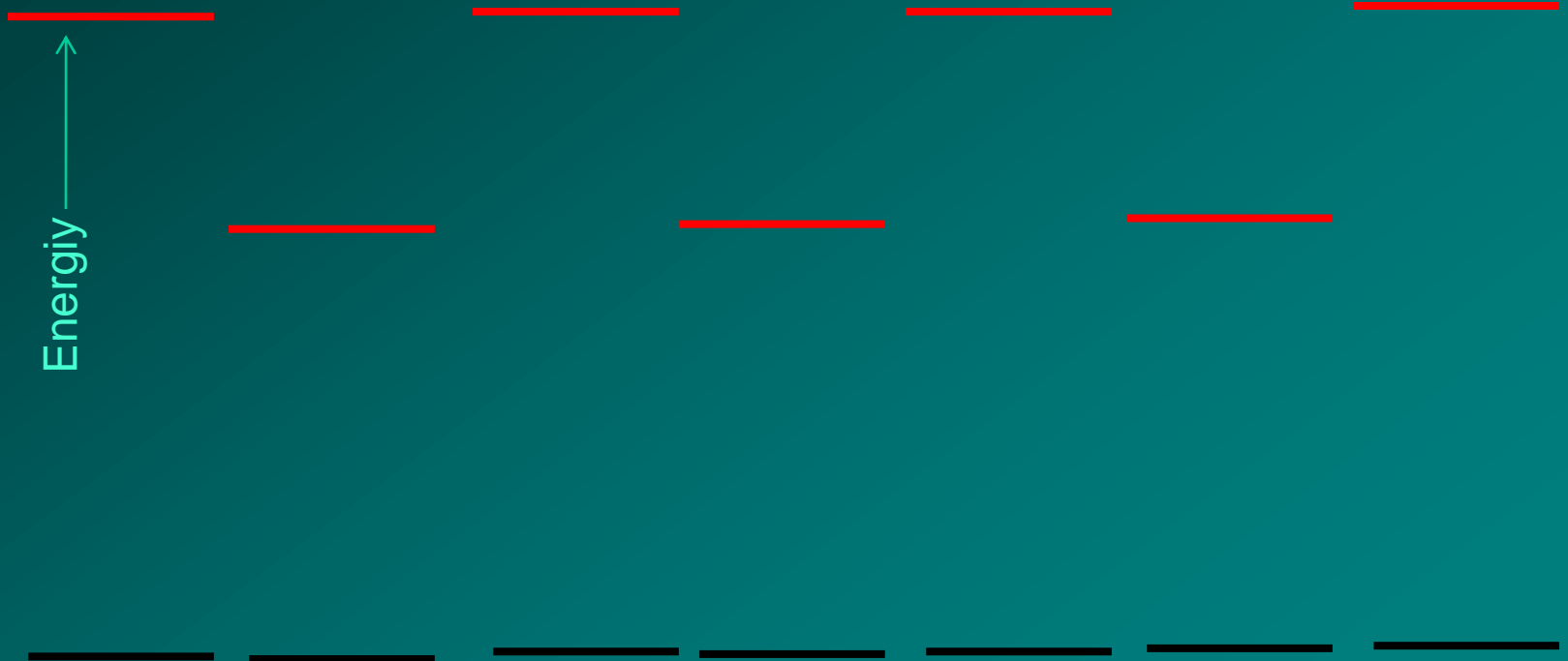
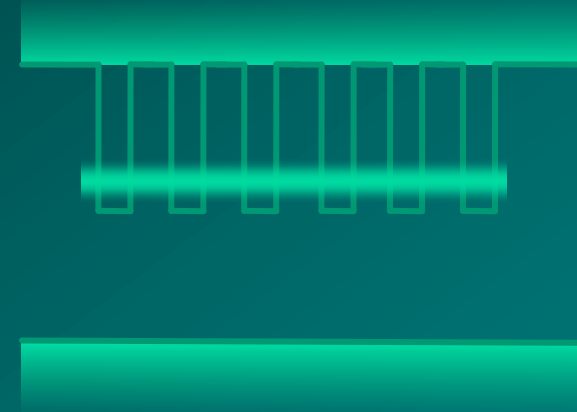
VB



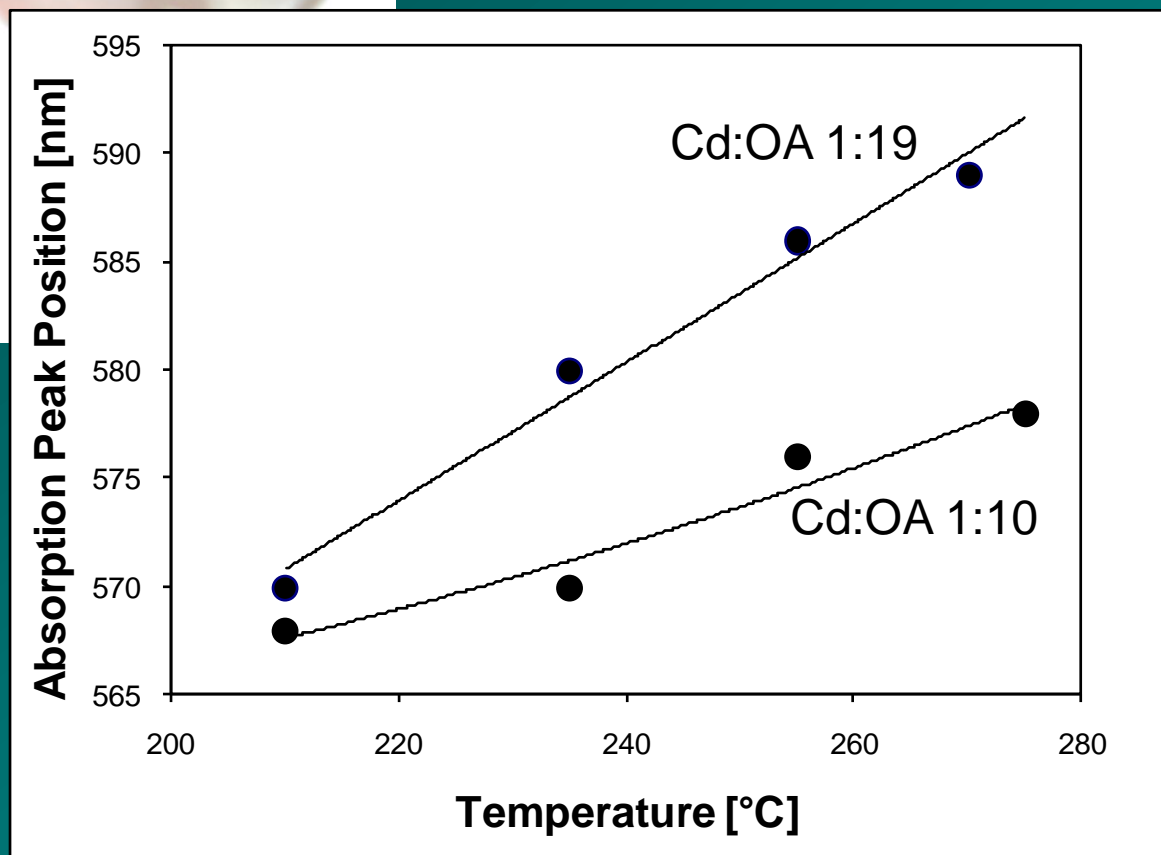
# Our approach for synthesizing an IB material

Matrice di ZnSe matrix – CdSe QDs

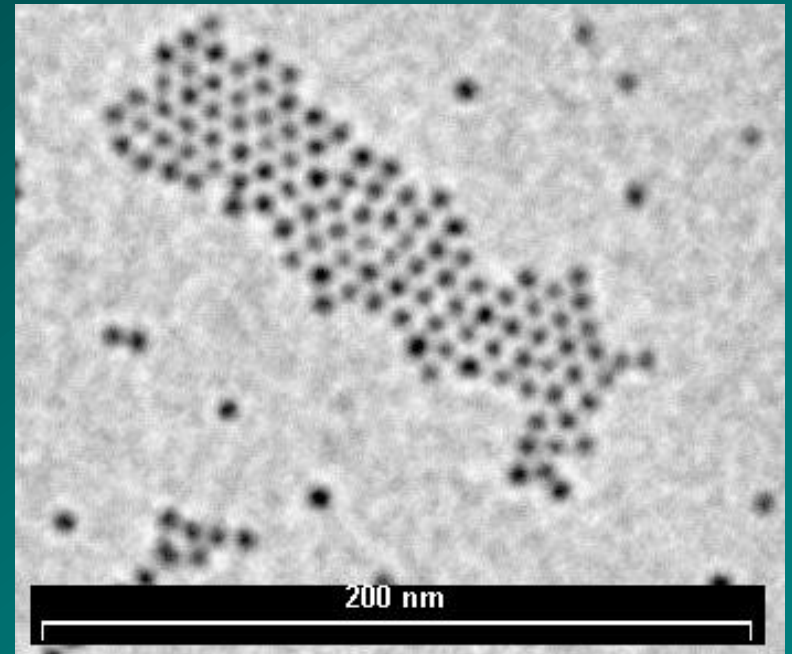
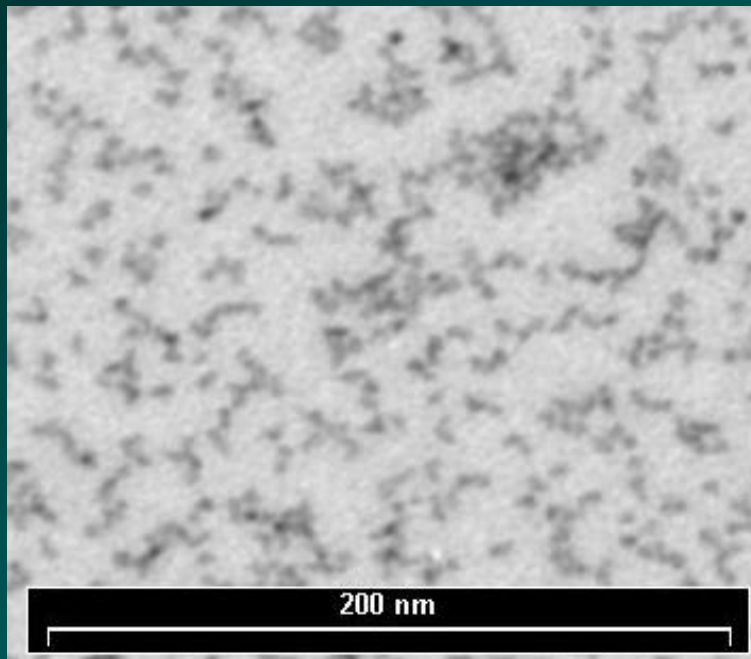
	ZnSe	CdSe	ZnSe
Electron affinity	4.09	4.95	4.09
Bandgap	2.58	1.74	2.58



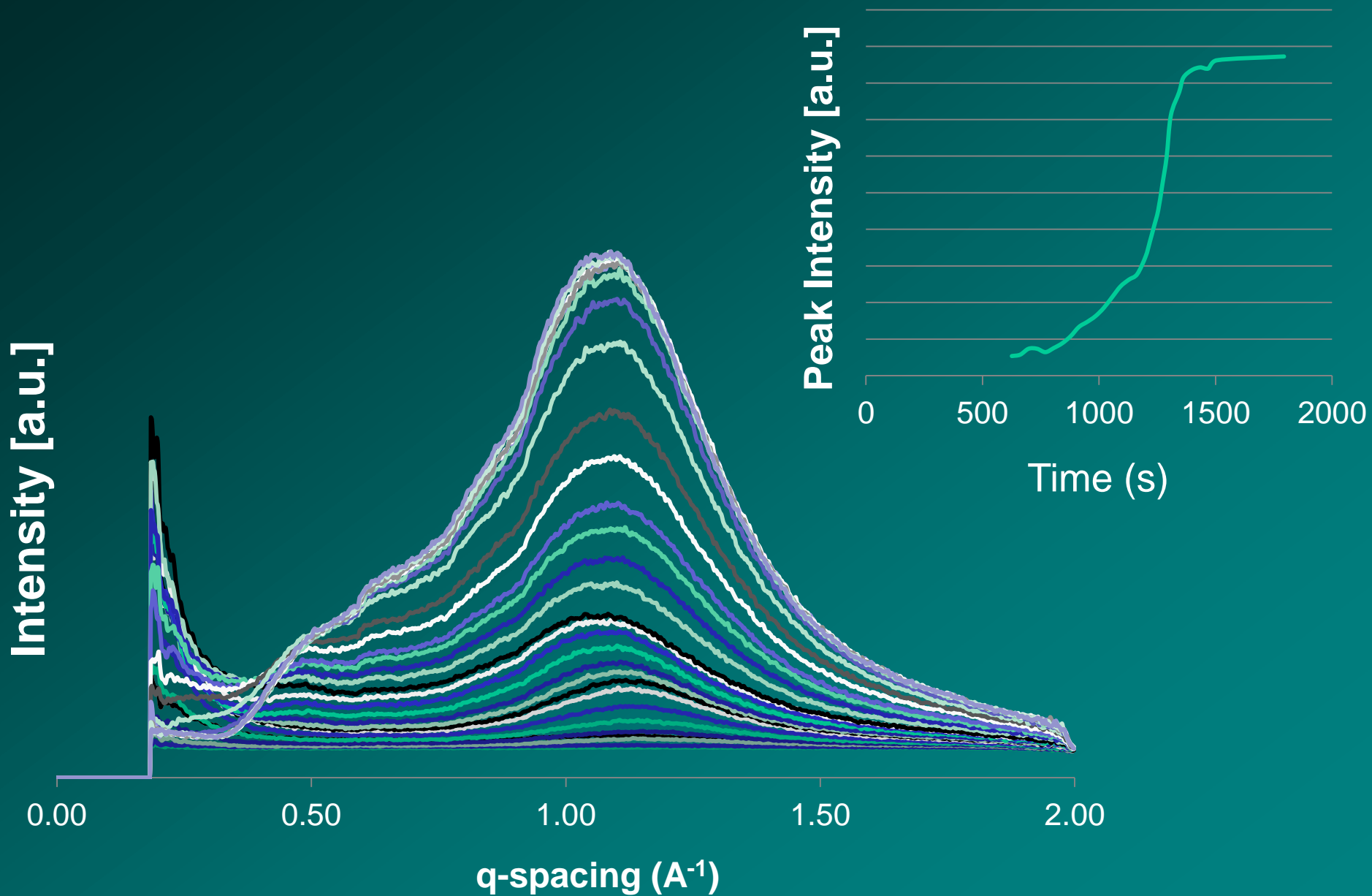
# NCs Growth Kinetics – Control of Size



# Assembly: Control of interparticle forces

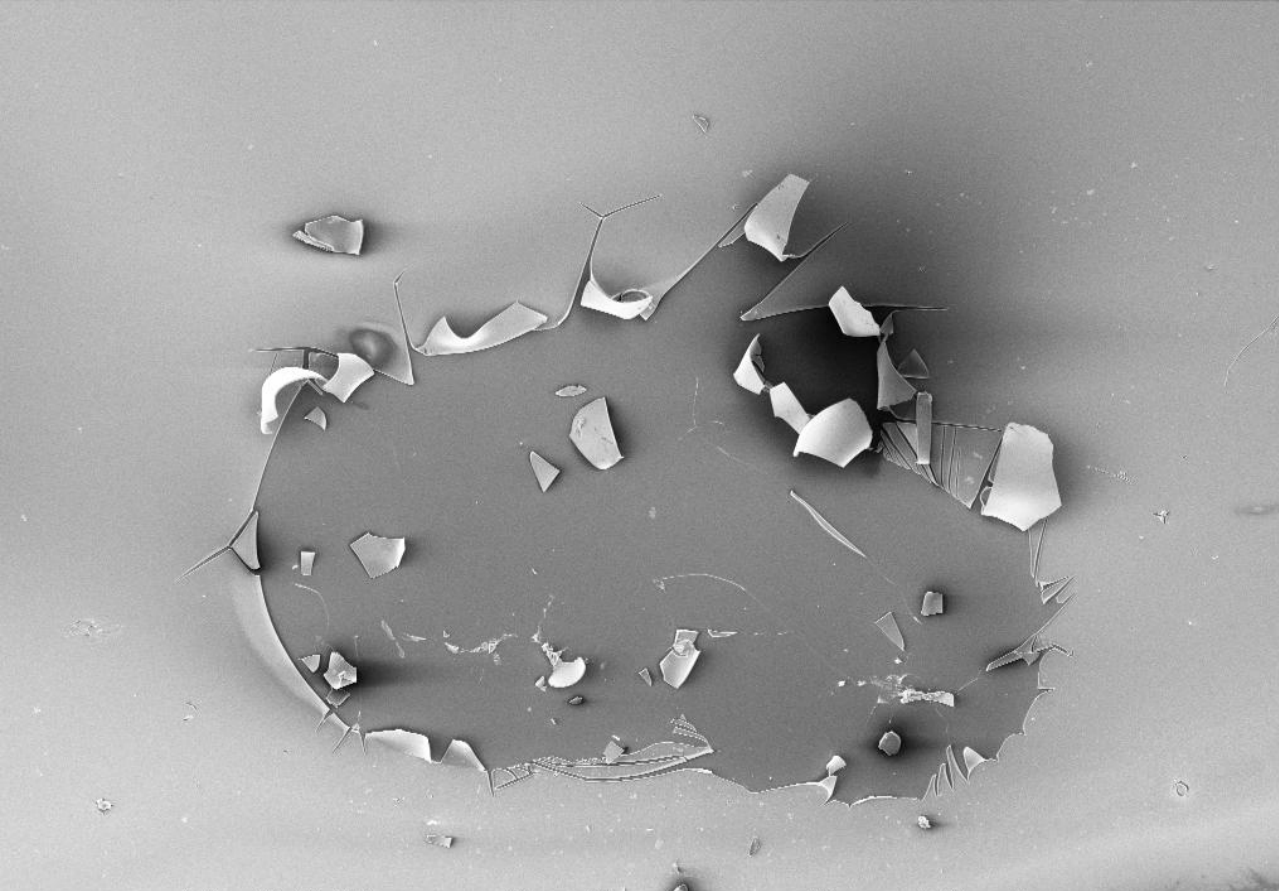


# Assembly: Ordering





# Uniform Thin Films of NC assemblies

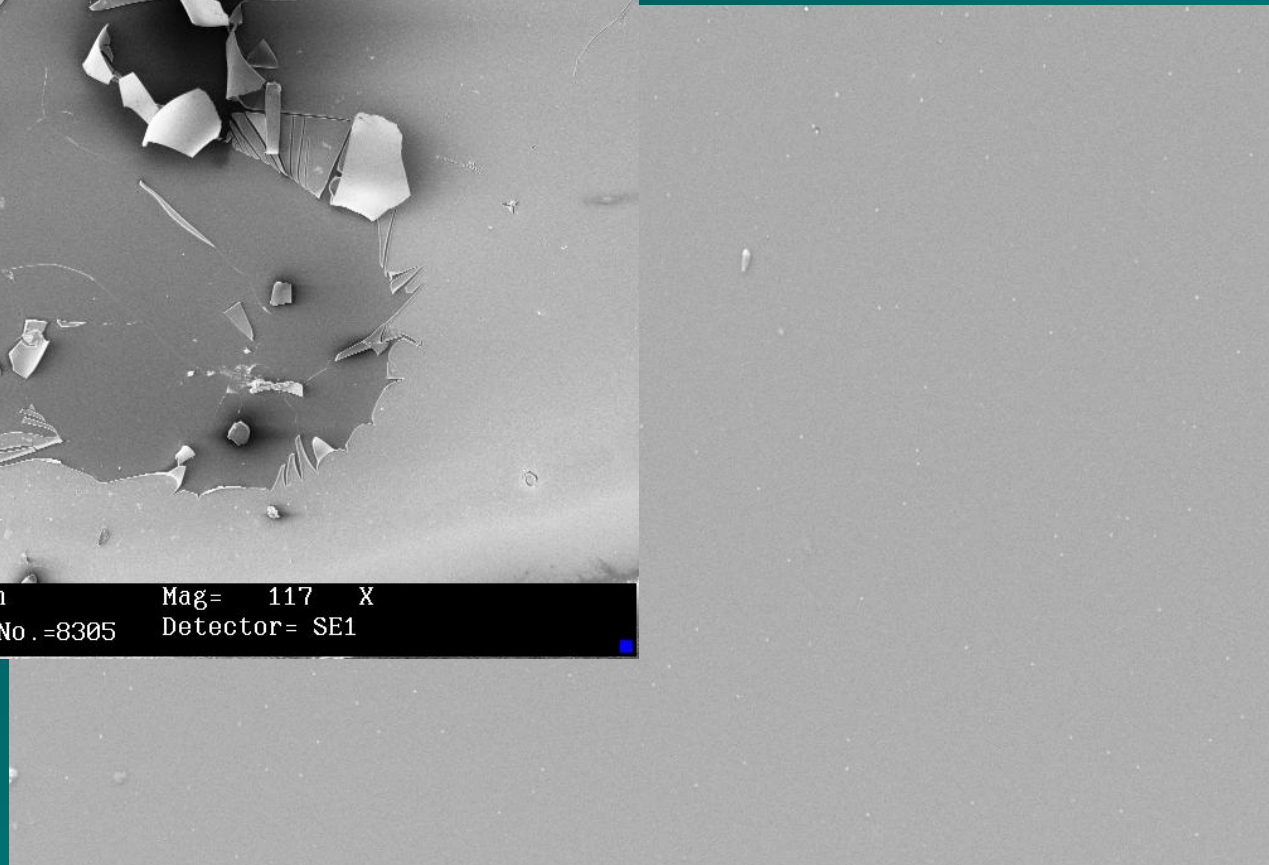


EHT=15.00 kV  
200µm

WD= 19 mm

Photo No.=8305

Mag= 117 X  
Detector= SE1



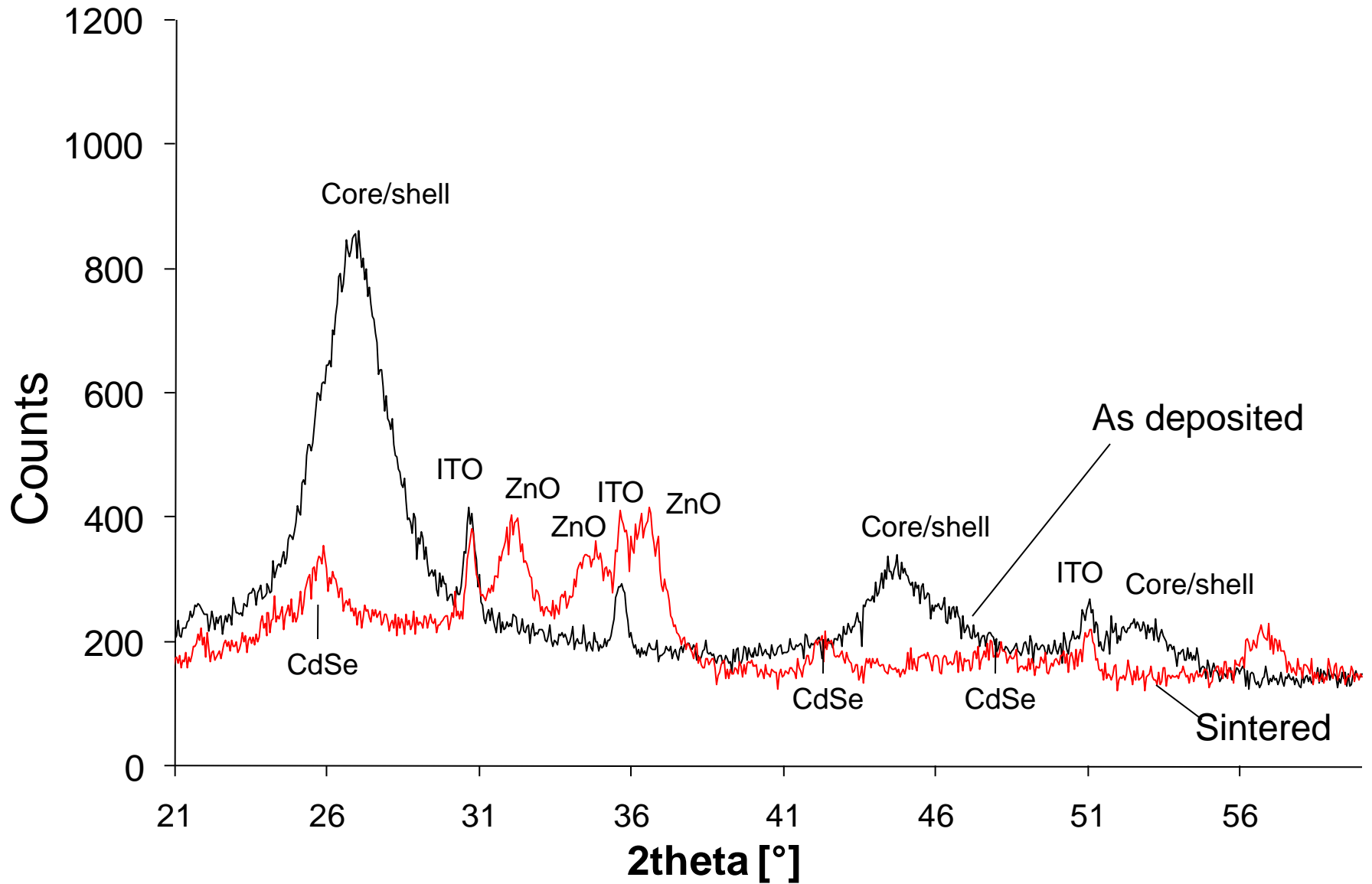
EHT=15.00 kV  
30µm

WD= 20 mm

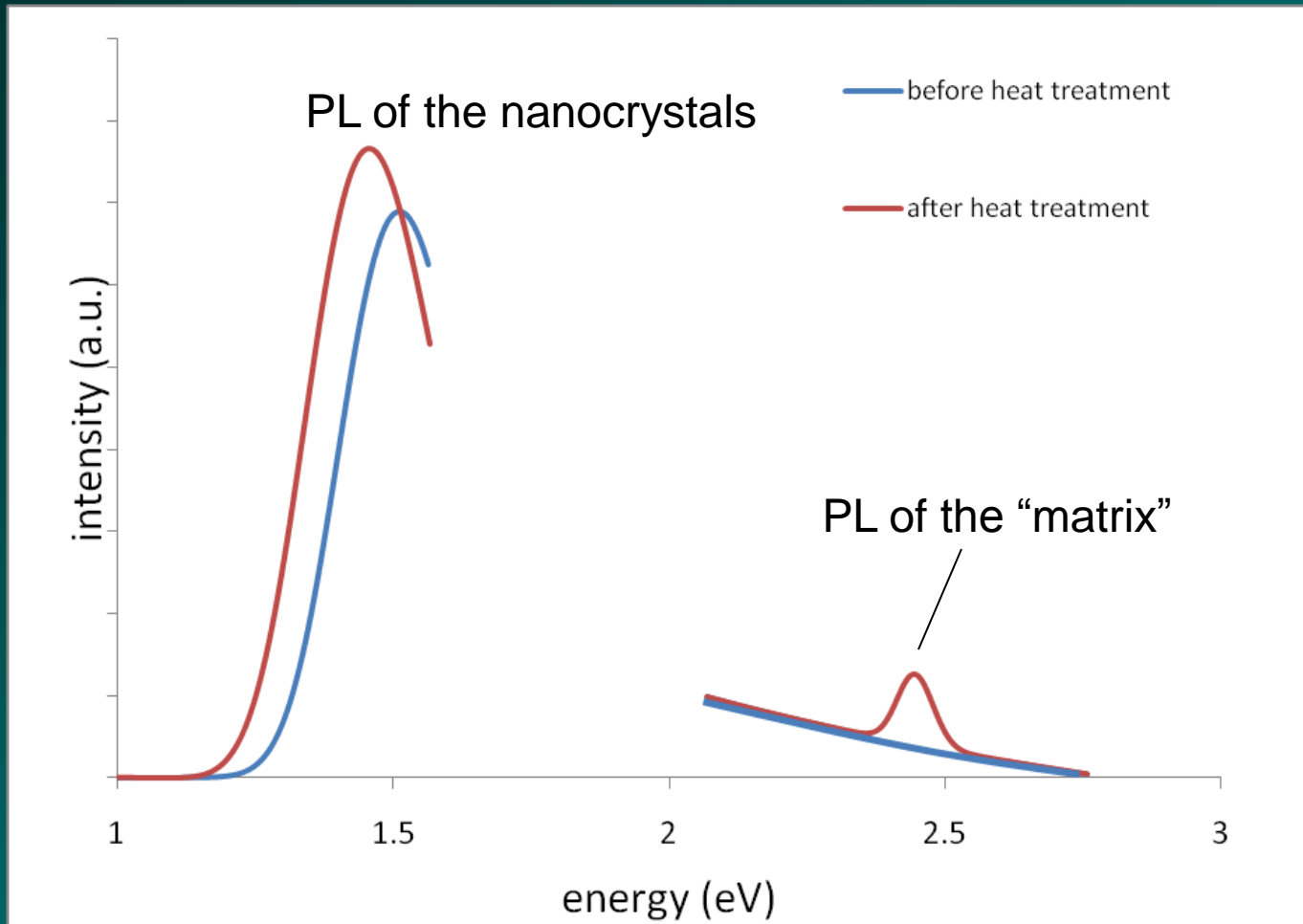
Photo No.=8308

Mag= 801 X  
Detector= SE1

# Densification of NC assemblies



# Optical properties of NC assemblies



# Concluding Remarks

- PV is at a “tipping point” – breakthrough technology is just around the corner
- Bio- and Nanotechnology will likely be the key to high performance, low cost PV devices
- Colloidal routes to fabricate PV materials are extremely promising:
  - The structure can be finely engineered at the nanoscale
  - Cost can be reduced (ambient process conditions)

# Aknowledgements

*Doctoral student:*

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*Students:*

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Giulio Pipan

Alice Orzan

Stefania Cacovich

Alice Furlan

Luca Pavan

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Mauro Del Ben

*Facilties:*

Dept. Materials and Natural Resources (DMRN)

Spectroscopy Lab DMRN





# State of the art

Table I. Confirmed terrestrial cell and submodule efficiencies measured under the global AM1.5 spectrum ( $1000 \text{ Wm}^{-2}$ ) at  $25^\circ\text{C}$

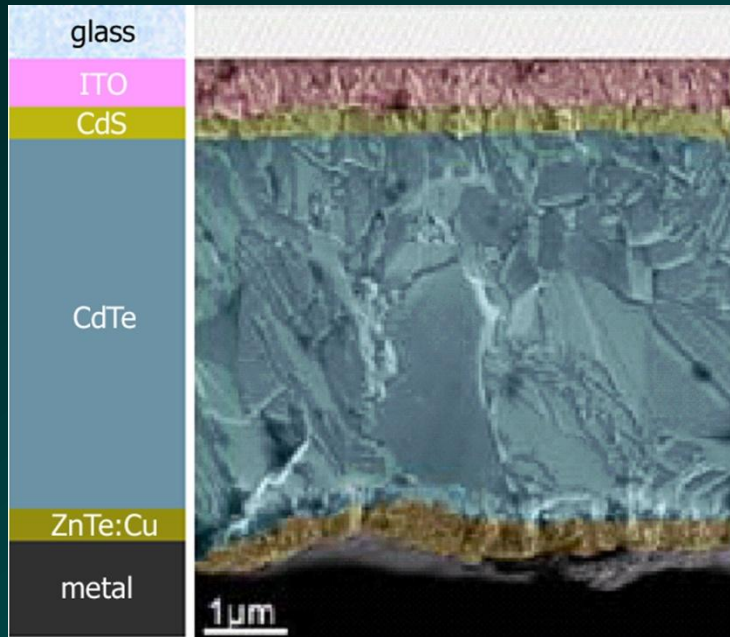
Classification*	Effic. <sup>†</sup> (%)	Area <sup>‡</sup> ( $\text{cm}^2$ )	$V_{oc}$ (V)	$J_{sc}$ ( $\text{mA}/\text{cm}^2$ )	FF <sup>§</sup> (%)	Test centre <sup>  </sup> (and Date)	Description
<b>Silicon</b>							
Si (crystalline)	$24.7 \pm 0.5$	4.00 (da)	0.706	42.2	82.8	Sandia (3/99)	UNSW PERL <sup>9</sup>
Si (multicrystalline)	$20.3 \pm 0.5$	1.002 (ap)	0.664	37.7	80.9	NREL (5/04)	FhG-ISE <sup>10</sup>
Si (thin-film transfer)	$16.6 \pm 0.4$	4.017 (ap)	0.645	32.8	78.2	FhG-ISE (7/01)	U. Stuttgart (45 $\mu\text{m}$ thick) <sup>11</sup>
<b>Si (thin-film submodule)</b>	<b><math>9.8 \pm 0.3</math></b>	<b>96.3 (ap)</b>	<b>0.487<sup>¶</sup></b>	<b>27.0<sup>¶</sup></b>	<b>74.5</b>	<b>Sandia (8/06)</b>	<b>CSG Solar (1–2 <math>\mu\text{m}</math> on glass; 20 cells)<sup>5</sup></b>
<b>III–V Cells</b>							
GaAs (crystalline)	$25.1 \pm 0.8$	3.91 (t)	1.022	28.2	87.1	NREL (3/90)	Kopin, AlGaAs window <sup>12</sup>
GaAs (thin-film)	$24.5 \pm 0.5$	1.002 (t)	1.029	28.8	82.5	FhG-ISE (5/05)	Radboud U., NL <sup>13</sup>
GaAs (multicrystalline)	$18.2 \pm 0.5$	4.011 (t)	0.994	23.0	79.7	NREL (11/95)	RTI, Ge substrate <sup>14</sup>
InP (crystalline)	$21.9 \pm 0.7$	4.02 (t)	0.878	29.3	85.4	NREL (4/90)	Spire, epitaxial <sup>15</sup>
<b>Thin-film chalcogenide</b>							
<b>CIGS (cell)</b>	<b><math>18.8 \pm 0.5^{\#}</math></b>	<b>0.998 (ap)</b>	<b>0.699</b>	<b>33.8</b>	<b>79.4</b>	<b>NREL (2/06)</b>	<b>NREL, CIGS on glass<sup>16</sup></b>
CIGS (submodule)	$16.6 \pm 0.4$	16.0 (ap)	0.661 <sup>¶</sup>	33.4 <sup>¶</sup>	75.1	FhG-ISE (3/00)	U. Uppsala, 4 serial cells <sup>17</sup>
CdTe (cell)	$16.5 \pm 0.5^{\#}$	1.032 (ap)	0.845	25.9	75.5	NREL (9/01)	NREL, mesa on glass <sup>18</sup>
<b>Amorphous/nanocrystalline Si</b>							
Si (amorphous)**	$9.5 \pm 0.3$	1.070 (ap)	0.859	17.5	63.0	NREL (4/03)	U. Neuchatel <sup>19</sup>
Si (nanocrystalline)	$10.1 \pm 0.2$	1.199 (ap)	0.539	24.4	76.6	JQA (12/97)	Kaneka (2 $\mu\text{m}$ on glass) <sup>20</sup>
<b>Photochemical</b>							
Dye sensitised		1.004 (ap)	0.729	21.8	65.2	AIST (8/05)	Sharp <sup>21</sup>
	$10.4 \pm 0.3$						
Dye sensitised (submodule)	$6.3 \pm 0.2$	26.5 (ap)	6.145	1.70	60.4	AIST (8/05)	Sharp <sup>22</sup>
<b>Organic</b>							
Organic polymer <sup>††</sup>	$3.0 \pm 0.1$	1.001 (ap)	0.538	9.68	52.4	AIST (3/06)	Sharp, fullerene derivative <sup>23</sup>
<b>Multijunction devices</b>							
GaInP/GaAs/Ge	$32.0 \pm 1.5$	3.989 (t)	2.622	14.37	85.0	NREL (1/03)	Spectrolab (monolithic)
GaInP/GaAs	30.3	4.0 (t)	2.488	14.22	85.6	JQA (4/96)	Japan Energy (monolithic) <sup>24</sup>
GaAs/CIS (thin-film)	$25.8 \pm 1.3$	4.00 (t)	-	-	-	NREL (11/89)	Kopin/Boeing (4 terminal) <sup>25</sup>
a-Si/ $\mu\text{c}$ -Si (thin submodule) <sup>††</sup>	$11.7 \pm 0.4$	14.23 (ap)	5.462	2.99	71.3	AIST (9/04)	Kaneka (thin-film) <sup>26</sup>

# Stato dell'arte

Table II. Confirmed terrestrial module efficiencies measured under the global AM1.5 spectrum ( $1000 \text{ W/m}^2$ ) at a cell temperature of  $25^\circ\text{C}$

Classification*	Effic. <sup>†</sup> (%)	Area <sup>‡</sup> ( $\text{cm}^2$ )	$V_{oc}$ (V)	Isc (A)	FF <sup>§</sup> (%)	Test centre (and Date)	Description
Si (crystalline)	$22.7 \pm 0.6$	778 (da)	5.60	3.93	80.3	Sandia (9/96)	UNSW/Gochermann <sup>27</sup>
Si (multicrystalline)	$15.3 \pm 0.4^{\parallel}$	1017 (ap)	14.6	1.36	78.6	Sandia (10/94)	Sandia/HEM <sup>28</sup>
Si (thin-film polycrystalline)	$8.2 \pm 0.2$	661 (ap)	25.0	0.318	68.0	Sandia (7/02)	Pacific Solar (1–2 $\mu\text{m}$ on glass) <sup>29</sup>
CIGSS	$13.4 \pm 0.7$	3459 (ap)	31.2	2.16	68.9	NREL (8/02)	Showa Shell (Cd free) <sup>30</sup>
CdTe	$10.7 \pm 0.5$	4874 (ap)	26.21	3.205	62.3	NREL (4/00)	BP Solarex <sup>31</sup>
a-Si/a-SiGe/a-SiGe (tandem) <sup>¶</sup>	$10.4 \pm 0.5$	905 (ap)	4.353	3.285	66.0	NREL (10/98)	USSC (a-Si/a-Si/a-Si:Ge) <sup>32</sup>

# Moduli basati su film sottile



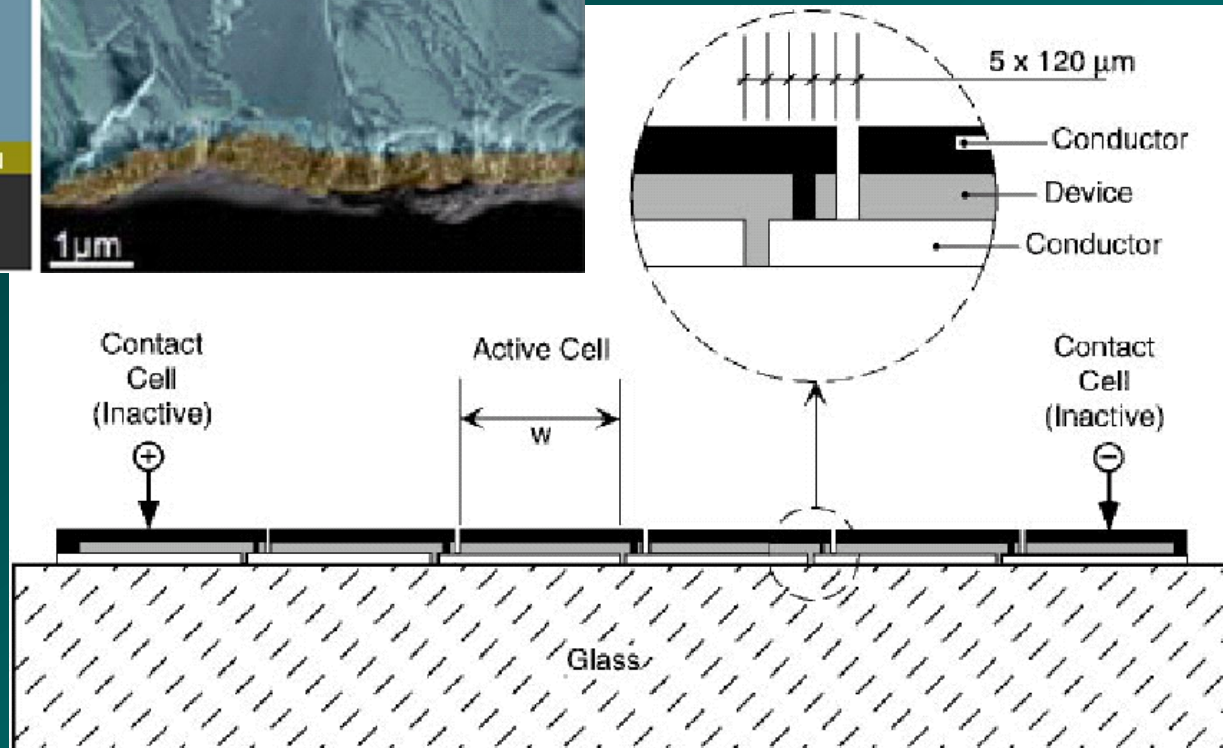
Materiali con eccellente assorbimento della radiazione solare



Piccoli spessori

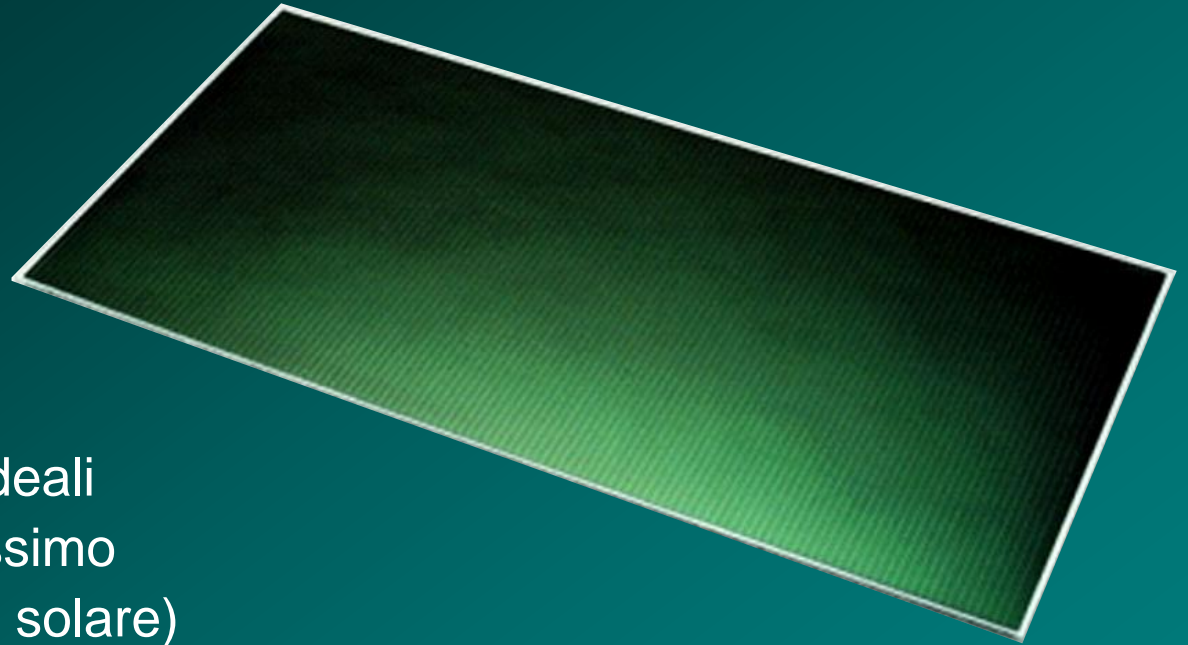


- Stabilità dei costi
- Sostenibilità degli approvvigionamenti
- Flessibilità nella scelta del substrato
- Moduli integrati



Esempi: Silicio amorfo; CIGS; CdTe

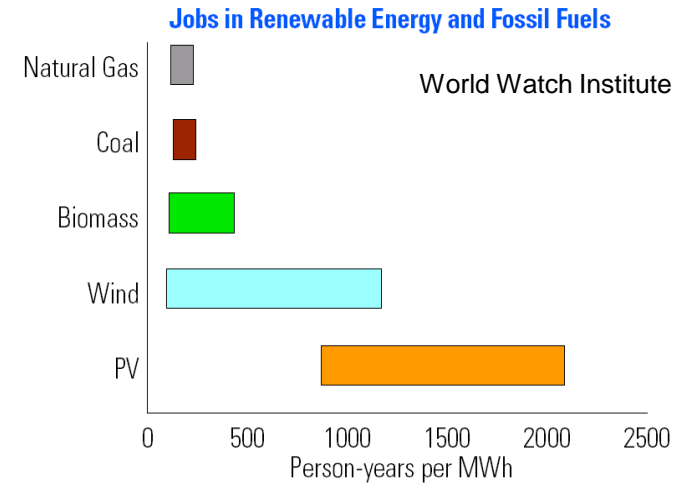
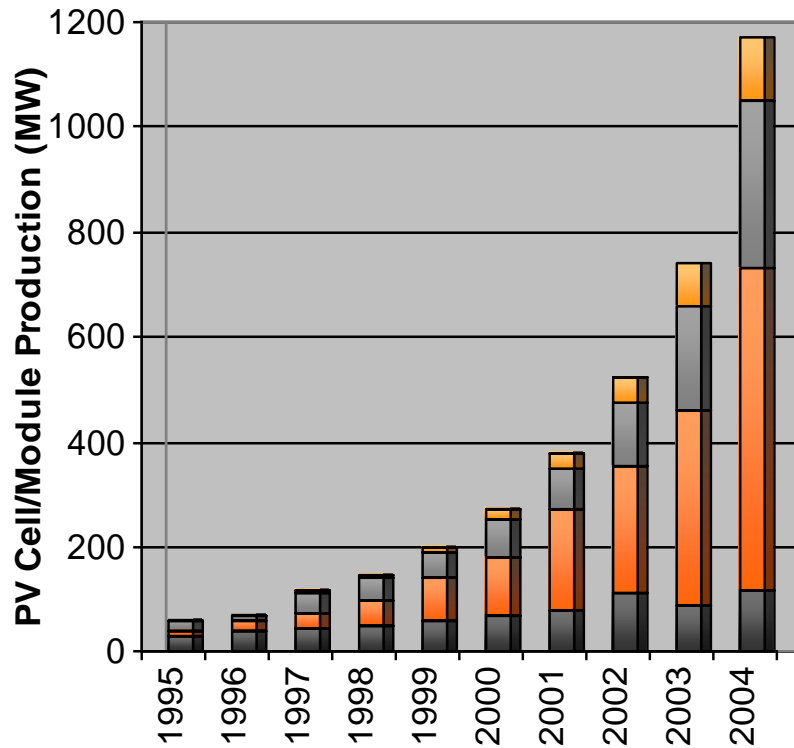
# Moduli basati su film sottili di CdTe



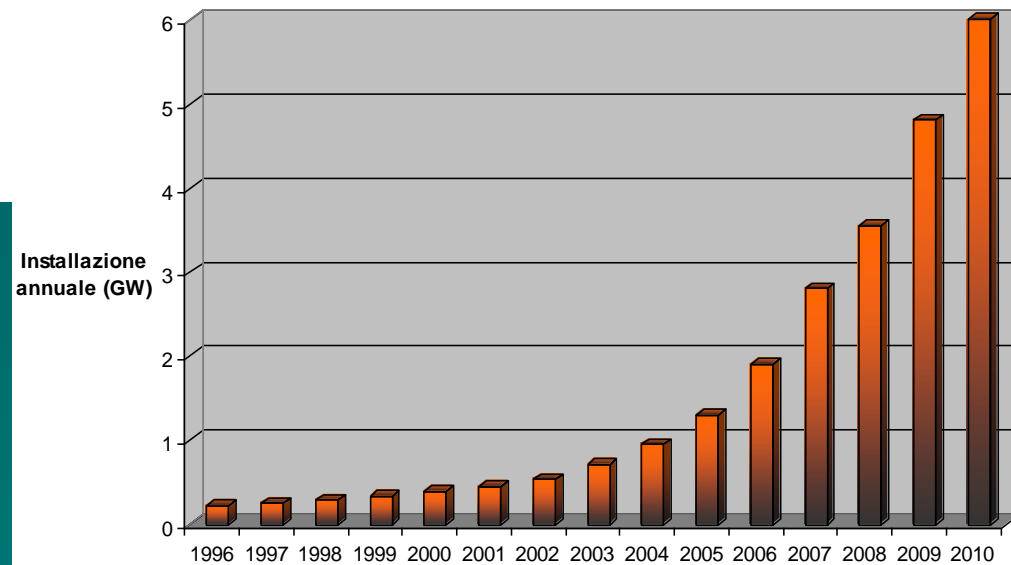
- Proprietà elettroniche ideali  
(bandgap 1.5 eV – massimo  
utilizzo della radiazione solare)
- Disponibilità delle materie prime
- Robustezza e varietà di processi  
produttivi disponibili
- Provata fattibilità industriale  
(First Solar; Antec)



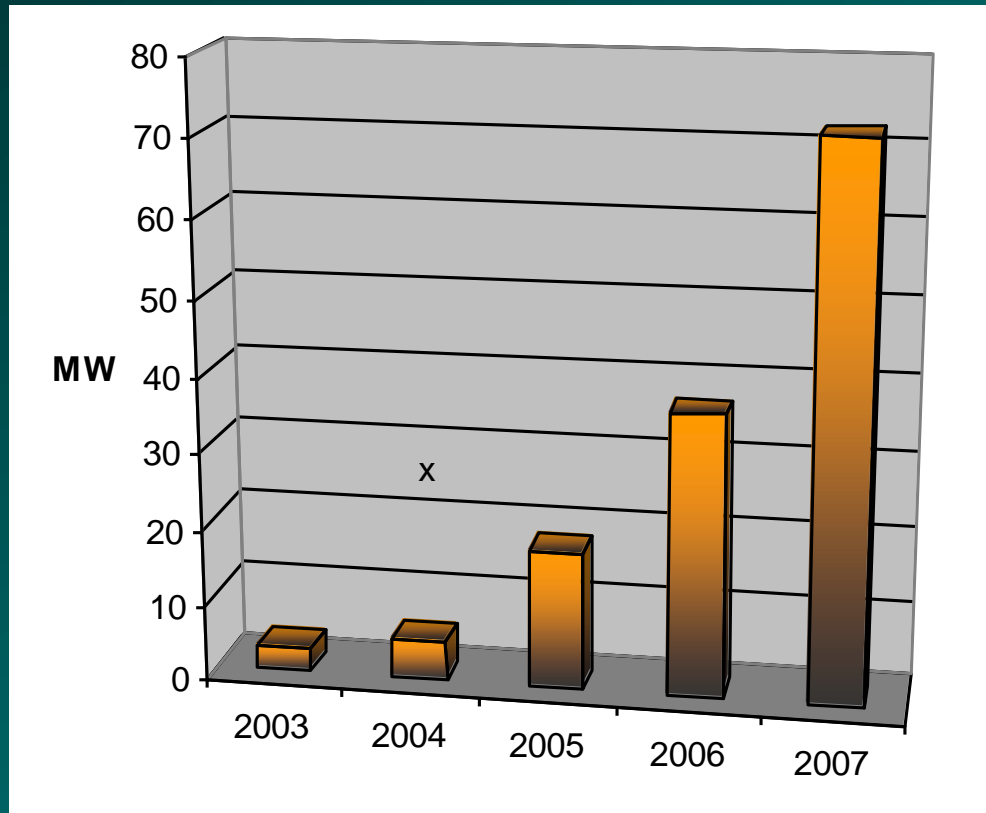
# Economia dell'industria fotovoltaica



Fatturato complessivo ~ 10 Mld. €/anno  
Crescita media ~ 35%/anno



# Vendite First Solar



# Costo dell'energia fotovoltaica

$$\$/\text{peak watt} \sim [\text{module cost}(\$/\text{m}^2) + \text{BOS cost}(\$/\text{m}^2)]/\text{Eff} + 0.1$$

where:

Eff = cell conversion efficiency x 1000 W/m<sup>2</sup> ( $W_p/\text{m}^2$ )

BOS = balance of systems (support structure, installation, wiring, land, etc)

\$0.1 = power conditioner, AC – DC inverter

$$\text{Also: } 1\$/W_p \cong \$0.05/\text{kWh}$$

To achieve \$0.02/kWh (fossil fuel cost), total cost  $\cong$  \$0.40/  $W_p$

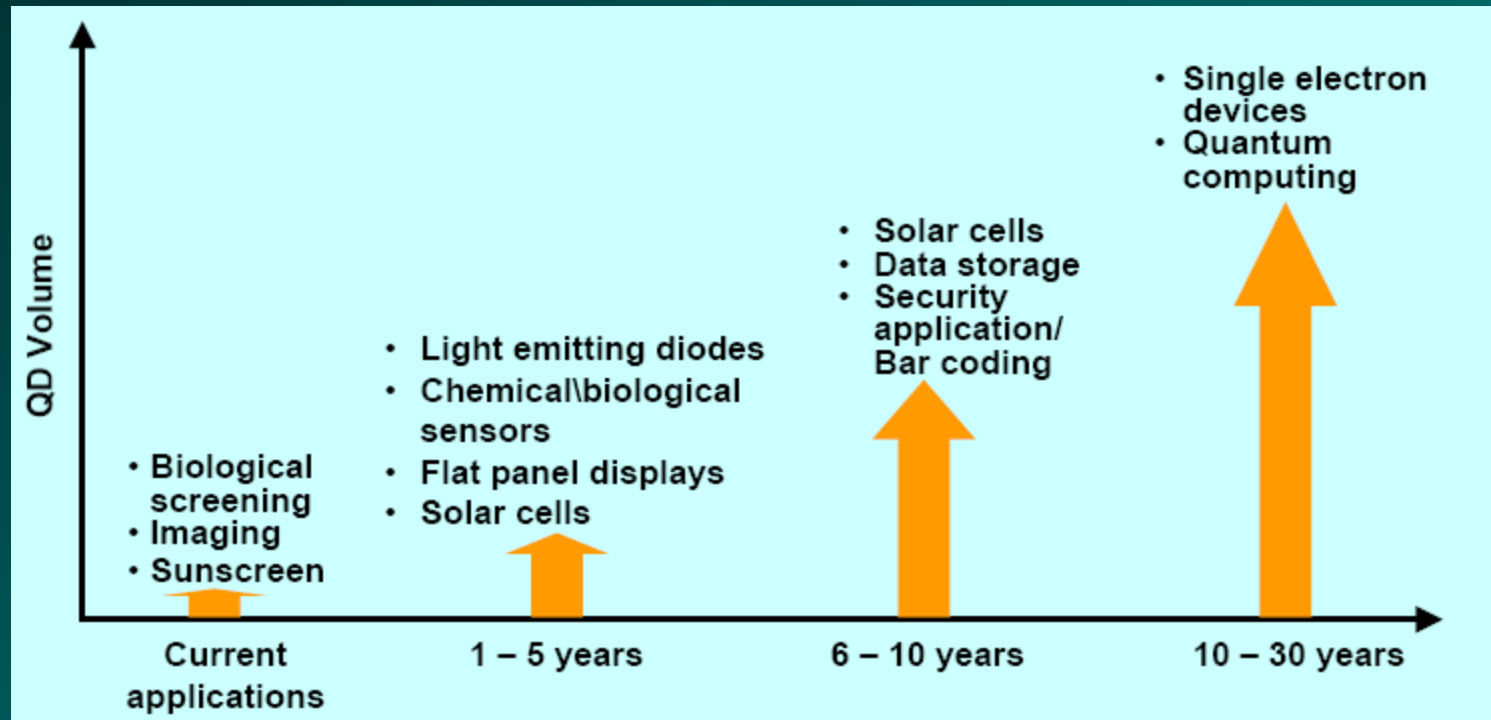
Current costs: Modules  $\sim$  \$350/m<sup>2</sup>; BOS  $\sim$  \$250/m<sup>2</sup>;

Thus,  $\$/W_p \sim \$600/(0.10 \times 1000) \sim \$6/W_p \sim \$0.30/\text{kWh}$

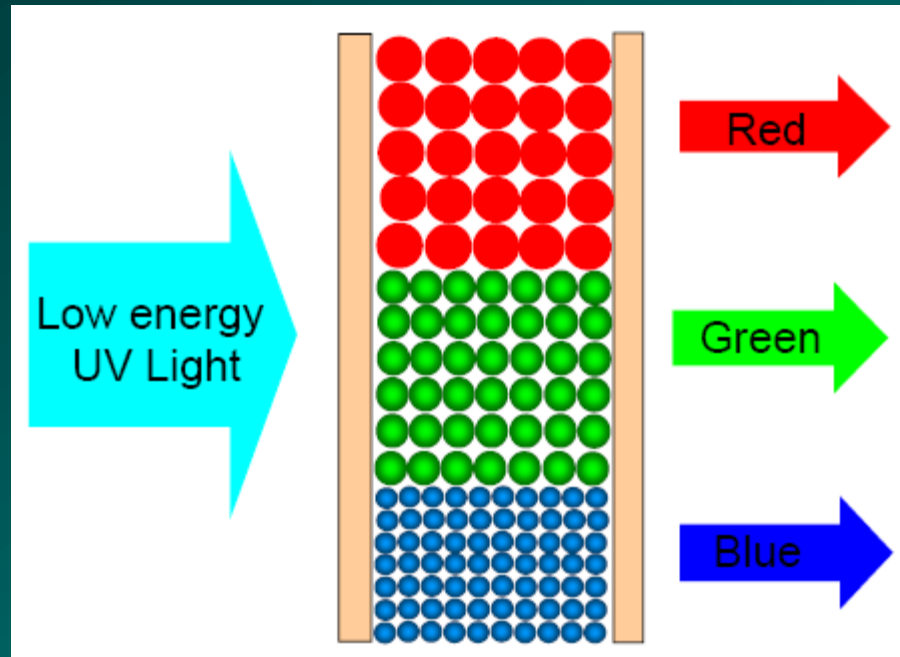
If **BOS** can be reduced to **\$70/ m<sup>2</sup>** and **module cost** reduced to **\$50/ m<sup>2</sup>** then **module efficiency** needs to be **30%** and **cell efficiency** at least **50%**. **(Note: this is the new DARPA goal)**

**Both Low Cost and High Efficiency are Needed !!**

# Altre applicazioni



# Schermi piatti



Basso consumo

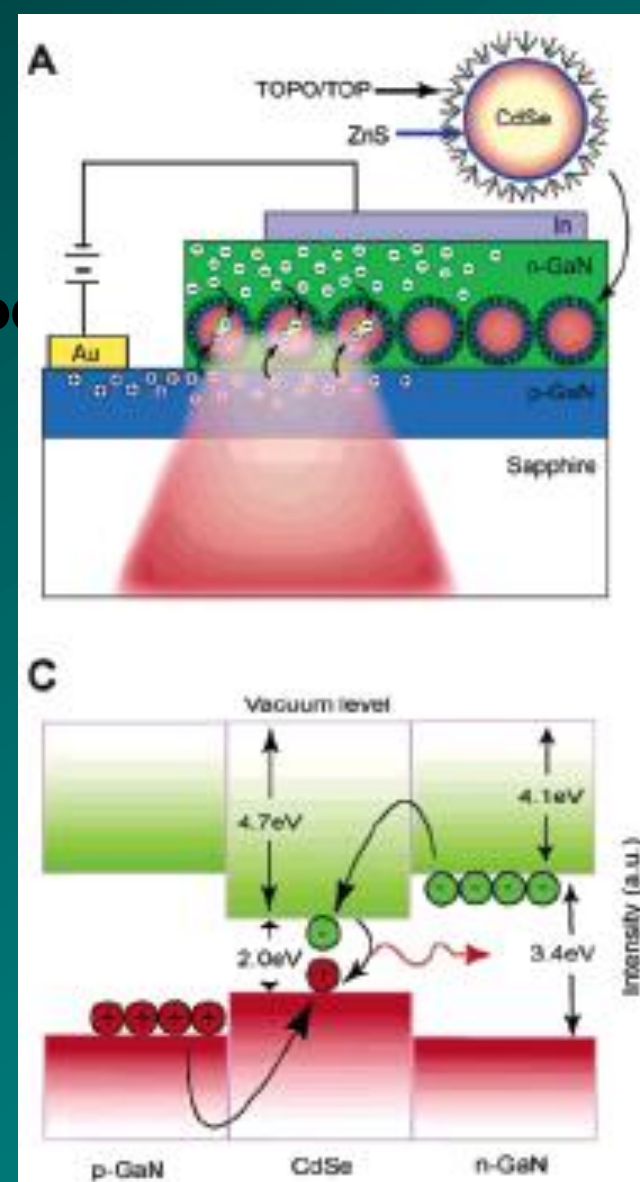
Alta efficienza

Un solo materiale per vari colori



# QD-LED

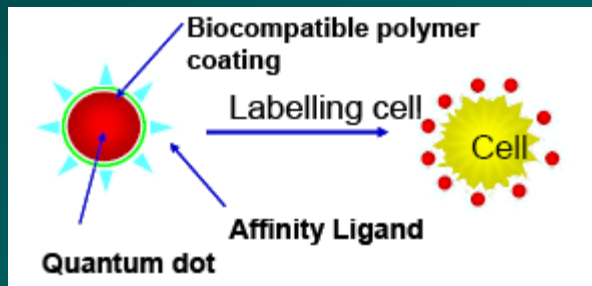
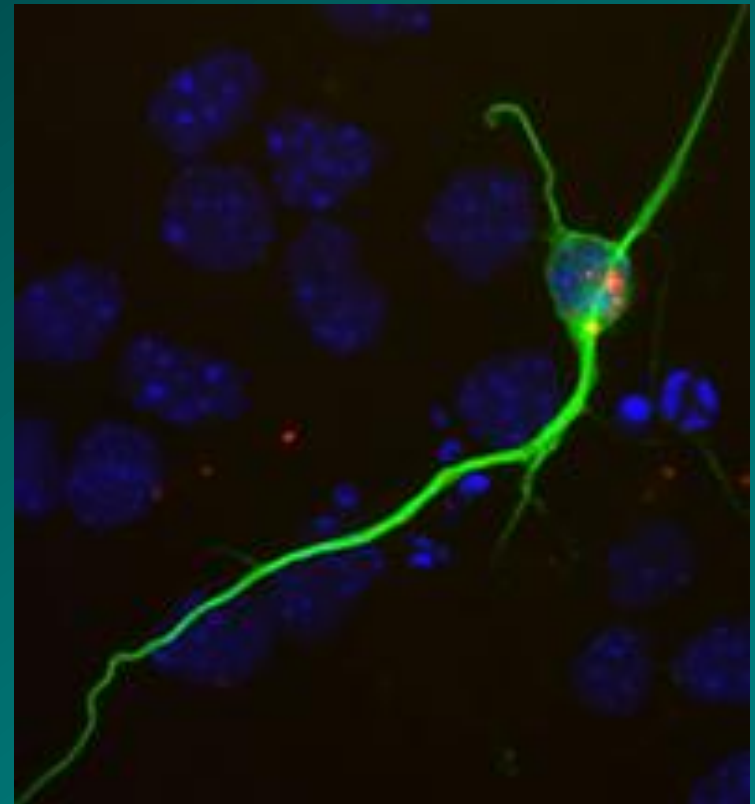
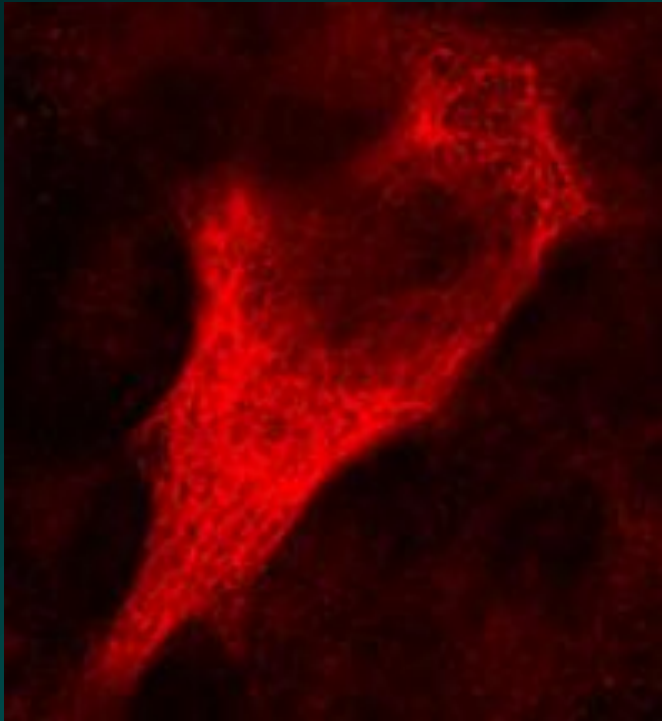
Quantum Dot-Based Light-Emitting Diode



La selezione della **dimensione dei nanocristalli** consente la **scelta del colore** da uno spettro continuo

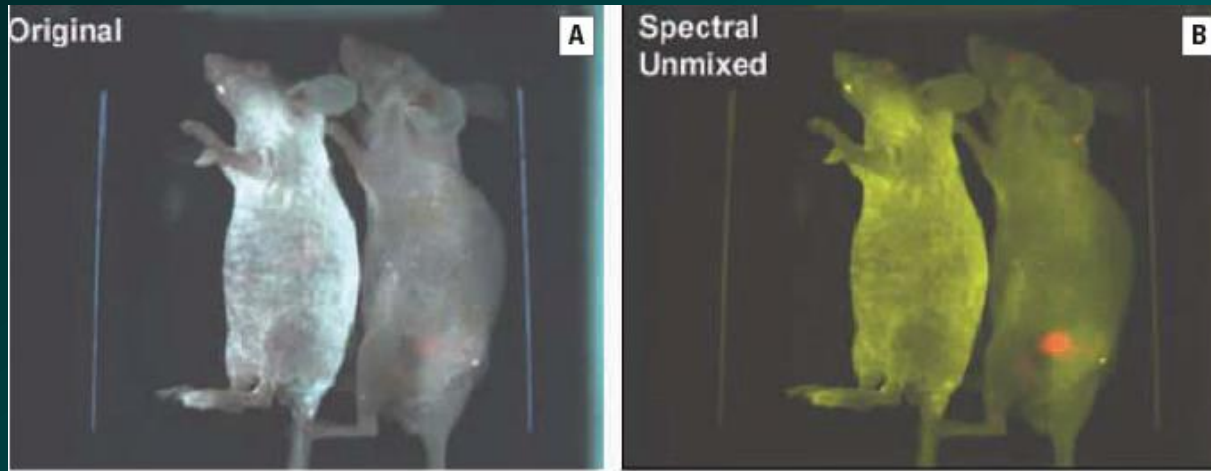
Applicazioni: Display più luminosi, con miglior riproduzione del colore, a basso consumo

# Dyes biocompatibili



Studio del comportamento di cellule, ed in generale degli esseri

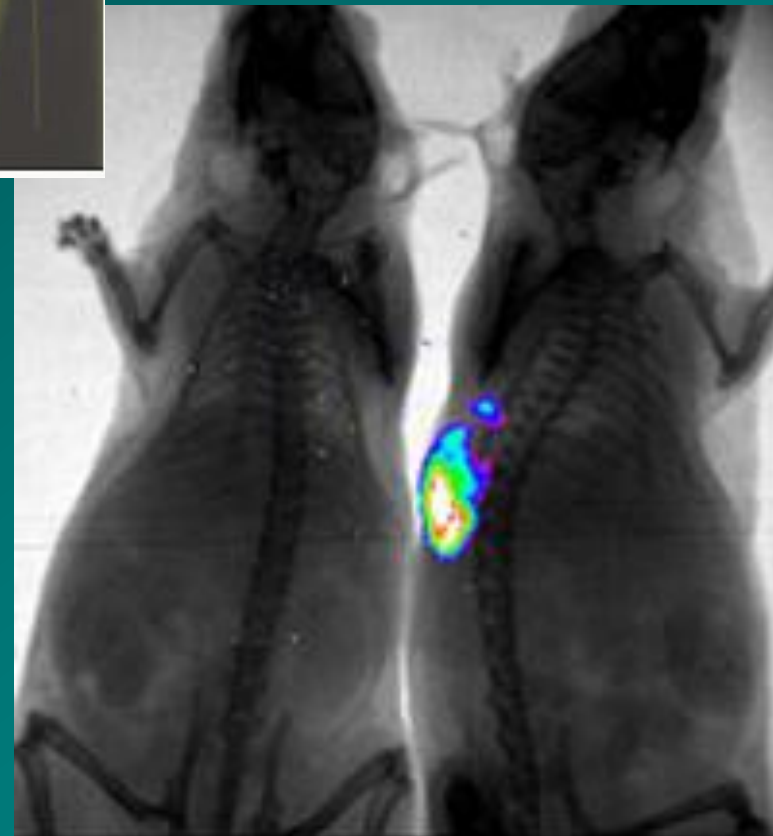
# Diagnosi e cura dei tumori



Le nanoparticelle vengono funzionalizzate in modo da venir accumulate presso il tumore

Le proprietà di emissione vengono utilizzate per individuare il tumore

Le proprietà di assorbimento vengono utilizzate per eliminare il tumore



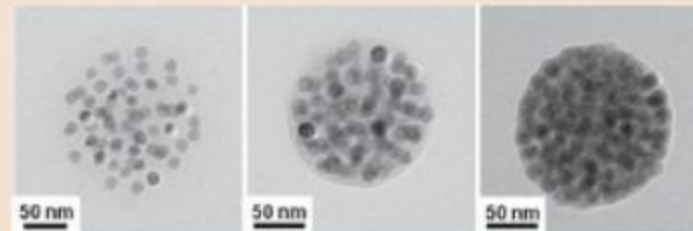


Considerable efforts are being directed toward developing multifunctional nanomedicines. Researchers from the Korea Advanced Institute of Science and Technology and Seoul National University have developed polymer nanoparticles (NPs) that act as multimodal imaging probes and use magnetic guidance to improve drug delivery [Kim *et al.*, *Adv. Mater.* (2008) 20, 478].

The platform comprises four key components:

(i) biodegradable poly(D,L-lactic-co-glycolic acid) (PLGA) NPs (100–200 nm in diameter) as the polymer matrix; (ii) hydrophobic, inorganic nanocrystals embedded into the matrix, either superparamagnetic  $\text{Fe}_3\text{O}_4$  nanocrystals (15 nm diameter) for MRI contrast and magnetically guided drug delivery or CdSe/ZnS semiconductor quantum dots (3 nm in diameter) for optical imaging; (iii) the chemotherapeutic drug doxorubicin (DOXO) incorporated into the polymer matrix in NP form; and (iv) finally, cancer-targeting folate conjugated onto the modified PLGA NPs via polyethylene glycol (PEG) groups.

MRI and fluorescence imaging tests were performed on untreated cancer cells over-expressing folate receptors and cells mixed with either folate-free or folate-coated functionalized PLGA (containing  $\text{Fe}_3\text{O}_4$  or CdSe/ZnS, as appropriate). Both techniques detected cancer cells treated with the NPs, with the best results achieved for folate-coated particles. When an external



*Transmission electron micrographs of uncoated PLGA NPs containing the chemotherapeutic drug DOXO and superparamagnetic  $\text{Fe}_3\text{O}_4$  nanocrystals. (Credit: Jaeyun Kim, Seoul National University.)*

magnetic field is applied, the sensitivity of MRI to the cancer cells increases even further. Fluorescence observations confirm that CdSe/ZnS-impregnated NPs can deliver a chemotherapeutic payload into target cells. Confocal laser scanning microscopy and flow cytometry similarly confirm cellular uptake of the  $\text{Fe}_3\text{O}_4$ -containing NPs. As expected, uptake of these particles is improved when an external magnetic field is applied.

*In vivo* studies are now planned to test whether the fully functionalized NPs can, indeed, be used to image tumor volumes and target drug delivery in the presence of an external magnetic field. Taeghwan Hyeon of Seoul National University is optimistic. "We expect the NPs will accumulate at the tumor site, allowing the tumor to be detected and destroyed at the same time," he says.

Paula Gould

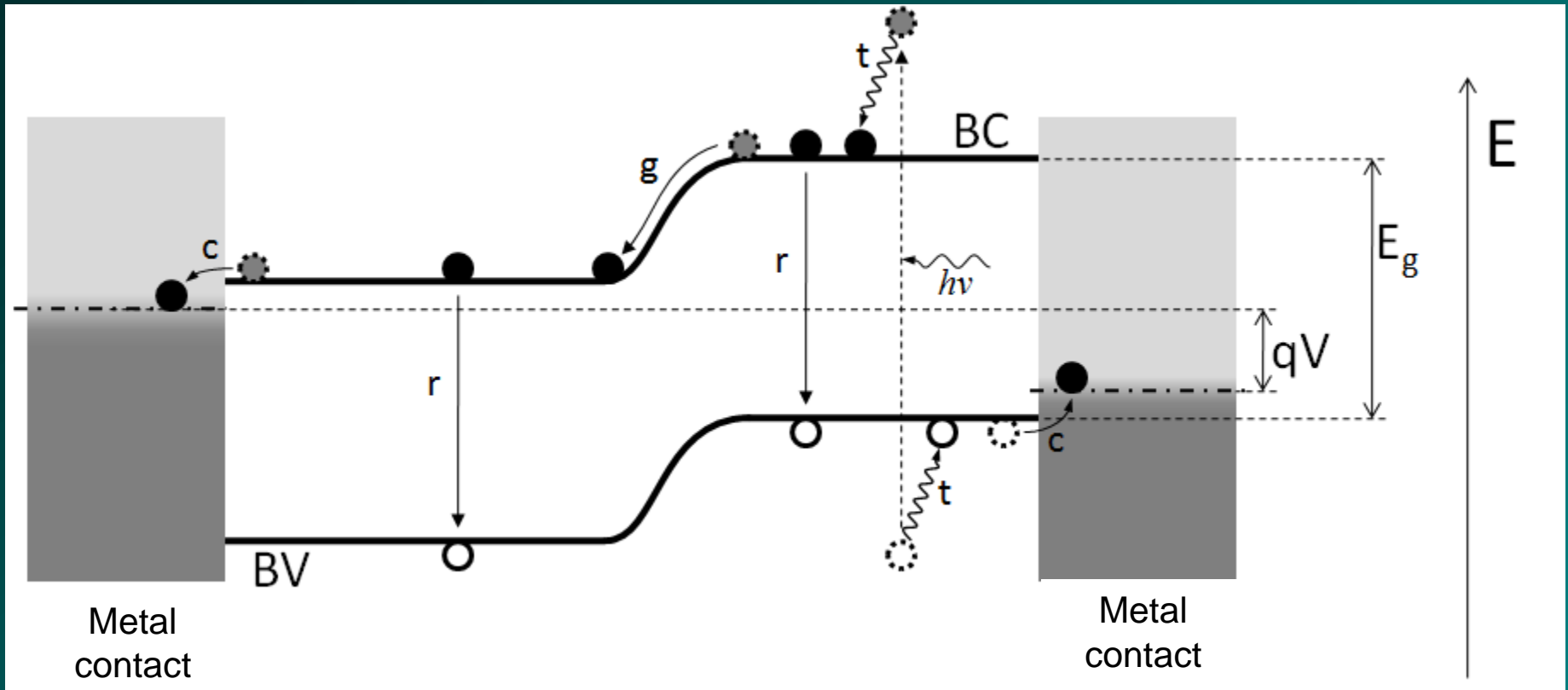
# Inchiostri a fluorescenza

Sicurezza e tecnologie anti-contraffazione





# Main Losses in PV Devices

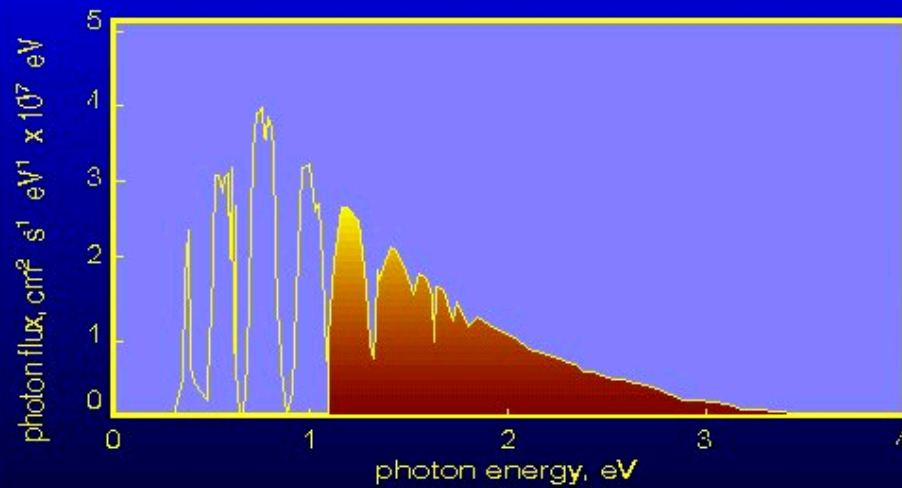


# Sommario

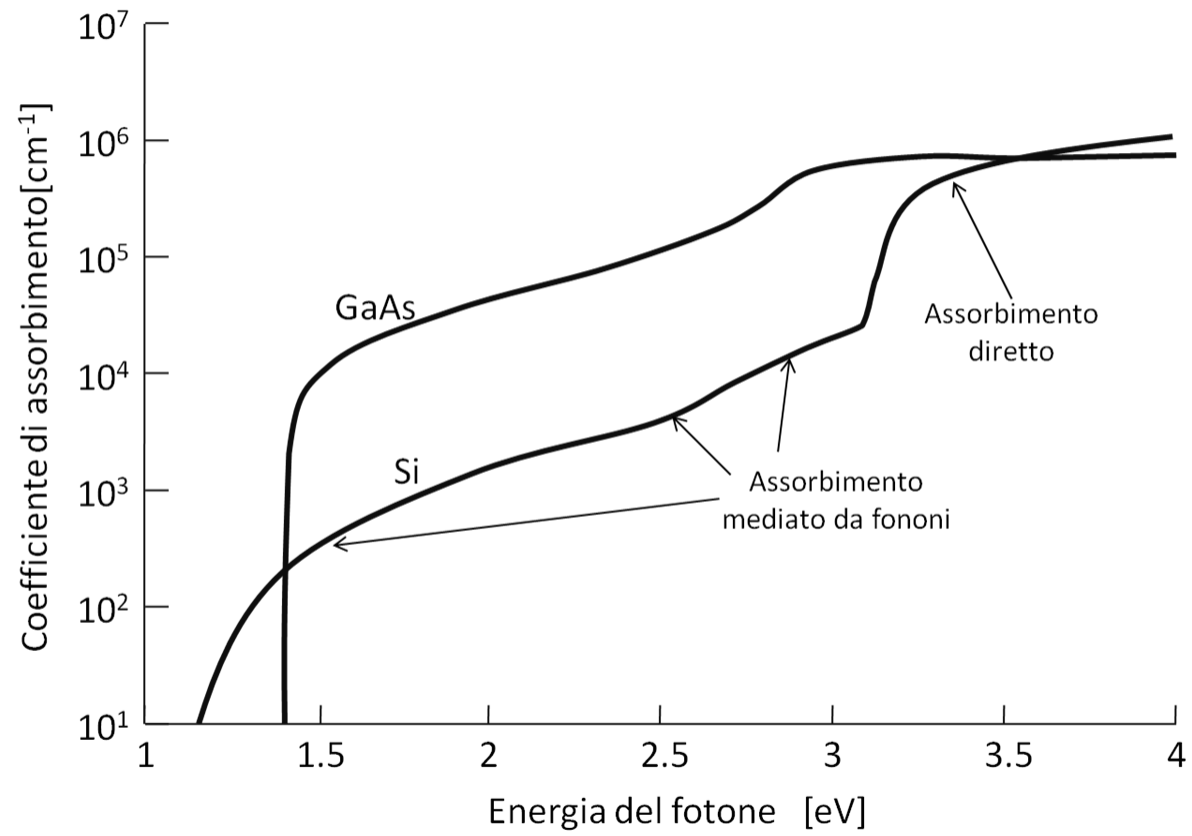
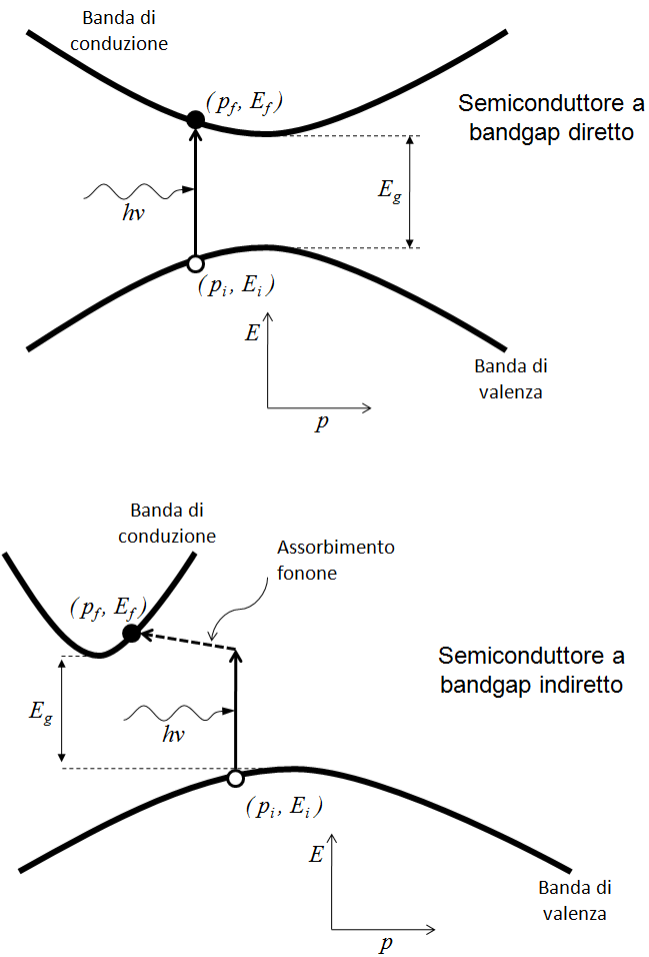
Tecnologia	Rendimento	Costo €/Wp	Tempo di ritorno dell'energia [anni]	Ritorno investimento energetico (EROI)
Silicio monocristallo	15-22%	4-5	2-5	5-15
Silicio policristallo	12-15%	4	1.7-3.5	8-17
Film sottili	5-13%	2-3	1-1.5	17-30
Celle tandem	30-42%	alto	?	?
DSSC	5-10%	(2-3)		
Materiali organici	3-6%	(1-2)	<1	>50
Nanomateriali	?	(<1)		

# The bandgap dilemma

## Photon flux utilised by a silicon solar cell



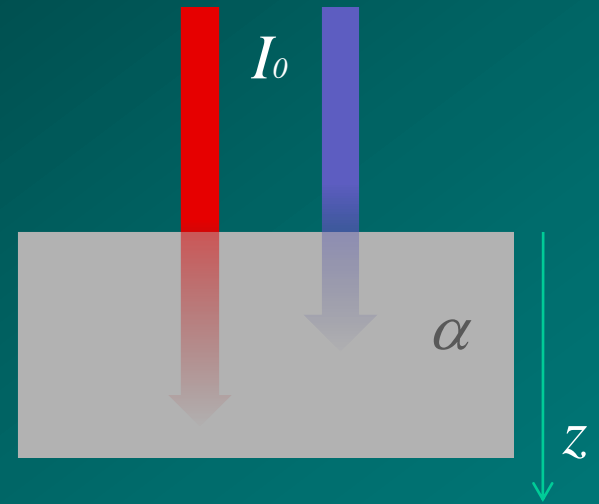
# Absorption coefficients



# Minimum thickness for full absorption

Legge di Lambert – Beer

$$I = I_0 \exp(-\alpha z)$$



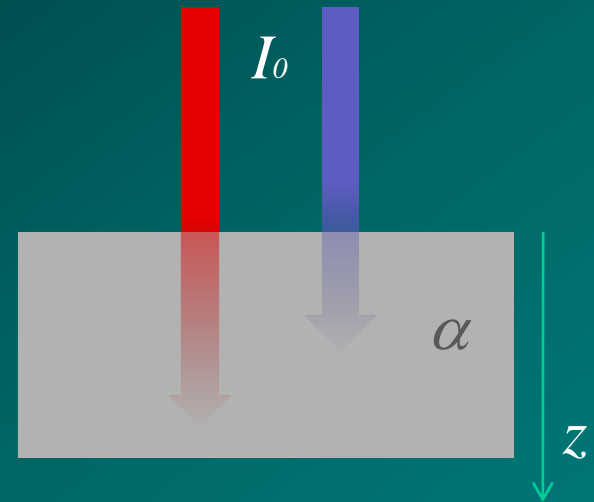
$$f(d) = \frac{\int_0^{\infty} (1 - \exp(-\alpha(\lambda)d)) N_{ph}(\lambda) d\lambda}{\int_0^{\lambda_g} N_{ph}(\lambda) d\lambda}$$



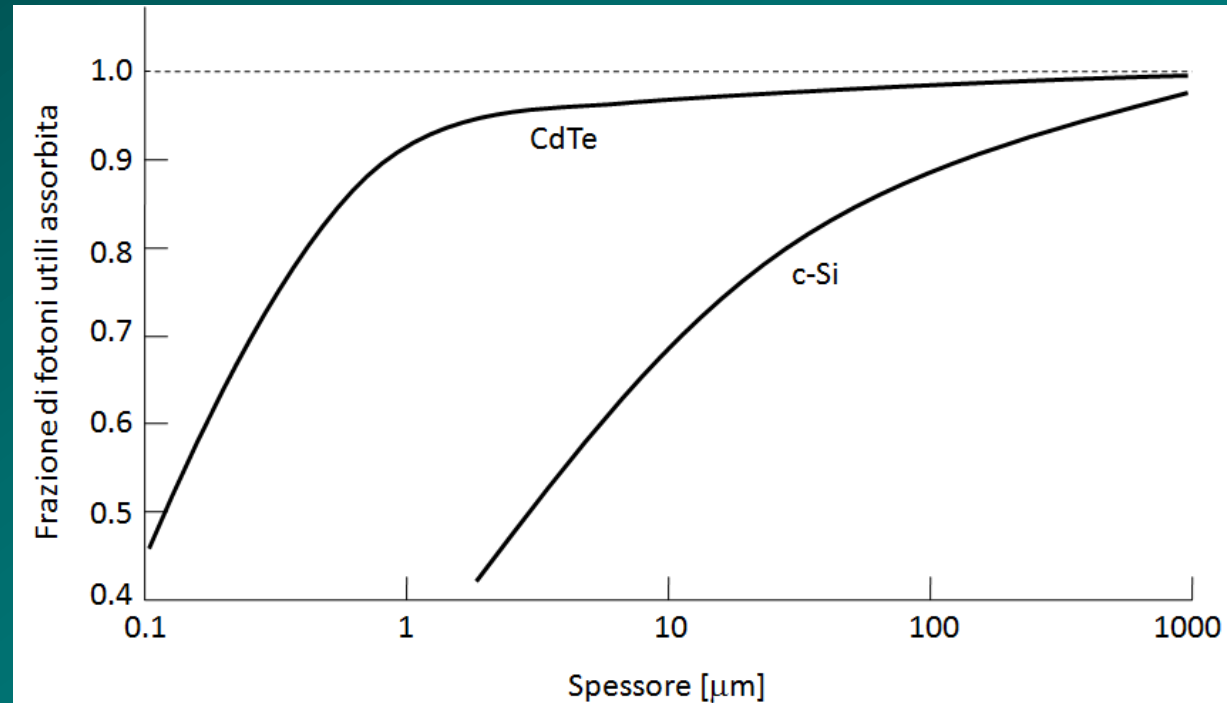
# Minimum thickness for full absorption

Legge di Lambert – Beer

$$I = I_0 \exp(-\alpha z)$$



$$f(d) = \frac{\int_0^{\lambda_g} (1 - \exp(-\alpha(\lambda)d)) N_{ph}(\lambda) d\lambda}{\int_0^{\lambda_g} N_{ph}(\lambda) d\lambda}$$



### Sintesi per test di reversibilità

